RENESAS

RL78 Family
EEPROM Emulation Software
RL78 Type 01
User's Manual

RENESAS Microcontrollers

RL78/G2x

Renesas Electronics
www.renesas.com

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General Precautions in the Handling of Microprocessing Unit and Microcontroller Unit Products

The following usage notes are applicable to all Microprocessing unit and Microcontroller unit products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

1. Precaution against Electrostatic Discharge (ESD)

   A strong electrical field, when exposed to a CMOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop the generation of static electricity as much as possible, and quickly dissipate it when it occurs. Environmental control must be adequate. When it is dry, a humidifier should be used. This is recommended to avoid using insulators that can easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors must be grounded. The operator must also be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions must be taken for printed circuit boards with mounted semiconductor devices.

2. Processing at power-on

   The state of the product is undefined at the time when power is supplied. The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the time when power is supplied. In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the time when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the time when power is supplied until the power reaches the level at which resetting is specified.

3. Input of signal during power-off state

   Do not input signals or an I/O pull-up power supply while the device is powered off. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Follow the guideline for input signal during power-off state as described in your product documentation.

4. Handling of unused pins

   Handle unused pins in accordance with the directions given under handling of unused pins in the manual. The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of the LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible.

5. Clock signals

   After applying a reset, only release the reset line after the operating clock signal becomes stable. When switching the clock signal during program execution, wait until the target clock signal is stabilized. When the clock signal is generated with an external resonator or from an external oscillator during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Additionally, when switching to a clock signal produced with an external resonator or by an external oscillator while program execution is in progress, wait until the target clock signal is stable.

6. Voltage application waveform at input pin

   Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between V_{IL} (Max.) and V_{IH} (Min.) due to noise, for example, the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between V_{IL} (Max.) and V_{IH} (Min.).

7. Prohibition of access to reserved addresses

   Access to reserved addresses is prohibited. The reserved addresses are provided for possible future expansion of functions. Do not access these addresses as the correct operation of the LSI is not guaranteed.

8. Differences between products

   Before changing from one product to another, for example to a product with a different part number, confirm that the change will not lead to problems. The characteristics of a microprocessing unit or microcontroller unit products in the same group but having a different part number might differ in terms of internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

How to Use This Manual

- Readers

    This manual is intended for users who wish to understand the features of the RL78 microcontrollers EEPROM Emulation and to use the EEPROM Emulation Software (EES) RL78 Type 01 in designing and developing application systems.

- Purpose

    This manual is intended to give users an understanding of the methods for using the EEPROM Emulation Software (EES) RL78 Type 01 to reprogram the data flash memory in the RL78/G2x microcontroller (i.e. write constant data by the application).

- Organization

    This manual is separated into the following sections.
    - Overview
    - System Configuration
    - EEPROM Emulation
    - Using EEPROM Emulation
    - User Interface
    - Sample Programs
    - Creating a Sample Project for EES RL78 Type 01

- How to Read this Manual

    It is assumed that the readers of this manual have general knowledge in the fields of electrical engineering, logic circuits, microcontrollers, C language, and assemblers.
    To understand the hardware functions of the RL78/G2x:
    - Refer to the User's Manual of the target RL78/G2x device.

- Conventions
    - Data significance: Higher digits on the left and lower digits on the right
    - Active low representations: $\overline{\times\times\times}$ (overscore over pin and signal name)
    - Note: Footnote for item marked with Note in the text
    - Caution: Information requiring particular attention
    - Remark: Supplementary information
    - Numeric representation:
        Binary: ×××× or ××××B
        Decimal: ××××
        Hexadecimal: ××××H or 0x××××
    - Prefixes indicating power of 2 (address space and memory capacity):
        K (kilo) 2^{10} = 1024
        M (mega) 2^{20} = 1024^2

- Related Documents

    The related documents indicated in this publication may include preliminary versions. However, preliminary versions are not marked as such.

No	Document Title	Document Number
1	RL78/G23 User's Manual Hardware	R01UH0896EJ
2	RL78/G22 User's Manual Hardware	R01UH0978EJ
3	RL78/G24 User's Manual Hardware	R01UH0961EJ
4	RL78 Family Renesas Flash Driver RL78 Type 01 User's Manual	R20UT4830EJ
5	E1/E20/E2 Emulator, E2 Emulator Lite Additional Document for User's Manual (Notes on Connection of RL78)	R20UT1994EJ
6	Renesas Flash Driver, EEPROM Emulation Software Target MCU List for RL78 - General-Purpose	R20UT5228EJ

Table of Contents

Abbreviations

Abbreviation	Description
EES	EEPROM Emulation Software
RFD	Renesas Flash Driver
API	Application Program Interface
BGO	Background Operation Instructions in the code flash memory can be executed during reprogramming of the data flash memory.
RAM	Random Access Memory Randomly accessible volatile memory. It is memory for holding values that are to be changed during program execution.
ROM	Read-Only Memory Non-volatile memory. It is memory whose contents cannot be changed. The code flash memory may be called ROM.

Terminology

Terminology	Description
Code flash memory	Flash memory for storing application code and constant data. Note that this memory may be abbreviated as "CF" in this document.
Data flash memory	Flash memory for storing data. Note that this memory may be abbreviated as "DF" in this document.
Extra area	Generic name of the configuration setting area, security setting area, lock protection area, and boot swap setting area.
Flash memory sequencer	The RL78 microcontroller has a dedicated circuit for controlling the flash memory. This circuit is called the flash memory sequencer in this document. The flash memory sequencer consists of the code/data flash area sequencer, which reprograms the code flash area or data flash area, and the extra area sequencer, which reprograms the extra area.
Flash memory control mode	The flash memory sequencer has the following modes, which indicate the programming enabled or disabled state. - Code flash memory programming mode - Data flash memory programming mode - Non-programmable mode
Code flash memory programming mode	The code flash memory (and extra area) can be reprogrammed in this mode.
Data flash memory programming mode	The data flash memory can be reprogrammed in this mode.
Non-programmable mode	The flash memory (and extra area) cannot be reprogrammed in this mode.
Self-programming	A method of reprogramming the flash memory by executing a user program instead of using an external flash memory programming tool.
RFD function	A generic term for the functions offered by the RFD.
EES function	A generic term for the functions offered by the EES.
RFD control functions for EES	A generic term for the RFD control functions offered by the EES.
EES Block	An abbreviation of blocks that the EEPROM emulation software accesses. In this user's manual, EEPROM emulation blocks are hereafter referred to as EES block.

1.   Overview

1.1   Outline

EEPROM emulation is a feature used to store data in the on-board flash memory in the same way as EEPROM. In EEPROM emulation, EEPROM Emulation Software RL78 Type 01 operates the Renesas Flash Driver (RFD) RL78 Type 01. And RFD writes and reads the data flash memory.

EEPROM Emulation Software RL78 Type 01 (hereafter called EES RL78 Type 01) is software for reprogramming the data flash memory in the RL78/G2x.

For information on Renesas Flash Driver (RFD) RL78 Type 01, refer to the RL78 Family Renesas Flash Driver RL78 Type 01 User's Manual.

1.1.1   Purpose

This manual is intended to give users an understanding of the methods for using the EEPROM Emulation Software (EES) RL78 Type 01 to reprogram the data flash memory in the RL78/G2x microcontroller. (i.e. write constant data by the application).

1.2   Contents

The API function of EES RL78 Type 01 is called from the user program. And reprogramming of the data in the EEPROM emulation block (EES block) placed into the data flash memory is possible.

The EES RL78 Type 01 package includes the following.

- This user's manual
- Source code files of EES RL78 Type 01 for controlling the data flash memory incorporated in the RL78/G2x.
- Sample program for operating the EES RL78 Type 01.

1.3   Features

EES RL78 Type 01 calls API functions for RFD RL78 Type 01 to operate the flash memory sequencer. Each API function of EES RL78 Type 01 consists of a single sub-function or two or more sub-functions, and the necessary processing is implemented by combinations of individual sub-functions and user processing. Such a configuration is adopted so as to flexibly handle processing dependent on the user application, such as, timeout processing in which the timeout value varies with the conditions of user application program execution.

Figure 1-1 shows the flash memory control by the user application using the API functions of EES RL78 Type 01.

EES RL78 Type 01 provides sample programs of the processing that is implemented by combinations of two or more API functions and user programs. Refer to the sample programs when embedding EEPROM emulation processing in the user application.
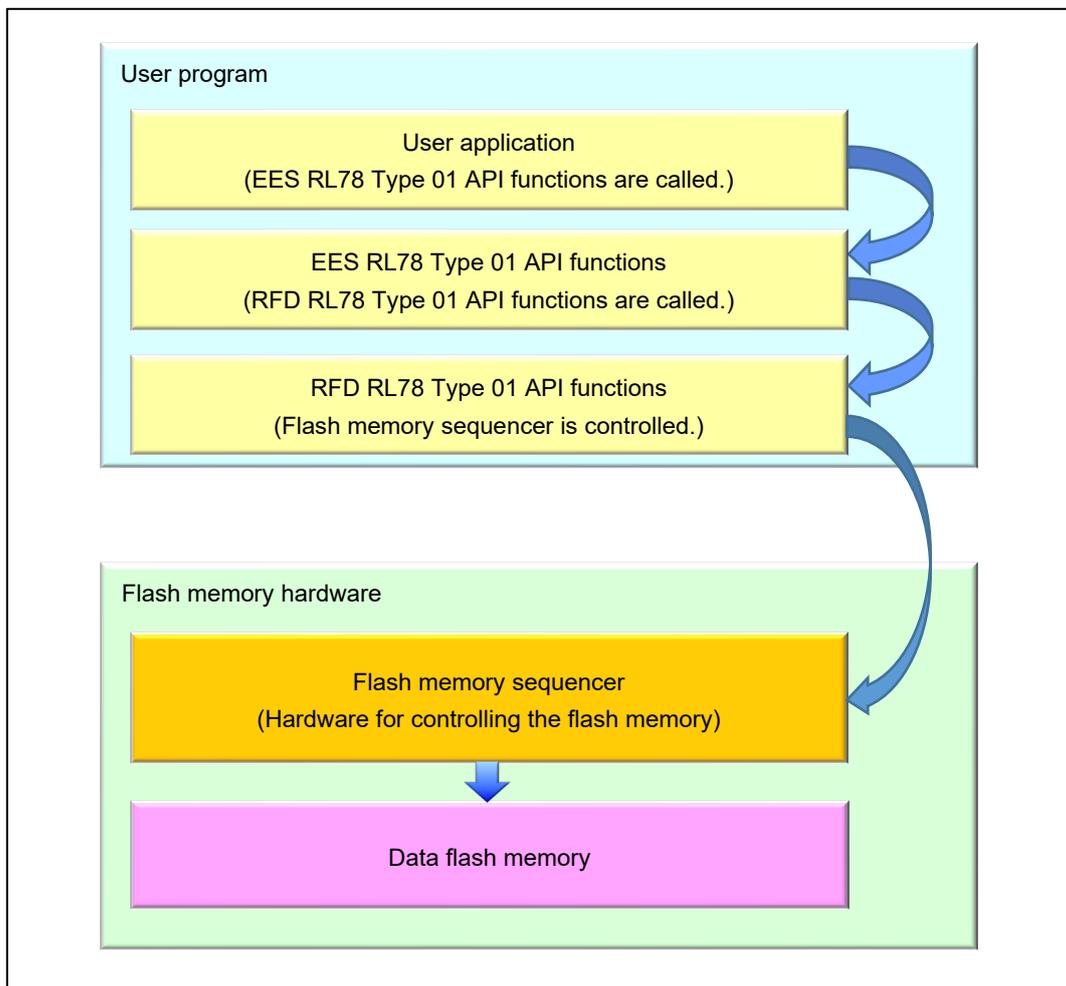
Figure 1-1 Data Flash Memory Control Using API Functions of EES RL78 Type 01

1.4   Operating Environment

- Host Computer
  The operation of EES RL78 Type 01 does not depend on the host computer but the appropriate environment for the C compiler package, debugger and emulator must be prepared. (EES RL78 Type 01 was developed and tested on Windows10 Enterprise.)

- C Compiler Package
  Table 1-1 shows the target C compiler packages for EES RL78 Type 01.

Table 1-1 The Target C Compiler Packages for EES RL78 Type 01

Compiler	IDE (Integrated Development Environment)	Manufacturer	Version
CC-RL	CS+ or e^2 studio	Renesas Electronics	V1.10 or later
IAR	IAR Embedded Workbench$^®$ for Renesas RL78	IAR Systems$^®$	V4.21 or later
LLVM	e^2 studio	(Open Source Software)	V10.0.0.202306 or later

Note. Integrated development environment(IDE) and compiler must support the target device.

- Emulator
  Table 1-2 shows the emulator on which the operation of EES RL78 Type 01 was confirmed.

Table 1-2 Emulator on which EES RL78 Type 01 Operation was Confirmed

Emulator	Manufacturer
E2 emulator	Renesas Electronics
E2 emulator Lite	Renesas Electronics

- Target MCU
  RL78/G23, RL78/G22, RL78/G24

- EEPROM Emulation Software (EES)
  Table 1-3 shows the EEPROM Emulation Software (EES) supported by this manual.

Table 1-3 The EEPROM Emulation Software (EES) Supported by this Manual

Package	Manufacturer	Package Version
EES RL78 Type 01	Renesas Electronics	Ver 1.20

Note. Use the version of RFD RL78 Type 01 listed in Table 1-4.

- Renesas Flash Driver (RFD)
  Table 1-4 shows the Renesas Flash Driver (RFD) used for EES RL78 Type 01.

Table 1-4 The Renesas Flash Driver (RFD) Used for EES RL78 Type 01

Package	Manufacturer	Package Version
RFD RL78 Type 01	Renesas Electronics	Ver 1.20

1.5   Points for Caution

EEPROM emulation is achieved by using a feature for manipulating the RL78/G2x microcontroller data flash memory. Therefore, it is necessary to note the following.

(1)   All EES code and constants must be placed in the same 64 KB flash block such that EES code and constants do not extend across a 64-KB boundary. (It dependent on each compiler.)

(2)   The EES must be initialized by the R_EES_Init function before any EES function is executed.

(3)   The data flash memory cannot be read during data flash memory operation by the EES.

(4)   It is not allowed to call any RFD function during a command execution of the EES.

(5)   It is not allowed to call any RFD control functions for EES directly from other than the EES.

(6)   Do not execute STOP mode or HALT mode processing while the EEPROM emulation is being used. If it is necessary to execute STOP mode or HALT mode processing, be sure to execute all of the processing up to and including the R_EES_Close function to finish EEPROM emulation.

(7)   The watchdog timer does not stop during execution of the EES.

(8)   Do not destroy the request structure (st_ees_request_t) during command execution.

(9)   Initialize the argument (RAM) that is used by the EEPROM emulation software function. When not initialized, a RAM parity error is detected and the RL78/G2x microcontroller might be reset. For a RAM parity error, refer to "User's Manual: Hardware" of a target device.

(10) All members of the request structure (st_ees_request_t) must be initialized once before a EES command is executed. If any unused member exists in the request structure (st_ees_request_t), set a desired value for the member. If any member is not initialized, the RL78/G2x microcontroller may be reset due to a RAM parity error. For details, refer to "User's Manual: Hardware" of a target device.

(11) The EES does not support multitask execution. Do not execute the EES functions during interrupt processing.

(12) After the R_EES_Close function have been executed, the requested command and ongoing command stop and cannot be resumed. Before calling the R_EES_Close function, finish all ongoing commands.

(13) Do not operate the code flash memory by RFD RL78 Type 01 while the EEPROM emulation is executed. Before the code flash memory is operated, be sure to execute a "R_EES_Close function" necessary in order to finish the EEPROM emulation. When using EEPROM emulation after executing the code flash memory operations using the RFD RL78 Type 01, it is necessary to start processing from the initializing function (the R_EES_Init function).

(14) Before starting the EEPROM emulation, be sure to start up the high-speed on-chip oscillator first. The high-speed on-chip oscillator must also be activated when using the external clock.

(15) No checksum is added to user data. If a checksum is needed, add it to user data and check through the user program.

(16) Do not operate the data flash control register (DFLCTL) during execution of the EES.

(17) To use the data flash memory for EEPROM emulation, it is necessary to execute the R_EES_ENUM_CMD_FORMAT command upon first starting up to initialize the data flash memory and make it usable as EES blocks.

(18) In order to use the EES, it is recommended to set at least 3 blocks in the EES block (virtual block).

(19) Do not destroy the EES blocks (virtual block) by the user program operating the data flash memory using the RFD from other than the EES.

(20) EES descriptor is changed, the EEPROM emulation can no longer be executed. In that case, the EES pool must be formatted by the R_EES_ENUM_CMD_FORMAT command in addition to initialization of EES. When adding data, however, the EEPROM emulation can be continuously executed.

(21) About an operating frequency of RL78/G2x microcontroller and an operating frequency value set by the initializing function (R_EES_Init), be aware of the following points:
- When using a frequency lower than 4 MHz as an operating frequency of RL78/G2x microcontroller, only 1 MHz, 2 MHz and 3 MHz can be used (frequencies other than integer values like a 1.5 MHz cannot be used). Also, set an integer value 1, 2, or 3 to the operating frequency value set by the initializing function.
- When using a frequency of 4 MHz or higher [Note] as an operating frequency of RL78/G2x microcontroller, a certain frequency can be used as an operating frequency of RL78/G2x microcontroller.
- This operating frequency is not the frequency of the high-speed on-chip oscillator.

Note: For a maximum frequency, refer to "User's Manual: Hardware" of a target device.

1.6   C Compiler Definitions

The definitions of the target compiler written in the header file (r_ees_compiler.h) for EES RL78 Type 01 are shown below.

The definitions differ between compilers. The "r_ ees_compiler.h" file is used to identify the current compiler and the definitions for the target compiler are used.

- Definition of CC-RL compiler :
  "__CCRL__" is defined.
  #define COMPILER_CC   (1)
- Definition of IAR compiler(V2, V3, V4) :
  "__IAR_SYSTEMS_ICC__" is defined.
  #define COMPILER_IAR   (2)
- Definition of LLVM compiler :
  "__llvm__" is defined.
  #define EES_COMPILER_LLVM   (3)

< Descriptions in the r_ees_compiler.h file >

```
/* Compiler definition */
#define EES_COMPILER_CC         (1)
#define EES_COMPILER_IAR        (2)
#define EES_COMPILER_LLVM       (3)


#if defined (__llvm__)
    #define EES_COMPILER EES_COMPILER_LLVM
#elif defined (__CCRL__)
    #define EES_COMPILER EES_COMPILER_CC
#elif defined (__IAR_SYSTEMS_ICC__)
    #define EES_COMPILER EES_COMPILER_IAR
#else
    /* Unknown compiler error */
    #error   "Non-supported compiler."
#endif


/* Compiler dependent definition */
#if (EES_COMPILER_CC == EES_COMPILER)
    #define R_EES_FAR_FUNC                          __far
#elif (EES_COMPILER_IAR == EES_COMPILER)
    #define R_EES_FAR_FUNC                          __far_func
#elif (EES_COMPILER_LLVM == EES_COMPILER)
    #define R_EES_FAR_FUNC                          __far
#else
    /* Unknown compiler error */
    #error   "Non-supported compiler."
#endif
```

C Compiler Options

The contents of the C compiler option setup which normal operation can be checking are shown below.

- [CC-RL(CS+)]

    Major compile options:
    -cpu=S3 -g -g_line -lang=c99

- [IAR(IAR Embedded Workbench)]

    Major compile options:
    --core s3 --calling_convention v2 --code_model far --data_model near -e -Ol --no_cse --no_unroll
    --no_inline --no_code_motion --no_tbaa --no_cross_call --no_scheduling --no_clustering --debug

- [LLVM(e^2 studio)]

    Major compile options:
    -Og -ffunction-sections -fdata-sections -fdiagnostics-parseable-fixits -Wunused -Wuninitialized -Wall
    -Wmissing-declarations -Wconversion -Wpointer-arith -Wshadow -Waggregate-return -g -mcpu=s3

2.   System Configuration

2.1   System Configuration

The EES offers interface for accessing the data flash area(the EES pool) defined by the user. The API functions provided by EES accesses the EES pool via the RFD control functions for EES, or RFD.

The arrows shown in the Figure 2-1 below indicate the flow of processing.
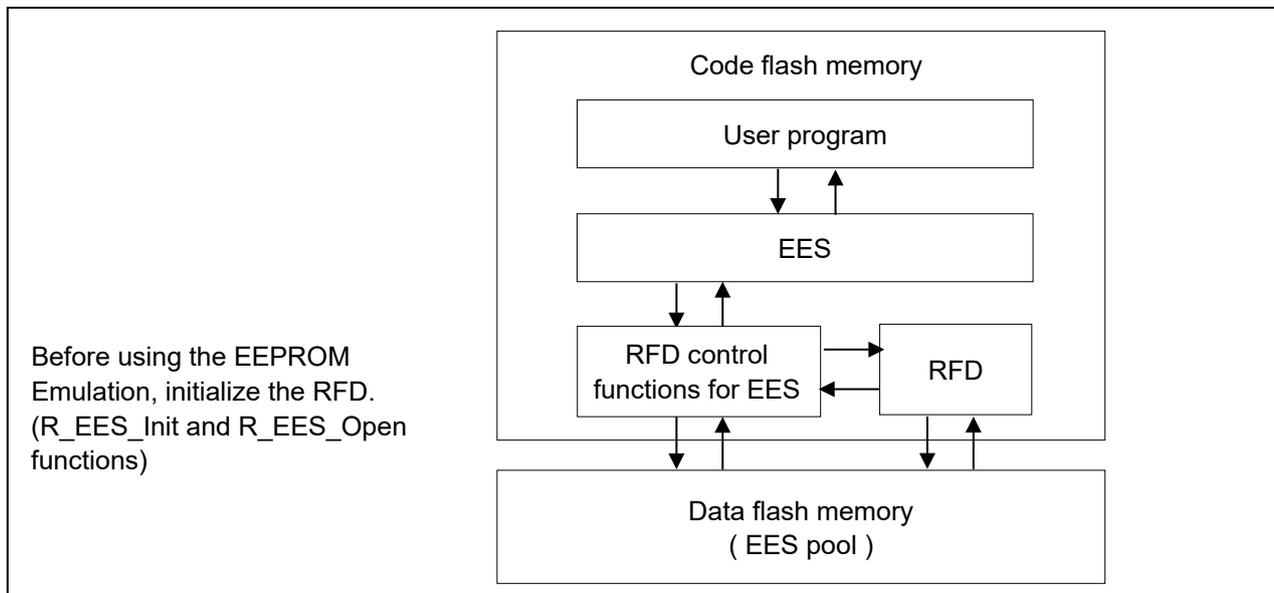
Figure 2-1 System Configuration

2.2   EES Architecture

This chapter describes the EES architecture required for the user to rewrite data flash memory (the EES pool) by using the EES.

2.2.1   EES Block

EES uses multiple blocks of the data flash memory as one virtual block. This area is called an EES block. The size of a block of the data flash memory mounted in RL78/G2x is 256 bytes. When EES block size is set to a 1K-byte, 4 blocks of the data flash memory are gathered, and EES handles as a 1K-byte's virtual block. Moreover, when EES block size is set to a 2K-byte, 8 blocks of the data flash memory are gathered, and EES is handled as a 2K-byte's virtual block.

Be sure to set the size of an EES block in consideration of the size and the total number of blocks of the data flash memory mounted in the target device. Refer to "4.2 Initial Values to be Set by User" for the setting method. The schematic diagram for the EES block 0 when 1 K-byte or 2 K-byte are set by EES block is shown in "Figure 2-2 Schematic diagram of EES block 0".

Maximum number of blocks that can be set in the EES block of a product equipped with 8 Kbytes of data flash memory:

   When the EES block size is set to 1 K-byte , the maximum number of blocks is 8.

   When the EES block size is set to 2 K-byte , the maximum number of blocks is 4.
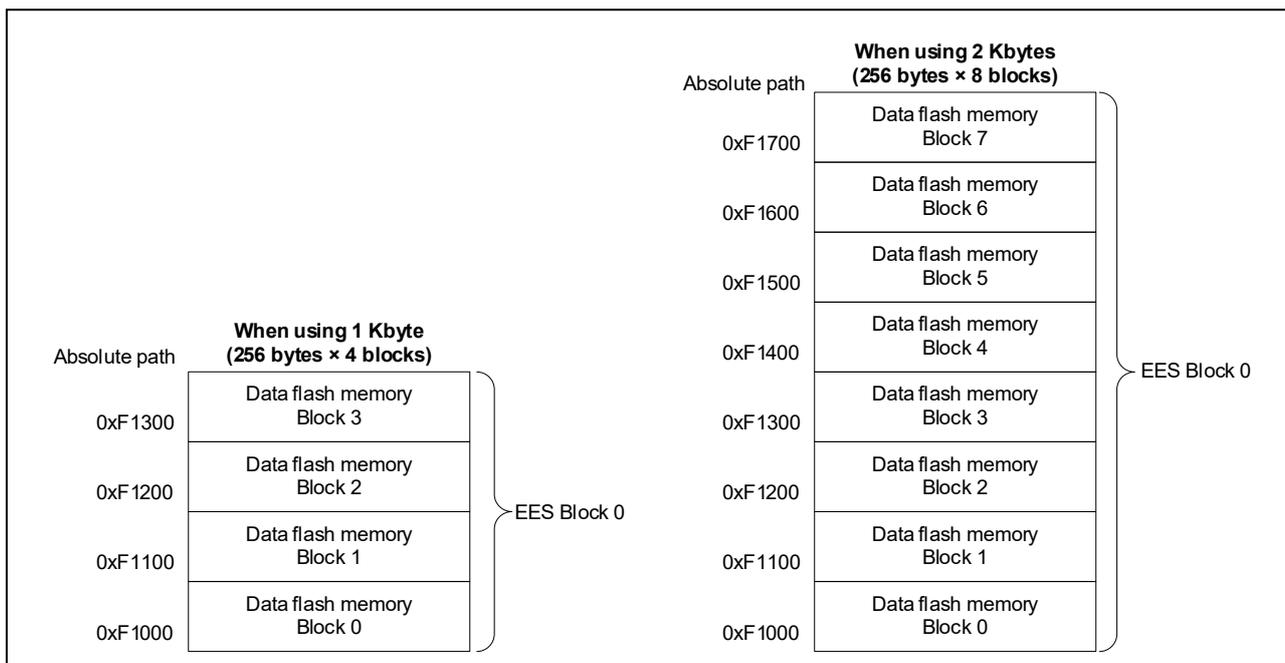
Figure 2-2 Schematic diagram of EES block 0

2.2.2　EES Pool

The EES pool is a user-defined data flash area that is accessible by the EES. The user program can access the data flash only by using this EES pool in the data flash via the RFD control functions for EES and the EES. The EES pool size must be specified with the number of size in the data flash of the target device. For the procedure to specify the number of blocks, see section 4.2 Initial Values to be Set by User.

Figure 2-3 shows an example of pool configuration for a device with 8 Kbytes data flash memory.
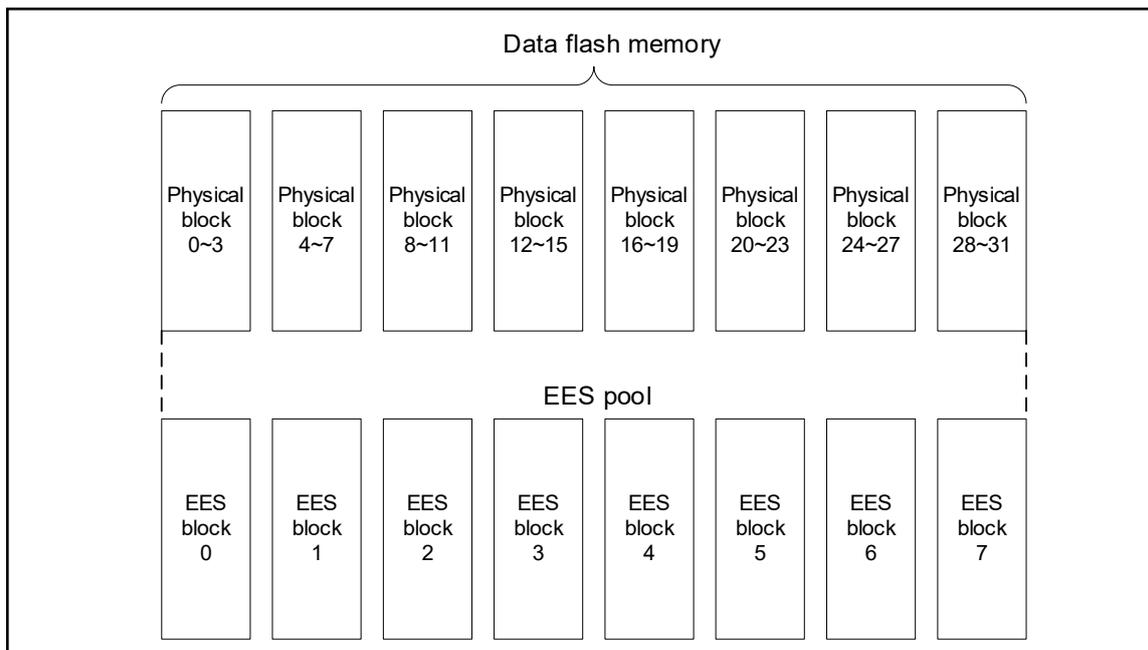
Figure 2-3 EES pool configuration example (EES block size: 1 Kbyte)

2.3   File Structure

2.3.1   Folder Structure

Figure 2-4 shows the folder structure of EES RL78 Type 01.
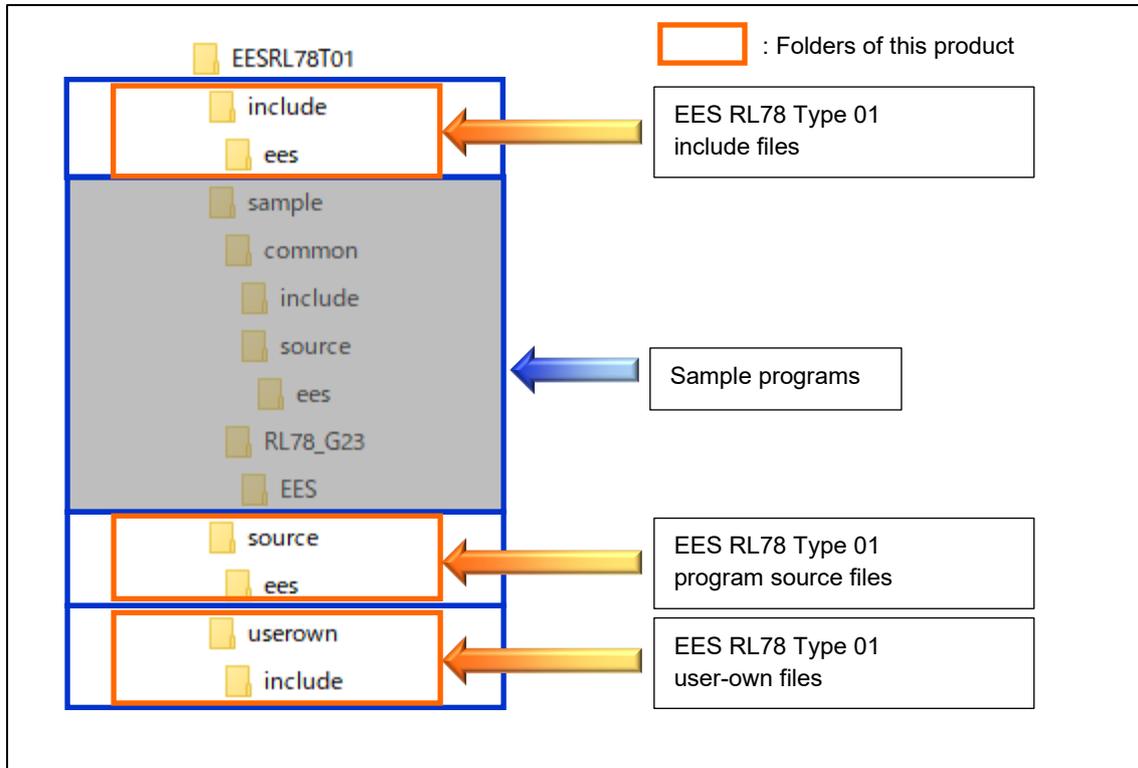
Figure 2-4   Folder Structure of EES RL78 Type 01

Note: Figure 2-4 shows an example of using RL78/G23. The installed "sample" folder contains a folder for each device group (e.g. RL78_G23, RL78_G24). Refer to "6.1.1 Folder Structure" for the sample folder for each device group.

2.3.2   List of Files

2.3.2.1   List of Source Files

Table 2-1 shows the program source files in the "source\ees\" folder.

Table 2-1   Program Source Files in the "source\ees\" Folder

No.	Source File Name	Description
1	r_ees_api.c	This file contains the API functions for EEPROM emulation control.
2	r_ees_exrfd_api.c	This file contains the API functions RFD control functions for EES
3	r_ees_sub_api.c	This file contains API functions that are used as internal functions for EEPROM emulation control.

Table 2-2 shows the program source file in the "userown\" folder.

Table 2-2   Program Source File in the "userown\" Folder

No.	Source File Name	Description
1	r_ees_descriptor.c	EES descriptor source file.

2.3.2.2   Header File List of Header Files

Table 2-3 shows the program header files in the "include\" folder.

Table 2-3   Program Header Files in the "include\" Folder

| No.	Header File Name	Description
1	r_ees_api.h	This file defines the prototypes used in EEPROM control functions.
2	r_ees_exrfd_api.h	This file defines the prototypes used in RFD control functions for EES.
3	r_ees_sub_api.h	This file defines the prototypes for internal functions used in EEPROM emulation control functions.

Table 2-4 shows the program header files in the "userown\include\" folder.

Table 2-4   Program Header Files in the "userown\include\" Folder

No.	Header File Name	Description
1	r_ees_descriptor.h	EES descriptor header file.
2	r_ees_user_types.h	This file defines the types of user data used in EES.

Table 2-5 shows the program header files in the "include\ees" folder.

Table 2-5   Program Header Files in the "include\ees" Folder

No.	Header File Name	Description
1	r_ees.h	Common header file.
2	r_ees_compiler.h	This file defines the compiler-dependent macros used in EES RL78 Type 01.
3	r_ees_defines.h	This file describes the definitions that differ between compilers used in EES RL78 Type 01.
4	r_ees_device.h	This file defines the hardware-specific macros used in EES RL78 Type 01.
5	r_ees_memmap.h	This file defines macros to describe sections used in EES RL78 Type 01.
6	r_ees_types.h	This file defines the types of variables used in EES RL78 Type 01.
7	r_typedefs.h	This file defines the types of data used in EES RL78 Type 01.

2.4　Resources of RL78/G2x

2.4.1　Memory Map

Table 2-6 shows the memory map (code flash memory: CF[1 block = 2 Kbytes], data flash memory: DF
[1 block = 256 bytes], and RAM) of the RL78/G23, RL78/G22 and RL78/G24.

Table 2-6　Memory Map (ROM, Data Flash, and RAM)

RL78	Device	Code Flash Memory: CF	RAM
G23	R7F100GxF (x = A, B, C, E, F, G, J, L)	96 Kbytes (00000H to 17FFFH)	12 Kbytes (FCF00H to FFEFFH)
	R7F100GxG (x = A, B, C, E, F, G, J, L, M, P)	128 Kbytes (00000H to 1FFFFH)	16 Kbytes (FBF00H to FFEFFH)
	R7F100GxH (x = A, B, C, E, F, G, J, L, M, P)	192 Kbytes (00000H to 2FFFFH)	20 Kbytes (FAF00H to FFEFFH)
	R7F100GxJ (x = A, B, C, E, F, G, J, L, M, P, S)	256 Kbytes (00000H to 3FFFFH)	24 Kbytes (F9F00H to FFEFFH)
	R7F100GxK (x = F, G, J, L, M, P, S)	384 Kbytes (00000H to 5FFFFH)	32 Kbytes (F7F00H to FFEFFH)
	R7F100GxL (x = F, G, J, L, M, P, S)	512 Kbytes (00000H to 7FFFFH)	48 Kbytes (F3F00H to FFEFFH)
	R7F100GxN (x = F, G, J, L, M, P, S)	768 Kbytes (00000H to BFFFFH)	48 Kbytes (F3F00H to FFEFFH)
	Data Flash Memory: DF	8 Kbytes (F1000H to F2FFFH) All RL78/G23 devices	
G22	R7F102GxC (x = 4, 6, 7, 8, A, B, C, E, F, G)	32 Kbytes (00000H to 07FFFH)	4 Kbytes (FEF00H to FFEFFH)
	R7F102GxE (x = 4, 6, 7, 8, A, B, C, E, F, G)	64 Kbytes (00000H to 0FFFFH)	4 Kbytes (FEF00H to FFEFFH)
	Data Flash Memory: DF	2 Kbytes (F1000H to F17FFH) All RL78/G22 devices	
G24	R7F101GxE (x=6,7,8,A,B,E,F,G,J,L)	64 Kbytes (00000H to 0FFFFH)	12 Kbytes (FCF00H to FFEFFH)
	R7F101GxG (x=6,7,8,A,B,E,F,G,J,L)	128 Kbytes (00000H to 1FFFFH)	12 Kbytes (FCF00H to FFEFFH)
	Data Flash Memory: DF	4 Kbytes (F1000H to F1FFFH) All RL78/G24 devices	

2.4.2 Allocation of Blocks

Figure 2-5, and Figure 2-6 shows the allocation of blocks in code flash memory (CF), and data flash memory (DF). Refer to the user's manual of a target device for allocation of blocks for other devices.

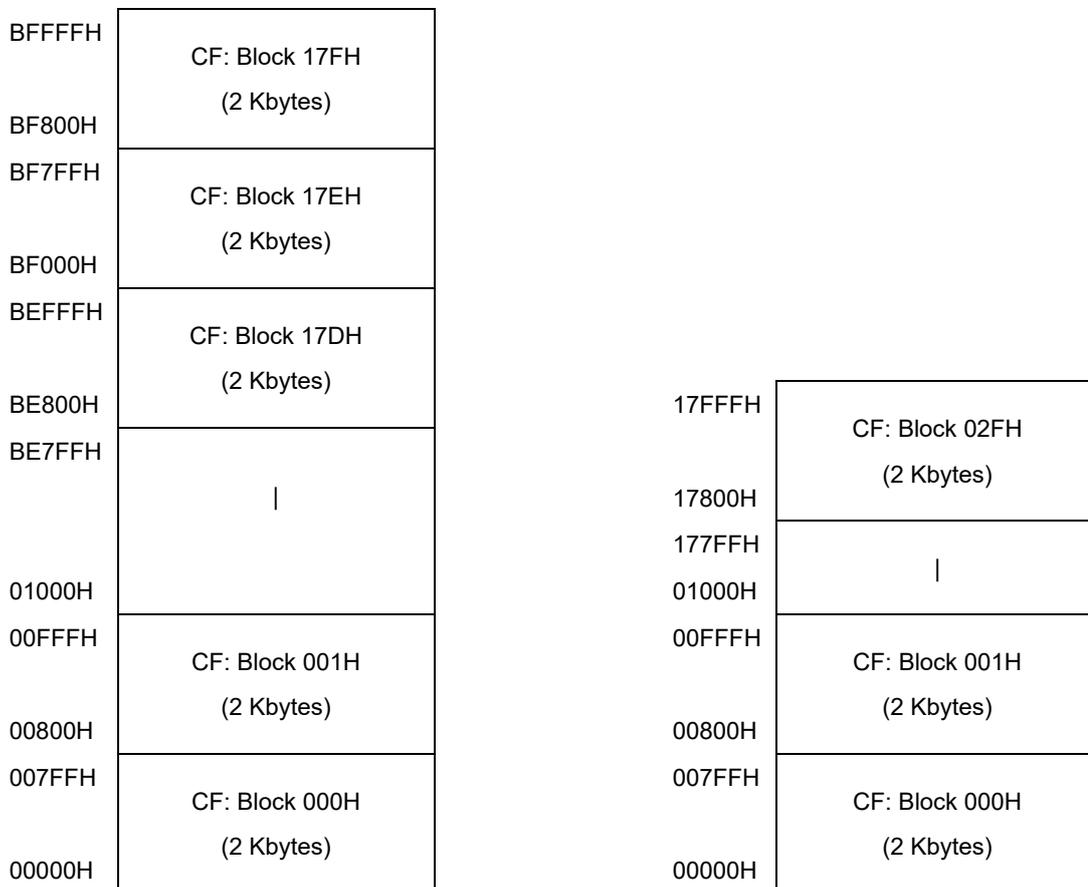(1) R7F100GxN (Code flash memory: 768 Kbytes)   (2) R7F100GxF (Code flash memory: 96 Kbytes)

Figure 2-5   Blocks in the Code Flash Memory

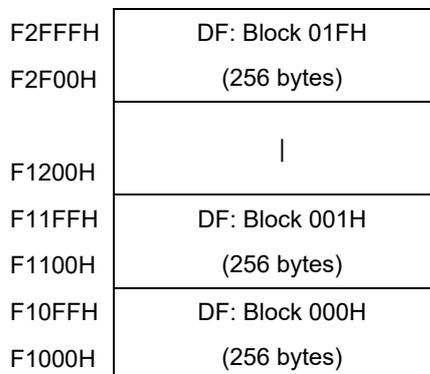(1) All RL78/G23 devices (Data flash memory: 8 Kbytes)

Figure 2-6   Blocks in the Data Flash Memory

2.4.3 Flash Operation Mode

(1) The range of operating frequency in each flash operation mode of RL78/G23.

Table 2-7 shows the range of operating frequency in each flash operation mode of RL78/G23.

Table 2-7 Operating Frequency Ranges for Individual Flash Operation Modes and Power Supply Voltages

Power Supply Voltage (V_{DD})	Flash Operation Mode	Operating Frequency
1.8 V ≤ V_{DD} ≤ 5.5 V	HS (high-speed main) mode	1 MHz to 32 MHz
	LS (low-speed main) mode	1 MHz to 24 MHz
1.6 V ≤ V_{DD} < 1.8 V	HS (high-speed main) mode	1, or 2 MHz
	LS (low-speed main) mode	1, or 2 MHz

Note: The flash memory cannot be reprogrammed in the LP (low-power main) mode.

(2) The range of operating frequency in each flash operation mode of RL78/G22.

Table 2-8 shows the range of operating frequency in each flash operation mode of RL78/G22.

Table 2-8 Operating Frequency Ranges for Individual Flash Operation Modes and Power Supply Voltages

Power Supply Voltage (V_{DD})	Flash Operation Mode	Operating Frequency
1.8 V ≤ V_{DD} ≤ 5.5 V	HS (high-speed main) mode	1 MHz to 32 MHz
	LS (low-speed main) mode	1 MHz to 24 MHz

Note: The flash memory cannot be reprogrammed in the LP (low-power main) mode.

(3) The range of operating frequency in each flash operation mode of RL78/G24.

Table 2-9 shows the range of operating frequency in each flash operation mode of RL78/G24.

Table 2-9 Operating Frequency Ranges for Individual Flash Operation Modes and Power Supply Voltages

Power Supply Voltage (V_{DD})	Flash Operation Mode	Operating Frequency
2.4 V ≤ V_{DD} ≤ 5.5 V	HS (high-speed main) mode (with prefetching on)	48 MHz
1.8 V ≤ V_{DD} ≤ 5.5 V	HS (high-speed main) mode (with prefetching off)	1 MHz to 32 MHz
	LS (low-speed main) mode	1 MHz to 24 MHz

Notes 1: The flash memory cannot be reprogrammed in the LP (low-power main) mode.

2: It is necessary to enable a prefetch buffer peculiar to RL78/G24 in the mode of "HS (high-speed main) mode (with prefetching on)".

2.5   Resources Used in EES RL78 Type 01

2.5.1   Sections Used in EES RL78 Type 01

Table 2-10 shows the sections used for EES and allocations of the sections.

Table 2-10   Sections Used in EES

Section Name	Description	Allocation
EES_CODE	Program section of API functions for EES control	ROM
EES_CNST	Constant variables section for EES initialized variables.	ROM
EES_VAR	Variables section for EES control	RAM
SMP_EES	Program section of sample functions for EES control	ROM
SMP_VAR	Variables section of sample functions for EES control	RAM

2.5.2   Software Resources

Table 2-11 shows software resources (Reference value).

Table 2-11   Software Resources[Notes1,2] (Reference value)

Item	Size (Byte)		
	CC-RL	IAR	LLVM
Stack	44	48	44
Code size[Note3]	4624	5177	5830

Notes 1: These values are when using the compiler options described in "1.6 C Compiler Definitions".

2: Does not include the stack and code size of the sample program.

3: Does not include code size of the RFD RL78 Type 01.

3.   EEPROM Emulation

3.1   Specifications of EEPROM Emulation

By calling the EES functions provided by the EES RL78 Type 01 from a user-created program, use is possible without the awareness of data flash memory operations.

For the EES RL78 Type 01, an one-bye identifier (data ID: 1 to 254) is assigned by the user for each data item, and reading and writing using any unit from 1 to 255 bytes are possible on an assigned identifier basis. (The EES can handle up to 254 identifiers.)

Also, EES blocks (virtual block) for storing data use more than three blocks of area (recommended) [Note]. These blocks are called EES blocks. Data written by EEPROM emulation is divided into reference data and user-specified data, and the reference data is written to the target blocks from the lower block address, while the user data is written from the higher block address.

Note: At least two blocks are necessary for EEPROM emulation. When two blocks are specified, if a write error occurs even once, only reading of normally written data is possible but writing is no longer possible. After that, the two target blocks must be formatted when the EES is used to write data. Written data is erased completely. Since a contingency (such as voltage drop) may occur in the system, we recommend that you specify at least three blocks.

3.2   Outline of Functions

The EES provides basic read/write functions having the following features.

- The value to set for the size of the EES block:
    RL78/G23 and RL78/G24: 1024 or 2048 bytes
    RL78/G22: 512 bytes
- Up to 254 data items settable
- A data size of 1 to 255 bytes settable
- Supporting the background operation (BGO)
- Memory consumption of data for EES management (Block header, Separator):
    10 bytes per EES block
- Memory consumption of reference data: 3 bytes per EES block write data)
- Restoration by R_EES_ENUM_CMD_REFRESH when execution is stopped by a CPU reset while R_EES_ENUM_CMD_WRITE or R_EES_ENUM_CMD_REFRESH is running
- Block rotation (averaging data flash use frequency)

Table 3-1 shows the range of settings when the EES functions are used.

Table 3-1 Range of Settings when the EES Functions are Used

Item	Range
EES block size	RL78/G22: 512 (bytes) RL78/G23 and RL78/G24: 1024 or 2048 (bytes)
User data length	1 to 255
Amount of stored user data Note 1	1 to 254
Data ID range	1 to 254 (The numbers assigned are from 1 to 254 in the order of registration, and the selection of settings is not possible.)
Number of EES blocks Note 2	3 to 255
Recommended user data size Note 1	The EES block size is set to 512 bytes: 502 / 2 (bytes) or less The EES block size is set to 1024 bytes: 1014 / 2 (bytes) or less The EES block size is set to 2048 bytes. 2038 / 2 (bytes) or less

Notes: 1. The total size of user data must be within 1/2 of each block when all user data are written to an EES block. Therefore, the range used for the number of stored user data items differs depending on the size of the stored user data. It is also necessary to consider the size of the reference data provided for each data item for management use when determining the total size. For details about the number of stored user data items and total size, see "4.1 Number of Stored User Data Items and Total User Data Size".

2. EES blocks cannot be set more than maximum number of blocks of on-board data flash memory.

3.3 EES Pool

This chapter describes the EES architecture required for the user to rewrite data flash memory (the EES pool) by using the EES.

3.3.1 EES Pool State

Each block has a state which indicates the current usage of the block. Table 3-2 shows States of the EES Blocks.

Table 3-2 States of the EES Blocks

State	Description
Active	Only a single EES block is active at a time to store defined data. The active block circulates in data flash blocks allocated in the EES pool.
Invalid	No data is stored in invalid blocks. EES blocks are marked as invalid by the EES or become invalid in the case of erasure blocks.
Excluded	If functional operation failed and possibility of a data flash failure is clarified, the EES excludes the relevant block and the block is no longer used for EEPROM emulation.

When no writable area is remaining in the active block (EES block 1 in the example) and data can no longer be stored (failure in write command), a new active block is selected in a cyclic manner and the current valid data set is copied to this new active block. This process is referred to as refresh. After the R_EES_ENUM_CMD_REFRESH command is executed, the previous active block becomes invalid and only a single active block exists. Excluded blocks (like block 7 in the example) are ignored during this process and not considered as candidates for the selection of the next active block.

Figure 3-1 shows an example of pool states (EES block size is set to 1 Kbyte).
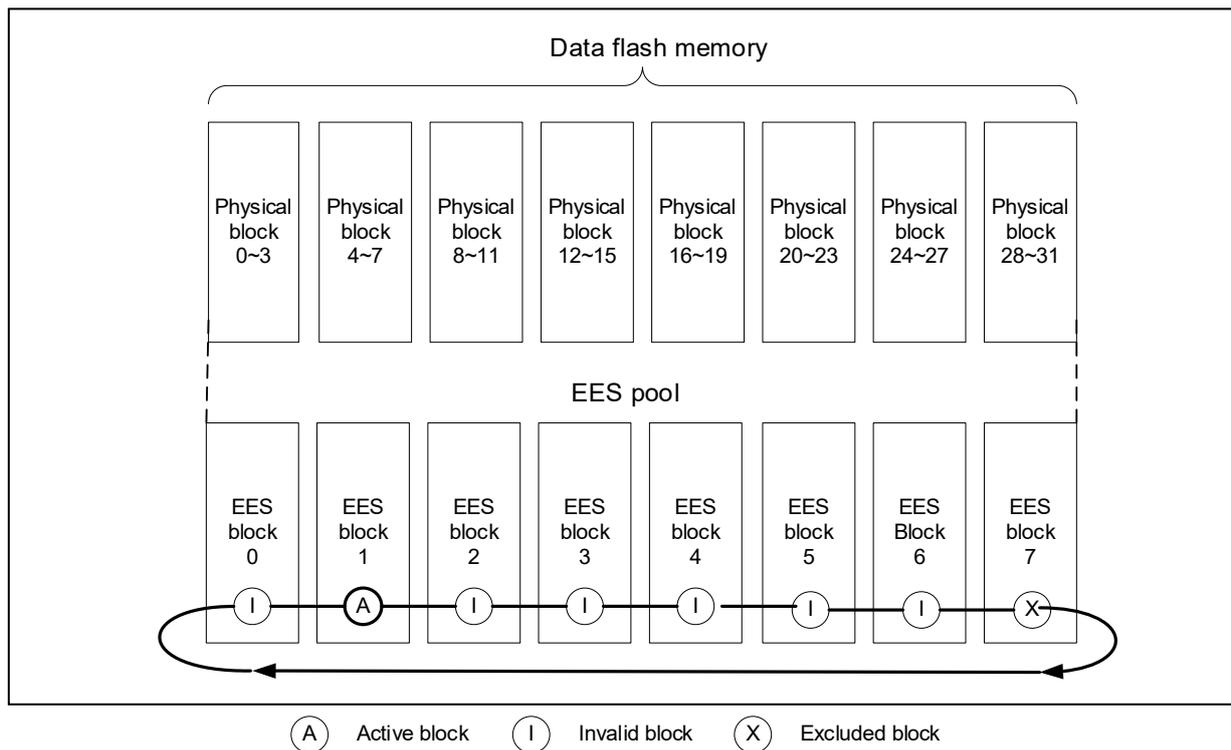
Figure 3-1   EES Pool States Example (The EES block size is set to 1 Kbyte)

The overall life cycle of a block in the EES pool is shown in Figure 3-2. During normal operation, the block switches between active and invalid state. When an error occurs during an access to the EES block, the error EES block is marked as excluded. This block will not enter the lifecycle again. However, the user can try to restore the block by a format of the complete pool which also erases all existing data content.

Caution: An EES block is a virtual block. If at least 1 block of erase blocks (physical block of a 256-byte unit)

of the data flash memory included in an EES block cannot be used by failure, the EES block

including the erase block will be judged to be "Excluded block".

Figure 3-2   Life Cycle of an EES Block

The EES pool has the four states shown below.

Table 3-3   States of the EES Pool

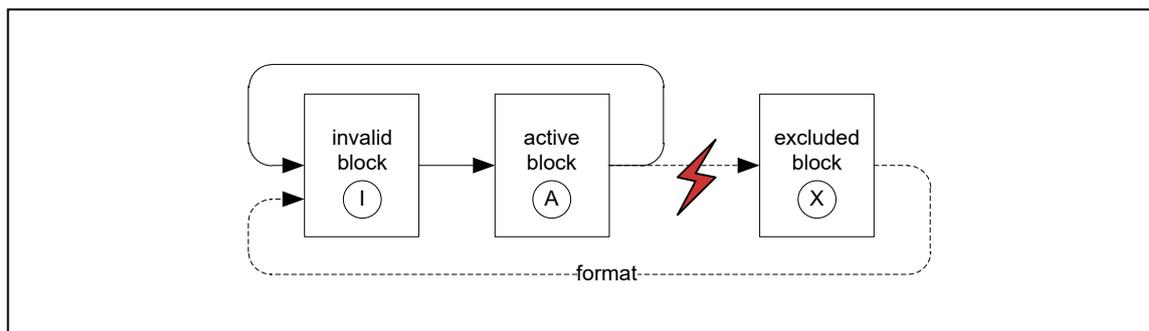| State	Description
Pool operational	This is the usual case during EES operation. All commands are available and can be executed.
Pool full	Free space for data write is insufficient in the active block in use. This state indicates that a refresh needs to be executed.
Pool exhausted	No continuously usable EES block is left. (At least two blocks that are not excluded are necessary for EES operations.)
Pool inconsistent	There is a mismatch in the pool state and the data structure in the EES block does not match the user-set data structure. The EES block is in the undefined state (e.g. no active block is present).

3.3.2   Structure of EES Block

The detailed block structure used by the EES is shown in . In general, an EES block is divided into three utilized areas: the block header, the reference area, and the data area.
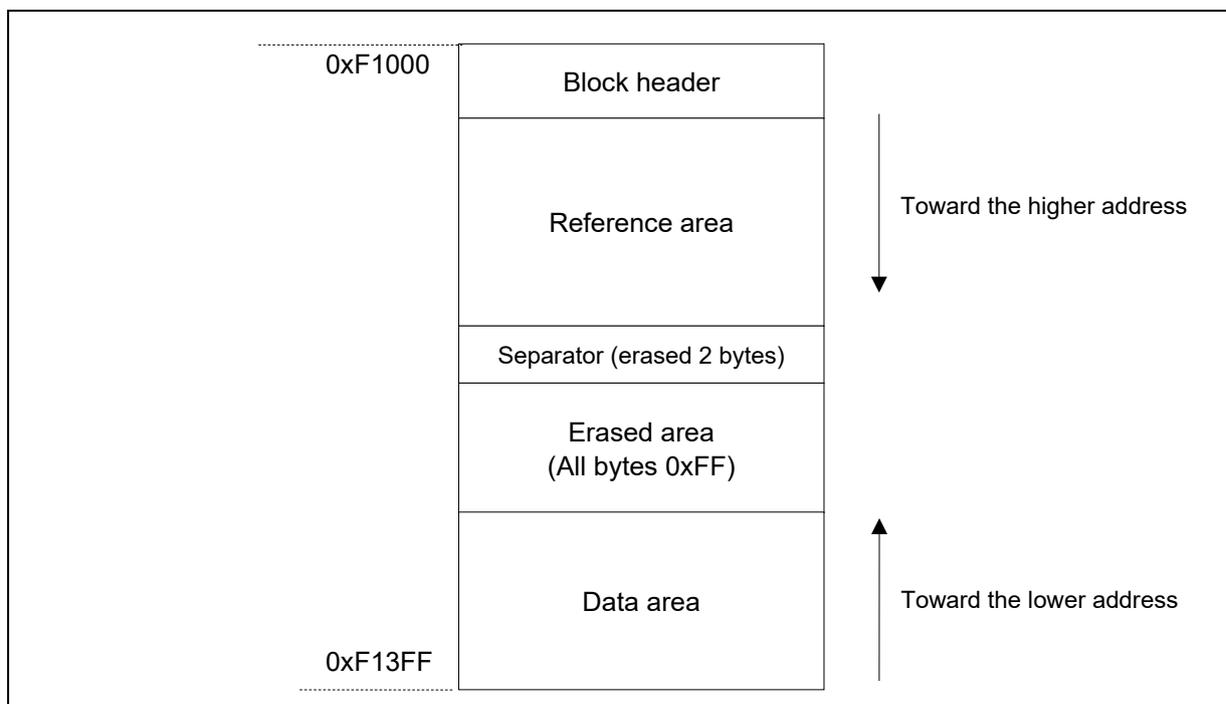
Figure 3-3   EES Block Structure(1 Kbyte）

Table 3-4   Configuration of Each EES Block

Name	Description
Block header	The block header contains all block status information needed for the block management within the EES-pool. It has a fixed size of 8 bytes.
Reference area	The reference area contains reference data which are required for the management of data. When data are written, this area expands in the direction of higher addresses.
Data area	The data area contains user data. When data are written, this area expands in the direction of lower addresses.

Between reference area and data area, there is an erased area. With each EES data update (i.e. the data is written), this area is reduced successively. However, at least 2 bytes of space always remain between reference area and data area for management and separation of these areas. This is indicated by the separator in Figure 3-3.

The EES block header is detailed in section "3.3.3 EES Block Header", while the structure of data stored in the reference and data area are described in section "3.3.4 Structure of Stored Data".

3.3.3   EES Block Header

The structure of the block header is depicted in Figure 3-4. It is composed of 8 bytes, three of which are reserved for the system.

relative byte index within block		
0x0000	A	N
0x0001	B	0xFF - N
0x0002	B'	0x00
0x0003	I	0x00
0x0004	X	0x00
0x0005	-	Reserved
0x0006	-	Reserved
0x0007	-	Reserved

Figure 3-4   Structure of EES Block Header

The block status flags start at the beginning of the block and include the A flag, B flag, B' flag, I flag, and X flag, each of which is 1 byte, for a total of 5 bytes of data. The combination of flags indicates the EES block status.

Figure 3-4 shows the placement status of flags, and Table 3-5 shows the combination status of flags.

Table 3-5   Overviews of Block Status Flags

Block Status Flag					State	Description
A Flag	B Flag	B' Flag	I Flag	X Flag		
0x01	0xFE	0x00	0xFF	0xFF	Active	Currently used block After the R_EES_ENUM_CMD_REFRESH command is executed, the A flag of a new active block is set to 0x02.
0x02	0xFD	0x00	0xFF	0xFF		Currently used block After the R_EES_ENUM_CMD_REFRESH command is executed, the A flag of a new active block is set to 0x03.
0x03	0xFC	0x00	0xFF	0xFF		Currently used block After the R_EES_ENUM_CMD_REFRESH command is executed, the A flag of a new active block is set to 0x01.
0x01	0xFE	0x01 – 0xFE	0xFF	0xFF	Active	Currently used block. However, new data cannot be added because the writing for B' flag is not completed. (Read is possible.) After executing the R_EES_ENUM_CMD_REFRESH command, the A flag of a new active block is set in the order of 0x01, 0x02, 0x03, 0x01,….
0x02	0xFD		0xFF	0xFF		
0x03	0xFC		0xFF	0xFF		
--	0xFF		0xFF	0xFF	Invalid	Invalid block
--			other than 0xFF	0xFF		
--			--	other than 0xFF	Excluded	Excluded block

3.3.4   Structure of Stored Data

The structure of stored data when user data is written to an EES block is shown in the figure below. A data is composed of three parts: the start-of-record (SoR) field and the end-of-record (EoR and EpR') field and the data field. The EES descriptor table can be used to set data for use in the EES. Each data is referred to by an identification number (ID) and can have a size between 1 and 255 bytes. (The exact specification of the format of the EES descriptor can be found in section "4.2 Initial Values to be Set by User".)

Each time data is written, stored data increase in the EES block and multiple units of stored data exist in the EES block, but only the most recent stored data is referenced.
SoR,EoR and EoR' build up the so-called reference data which is required for the management of the data.
The reference data and user data values are stored in different sections of the active block, namely the reference area and the data area, respectively. Figure 3-6 shows the overview of the entire structure of stored data.
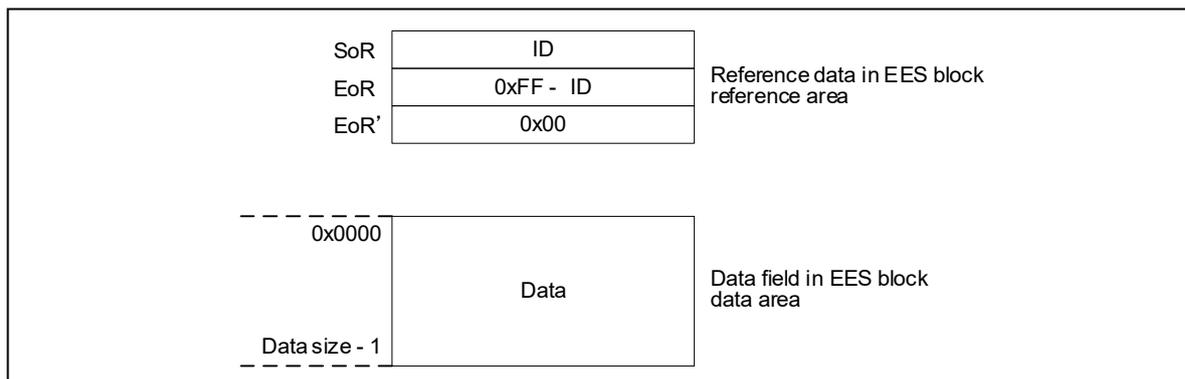
Figure 3-5　Structure of Stored Data

Table 3-6　Description of Each Field of Data Area

Name	Description
SoR field (Start of Record)	The 1 byte SoR field contains the ID of data. This field indicates the start of write processing. Data IDs 0x00 and 0xFF are not used to avoid patterns of erased cells.
EoR field (End of Record)	The 1 byte EoR field contains a 0xFF - data ID value. This field indicates successful end of write processing. If writing does not end normally due to a device reset or other reasons, the corresponding stored data is ignored by the EES.
EoR' field (End of Record')	The 1 byte EoR' field contains the completion of the write process to the EoR field. This field is written to 0x00 after the EoR field has been written. - When the value is between 0x01 - 0xFE, the stored data is valid, but the writing has not been completed. Therefore, the block is treated as a block to which data cannot be added. - When the value is 0xFF, EES judges with the execution result of the writing for the EoR field not having been a normal end.
Data field	The data field contains the user data. The size of user data is 1 to 255 bytes. When data of 2 bytes or more is stored, the smallest address of the data is allocated to the smallest address of the data field (as shown in Figure 3-6).

Data is written to the EES block in the order of SoR -> data field -> EoR -> EoR'. If the value of the EoR field is not written correctly, the immediately previous data becomes valid.

Notes:　1. The total size of the reference data consumed by each stored data is 3 bytes. This should be considered when evaluating the free space in a block before writing the data through the R_EES_GetSpace function.

　　　　2. No checksum is added to user data. If a checksum is needed, add it to user data and check through the user program.

3.3.5　EES Block Overview

Figure 3-6 shows an example of an EES block that contains multiple units of stored data:

- Data ID 0x01 with size = 0x04
- Data ID 0x02 with size = 0x01
- Data ID 0x03 is defined but not written here.
- Data ID 0x04 with size = 0x02

The data have been written in the sequence ID 0x01 -> ID 0x04 -> ID 0x02.

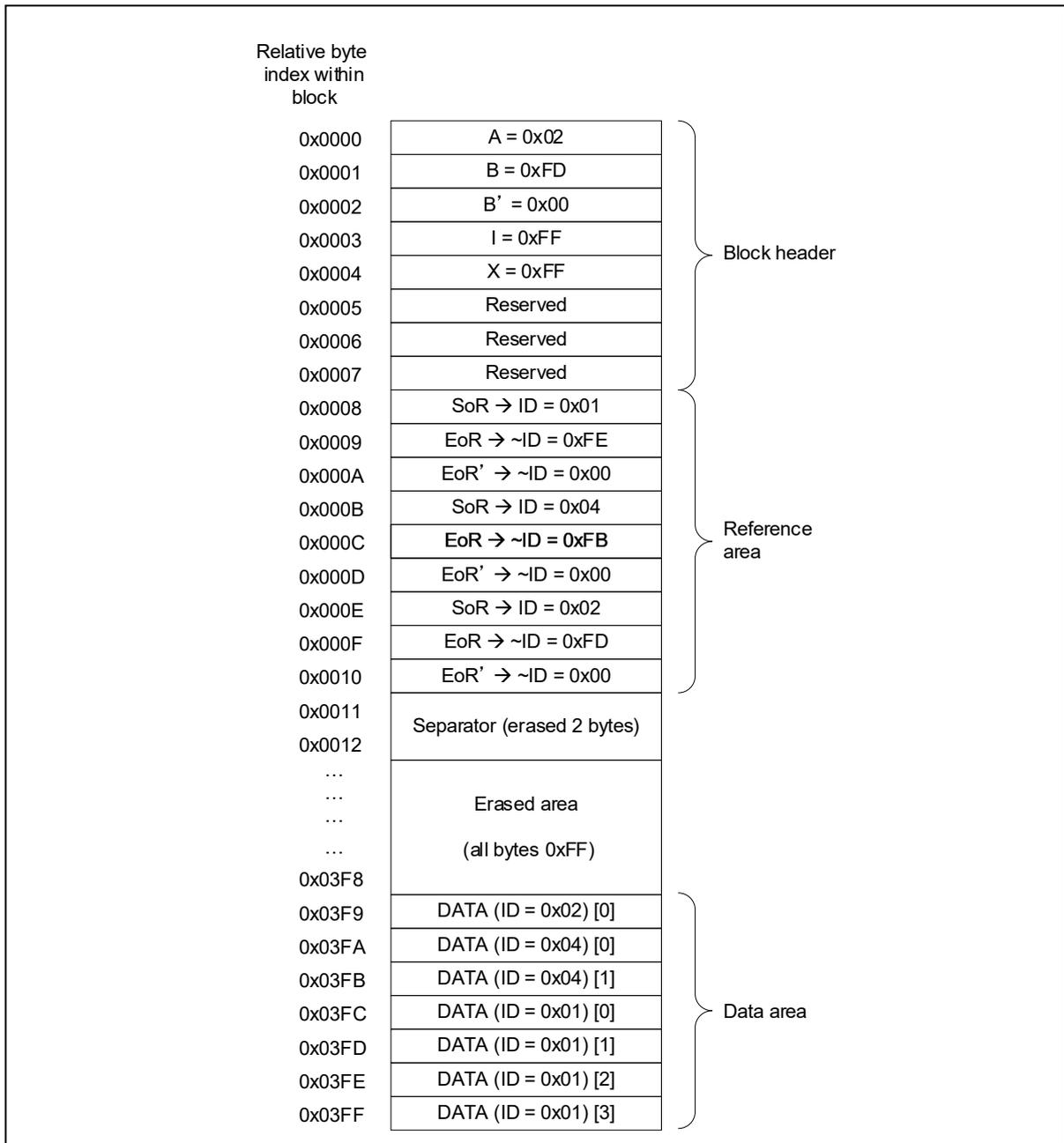In this example, the data with ID 0x03 has not been written yet.

Figure 3-6   Example of an Active EES Block

4.   Using EEPROM Emulation

EEPROM emulation can store a maximum of 254 data items each consisting of 1 to 255 bytes in the flash memory by using three or more blocks (recommended) of flash memory.

EEPROM emulation can be executed by incorporating the EES into a user-created program and executing that program.

4.1   Number of Stored User Data Items and Total User Data Size

The total size of user data that can be used in the EEPROM emulation is limited. The size required for writing all user data to an EES block must be within 1/2 of the block. Therefore, the number of stored data items that can be used differs depending on the size of user data that is actually stored. The following shows how to calculate the size that can be used when actually writing user data, as well as the total user data size.

[Maximum usable size of one block that can be used to write the user data]

Size required for EEPROM emulation block management: 8 bytes
Free space necessary as termination information (separator):   2 bytes

- EES Block size: 1024 bytes
  EES block size: 256 bytes * 4 = 1024 bytes
  Maximum usable size of one block = 1024 bytes - (8 bytes + 2 bytes) = 1014 bytes

- EES Block size: 2048 bytes
  EES block size: 256 bytes * 8 = 2048 bytes
  Maximum usable size of one block = 2048 bytes - (8 bytes + 2 bytes) = 2038 bytes

[Calculating the size for writing each user data item] Note

Size of each written user data item = data size + reference data size (3 bytes)

Note: For details, see 3.3.4 Structure of Stored Data.

[Calculating the basic total user data size]

Basic total size = (user data 1 + 3) + (user data 2 + 3) ... + (user data n + 3)

[Maximum size and recommended size]

Data must be held in one block. Therefore, the maximum size is the maximum usable size of one block but the following relational expression should be met. To enable all data to be updated at least once, we recommend that the data be within the half size of the maximum usable size of one block.

Maximum size: Assumed that the largest data can be updated once after all data have been written.
Recommended size : Assumed that all data can be updated once after all data have been written.

- EES Block size: 1024 bytes
  Maximum size = the basic total user data size + maximum data size + 2 ≤ 1014
  Recommended size = 1014 / 2 = 507 bytes or less

- EES Block size: 2048 bytes
  Maximum size = the basic total user data size + maximum data size + 2 ≤ 2038
  Recommended size = 1038 / 2 = 1019 bytes or less

4.2   Initial Values to be Set by User

As the initial values for the EES, be sure to set the items indicated below. In addition, before executing the EES, be sure to execute the high-speed on-chip oscillator. The high-speed on-chip oscillator must also be activated when using the external clock.

・Number of stored data items, and data size of the identifier (data ID)

< EEPROM emulation soft wear user include file (r_ees_descriptor.h) > [Notes 2, 3]

```
#define R_EES_EXRFD_VALUE_U16_PHYSICAL_BLOCK_SIZE   (256u)
                                    : (1) The size of one block of data flash memory
                                          (Physical block size).
#define R_EES_EXRFD_VALUE_U08_PHYSICAL_BLOCKS_PER_VIRTUAL_BLOCK   (4u)
                                    : (2) The number of data flash memory blocks
                                          (Number of physical blocks) to set in the EES
                                          block(Per virtual block). [Notes 1]
#define R_EES_EXRFD_VALUE_U08_POOL_VIRTUAL_BLOCKS               (4u)
                                    : (3) EES pool size (Number of virtual blocks)
#define R_EES_VALUE_U08_VAR_NO   (8u)    : (4) Number of stored data items
```

Notes 1: The number of data flash memory blocks to set in the EES block (Per virtual block):
         RL78/G22: 2u
         RL78/G23 and RL78/G24: 4u or 8u

< EEPROM emulation software user data definition file (r_ees_user_types.h) > [Notes 3]

```
typedef   uint8_t   type_A[2];              : (5) Data size definition of each data identifier
typedef   uint8_t   type_B[3];                    (data ID).
typedef   uint8_t   type_C[4];
typedef   uint8_t   type_D[5];
typedef   uint8_t   type_E[6];
typedef   uint8_t   type_F[10];
typedef   uint8_t   type_X[20];
typedef   uint8_t   type_Z[255];
```

< EEPROM emulation software user program file (r_ees_descriptor.c)> Note 3

```
__far const uint8_t g_ar_u08_ees_descriptor
[R_EES_VALUE_U08_VAR_NO + 2u] =
{
  (uint8_t)(R_EES_VAR_NO),   /* variable count   */  \
  (uint8_t)(sizeof(type_A)),    /* id=1              */  \
  (uint8_t)(sizeof(type_B)),    /* id=2              */  \
  (uint8_t)(sizeof(type_C)),    /* id=3              */  \
  (uint8_t)(sizeof(type_D)),    /* id=4              */  \
  (uint8_t)(sizeof(type_E)),    /* id=5              */  \
  (uint8_t)(sizeof(type_F)),    /* id=6              */  \
  (uint8_t)(sizeof(type_X)),    /* id=7              */  \
  (uint8_t)(sizeof(type_Z)),    /* id=8              */  \
  (uint8_t)(0x00),              /* zero terminator   */  \
};
```

: (6) Data size of each data identifier (data ID).

Notes 2: The macros that are being used are parameters which are common to the whole EES, so any changes should only be to numerical values.

3: After initializing the EEPROM emulation blocks (after executing the R_EES_ENUM_CMD_FORMAT command), do not change the values. If the values are changed, reinitialize the EES blocks (by executing the R_EES_ENUM_CMD_FORMAT command).

(1) The size of one block of data flash memory (Physical block size).
   Set the size of one block of data flash memory installed (mounted) in the target device.

(2) The number of data flash memory blocks (Number of physical blocks) to set in the EES block.
   Sets the number of data flash memory blocks to use for the EES block.

(3) EES pool size. Note
   The number of blocks in the data flash memory of the target device must be specified as the number of blocks in the EES pool.
   Note: Specify 3 (3 blocks) or a greater value (recommended).

(4) Number of stored data items
   Specify the number of data items to be used in the EEPROM emulation. A value of 1 to 254 can be set.

(5) Data size definition of each data identifier (data ID).
   Defines the data type name for the byte size of each user data. The EES descriptor table reflects the byte size of each user data.

(6) Data size of each data identifier (data ID)

A table to define the data size of each identifier is provided below. This is called an EES descriptor table.

Data to be written must be registered in the EES descriptor table in advance.

__far const uint8_t g_ar_u08_ees_descriptor [Number of stored data items + 2]

R_EES_VALUE_U08_VAR_NO
Byte size of data ID1
Byte size of data ID2
Byte size of data ID3
Byte size of data ID4
Byte size of data ID5
Byte size of data ID6
Byte size of data ID7
Byte size of data ID8
0x00

Figure 4-1   EES Descriptor Table (When there are eight different data items)

・R_EES_VALUE_U08_VAR_NO

User-specified number of data items used in the EES

・Byte size of data IDx

User-specified size of user data (in bytes)

・Termination area (0x00)

Specify 0 as the termination information.

5. User Interface

5.1 Request Structure (st_ees_request_t) Settings

Basic operations such as reading from and writing to the data flash memory are performed by a single function. The function transfers commands and data ID to the EES via the request structure (st_ees_request_t). Furthermore, the EES state and error information are acquired via the request structure (st_ees_request_t).

In subsequent sections, write access to the request structure (st_ees_request_t) from the user is called user write access, and read access to it from the user is called user read access.

Figure 5-1   Request Structure (st_ees_request_t)
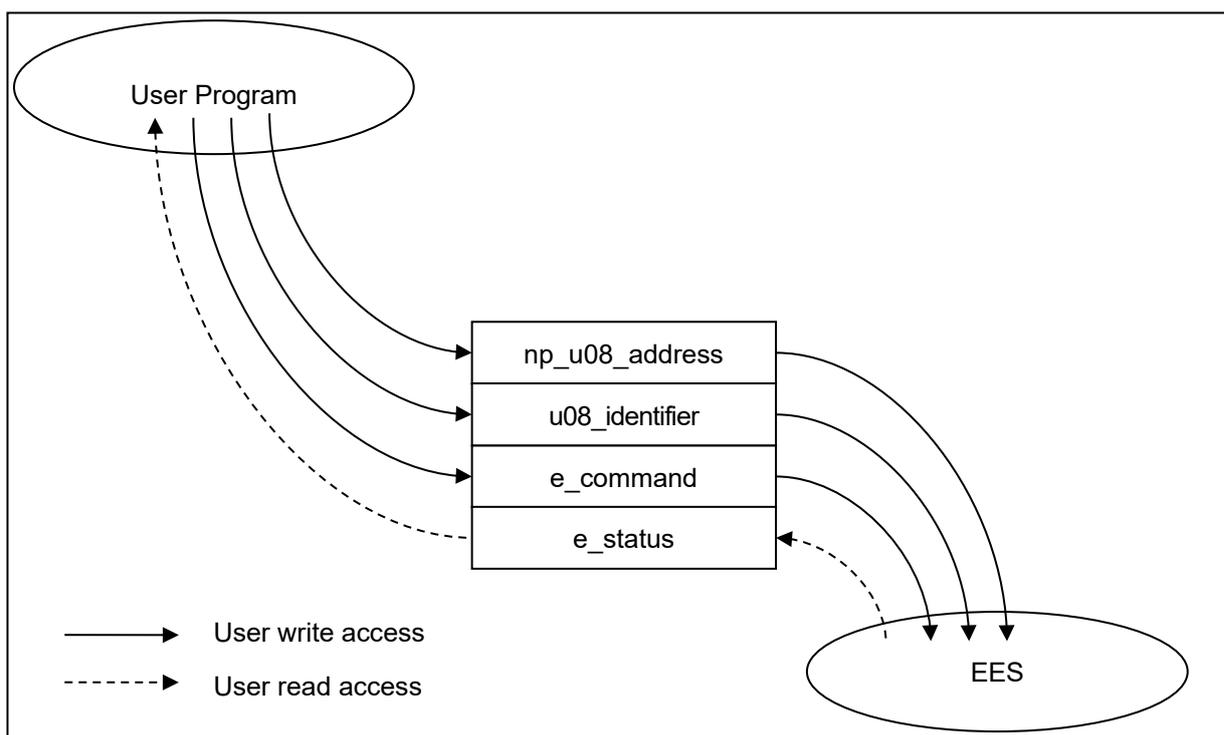
The request structure (st_ees_request_t) is defined in the r_ees_types.h file. It should not be changed by the user.

[Definition of the request structure (st_ees_request_t)]

```
typedef struct st_ees_request
{
  uint8_t __near *      np_u08_address;
  uint8_t               u08_identifier;
  e_ees_command_t   e_command;
  e_ees_ret_status_t   e_status;
} st_ees_request_t;
```
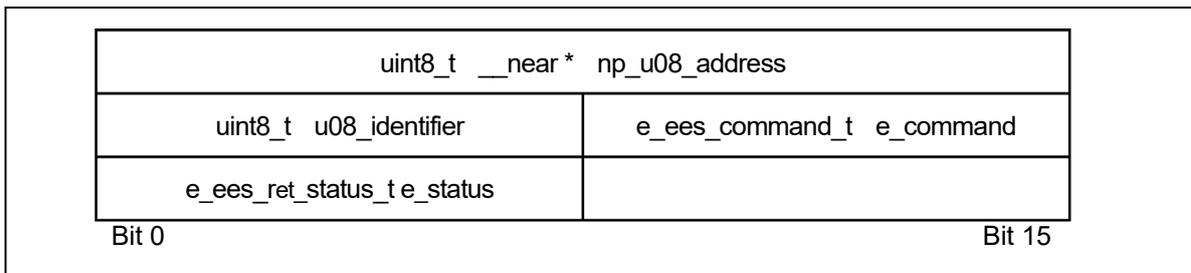
uint8_t __near * np_u08_address	
uint8_t u08_identifier	e_ees_command_t e_command
e_ees_ret_status_t e_status	
Bit 0	Bit 15

Figure 5-2   Alignment of Variables of the Request Structure (st_ees_request_t)

5.1.1   User Write Access

(1) np_u08_address

Specifies a pointer to the start address of the data buffer used for R_EES_ENUM_CMD_WRITE command and R_EES_ENUM_CMD_READ command execution.

Associated command (macro name)	Setting
R_EES_ENUM_CMD_WRITE	Pointer to the start address of the data buffer. Note 1
R_EES_ENUM_CMD_READ	Pointer to the start address of the data buffer. Note 2

Notes 1: Buffer which contains data written by the user
         2: Buffer which contains data read from the data flash memory

(2) u08_identifier

Specify the data ID used for each command. For more information about how to do this, see the description of the R_EES_Execute function in section "5.7 Specifications of API Functions".

Associated command (macro name)	Setting
R_EES_ENUM_CMD_WRITE	ID of write data
R_EES_ENUM_CMD_READ	ID of read data

(3) e_command

Commands to be set in the common executable function.

Associated command (macro name)	Description
R_EES_ENUM_CMD_UNDEFINED	Undefined command (Initial value: It is used only for initialization.)
R_EES_ENUM_CMD_STARTUP	Startup processing
R_EES_ENUM_CMD_WRITE	Write processing
R_EES_ENUM_CMD_READ	Read processing
R_EES_ENUM_CMD_REFRESH	Refresh processing
R_EES_ENUM_CMD_FORMAT	Format processing
R_EES_ENUM_CMD_SHUTDOWN	Shutdown processing

5.1.2   User Read Access

- e_status

EES status and error information. For information about the status and errors which might occur during execution of the functions, see the description of the R_EES_Execute function in section "5.7 Specifications of API Functions"

5.2   List of API Functions and R_EES_Execute Function Commands for the EES

5.2.1   API Functions for the EES

Table 5-1 shows the API functions for EES RL78 Type 01.

Table 5-1   API Functions for EES RL78 Type 01

	API Name	Overview
1	R_EES_Init	Sets the frequency specified by the parameter in the flash memory sequencer and initializes RFD RL78 Type 01.
2	R_EES_Open	EEPROM emulation preparation processing. This function makes the EEPROM emulation executable.
3	R_EES_Close	EEPROM emulation end processing. This function makes the EEPROM emulation un-executable.
4	R_EES_Execute	EEPROM emulation execution function. Each type of processing for performing EEPROM emulation operations is specified for this function as an argument in the command format, and the processing is executed.
5	R_EES_Handler	Continuous EEPROM emulation execution processing. This function is used to check for the completion of processing while allowing processing of EEPROM emulation specified by the R_EES_Execute function to continue.
6	R_EES_GetSpace	Gets the free space of the active block.

5.2.2   Commands for R_EES_Execute Function

Table 5-2 shows commands for R_EES_Execute.

Table 5-2 List of Commands for R_EES_Execute.

	Command Name	Outline
1	R_EES_ENUM_CMD_STARTUP	[Startup Processing] This command checks the block status and sets the system to the EEPROM emulation (data access) valid state (Full Access). If two active blocks exist, the incorrect block is changed to an invalid block. Be sure to execute this command before executing commands other than the R_EES_ENUM_CMD_FORMAT command and make sure that the command finishes normally.
2	R_EES_ ENUM_CMD_WRITE [Note1]	[Write Processing] This command writes the specified data to the EES blocks. * The following arguments must be specified prior to execution. - np_u08_ees_address: Specifies a pointer to the start address of the RAM area where the write data is stored. - u08_ees_identifier: Specifies the data ID of the write data.
3	R_EES_ ENUM_CMD_READ [Note1]	[Read Processing] Read the specified data from an EES block. * The following arguments must be specified prior to execution. - np_u08_ees_address: Specifies a pointer to the start address of the RAM area where the read data is stored. - u08_ees_identifier: Specifies the data ID of the read data.
4	R_EES_ ENUM_CMD_REFRESH [Note1,2]	[Refresh Processing] Copy the latest stored data from the active block (copy source EES block) to the next block (copy destination EES block) in the EES pool after the erase processing. This makes the copy destination block active.
5	R_EES_ ENUM_CMD_FORMAT	[Format Processing] Initialize (erase) everything, including the data recorded in the whole EES pool. Be sure to use this command before using EEPROM emulation for the first time. Note that issuing this command is also necessary to initialize all blocks if a malfunction occurs in an EES block (such as an active block disappearing) or the values in the descriptor table (those which are fixed values that cannot be changed) are modified. Because EEPROM emulation switches to the stopped state (opened) regardless of the results after the processing finishes, execute the R_EES_ENUM_CMD_STARTUP command to continue using EEPROM emulation.
6	R_EES_ ENUM_CMD_SHUTDOWN [Note1]	[Shutdown Processing] Set the EEPROM emulation operation to the stopped state (opened).

Notes 1: Do not execute this command until the R_EES_ENUM_CMD_STARTUP command has finished
   normally.
   2: The erase processing is performed by executing the R_EES_ ENUM_CMD_REFRESH command.

5.2.3   RFD Control API Functions for EES

Table **5-3** shows RFD control API functions for EES.
This function is used internally by EES. It does not need to be used directly by the user.

Table 5-3   **List of RFD Control API Functions for EES**

	API Name	Overview
1	R_EES_EXRFD_Init	Initializes RFD RL78 Type 01.
2	R_EES_EXRFD_Open	Set the data flash control register (DFLCTL) to the state where accessing the data flash memory is permitted(DFLEN = 1).
3	R_EES_EXRFD_Close	Set the data flash control register (DFLCTL) to the state where access to the data flash memory is inhibited (DFLEN = 0). All ongoing EES processing stop.
4	R_EES_EXRFD_Erase	Start erasing the EES block(one virtual block).
5	R_EES_EXRFD_Write	Starts writing to the specified the data flash memory address(one byte).
6	R_EES_EXRFD_BlankCheck	Starts Blank check to the specified the data flash memory address.
7	R_EES_EXRFD_Read	Reads the specified address in the data flash memory.
8	R_EES_EXRFD_Handler	Continues processing of the RFD control function for EES that is executing, and confirms termination.

5.3   State Transitions

To use EEPROM emulation from a user-created program, it is necessary to initialize the EES and execute functions that perform operations such as reading and writing on EES blocks. **Figure 5-3** shows the overall state transitions, and **Figure 5-4** shows an operation flow for using basic features. When using EEPROM emulation, incorporate EEPROM emulation into user-created programs by following this flow.
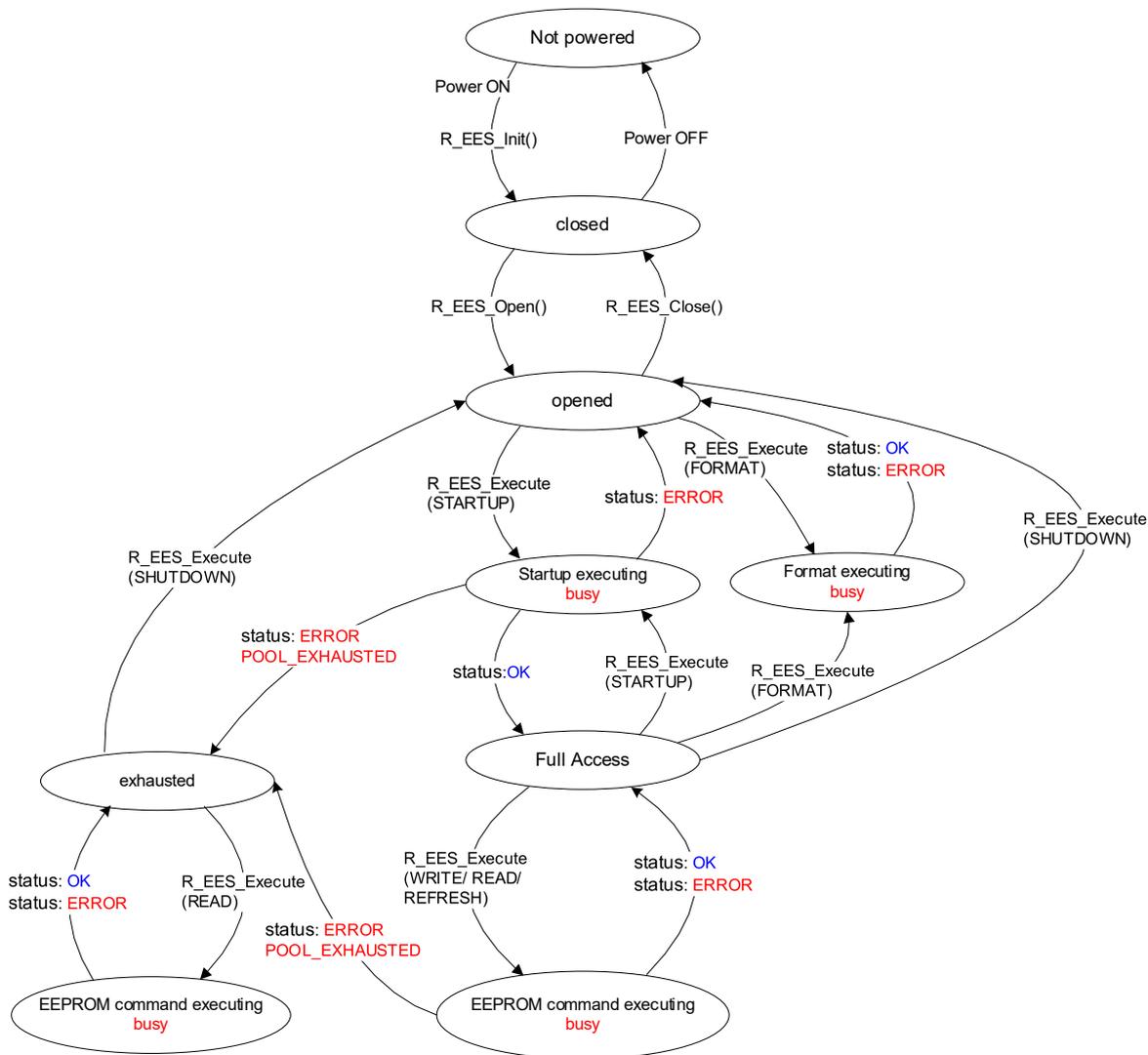

Figure 5-3   State Transitions Diagram

Note 1: Once the R_EES_ENUM_CMD_FORMAT command has started running, execute the
R_EES_Handler function to check for its completion.

[Overview of state transitions diagram]

To use EES to manipulate the data flash memory, it is necessary to execute the provided functions in order to advance the processing.

(1) Not powered

Status is Power Off.

(2) closed

This is the state in which the data to perform EEPROM emulation is initialized by executing the R_EES_Init functions (no ongoing operation to the data flash memory).

Do not execute "operation of the code flash memory", STOP mode or HALT mode while the EEPROM emulation is executing. In the case where they are executed, execute R_EES_Close function and change to a Closed state.

(3) opened

This state is switched to by executing R_EES_Open in the closed state and makes it possible to perform operations on the data flash memory. Even if the R_EES_Close function is executed, do not execute "operation of the code flash memory", STOP mode, or HALT mode until a state changes to "closed".

(4) started

This state is switched to by executing the R_EES_ENUM_CMD_STARTUP command in the opened state and makes it possible to execute EEPROM emulation. Writes and reads that use EEPROM emulation are performed in this state.

(5) exhausted

This state is made from the opened or started state when continuously usable EES blocks have been exhausted during command execution. In this state, only R_EES_ENUM_CMD_READ, and R_EES_ENUM_CMD_SHUTDOWN commands are executable.

(6) busy

This is the state used when executing a specified command. The state that is switched to differ depending on which command is executed and how it terminates.

5.4　Basic Flowchart

Figure 5-4 below shows the basic procedure to perform read and write operations for the data flash by using the EES.
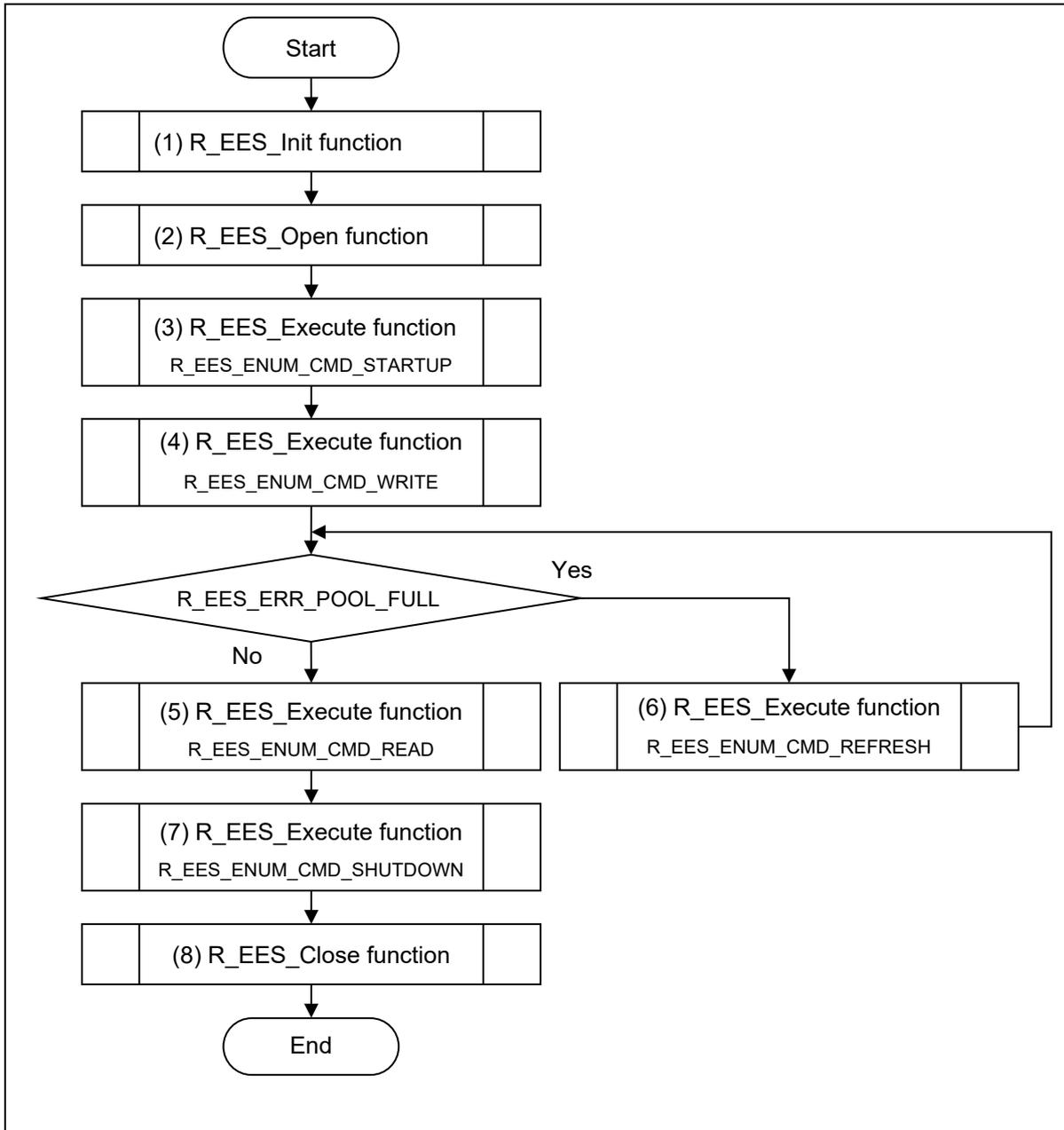

Figure 5-4　Basic Flowchart of EES

Notes 1: When using the EEPROM emulation for the first time, be sure to execute the

R_EES_ENUM_CMD_FORMAT command.

2: This flowchart omits error handling and R_EES_Handler processing after command execution.

[Overview of basic operation flow]

(1) EES initialization processing (R_EES_Init)

Initialize the parameters used by the EES.

(2) EEPROM emulation preparation processing (R_EES_Open)

Set the data flash memory to a state (opened) for which control is enabled to execute EEPROM
emulation.

(3) EEPROM emulation execution start processing (R_EES_Execute: R_EES_ENUM_CMD_STARTUP
command)

Set the system to a state (Full Access) in which EEPROM emulation can be executed.

(4) EEPROM emulation data write processing (R_EES_Execute: R_EES_ENUM_CMD_WRITE command)

Write the specified data to an EES block.

(5) EEPROM emulation data read processing (R_EES_Execute: R_EES_ENUM_CMD_READ command)

Read the specified data from an EES block.

(6) EEPROM emulation refresh processing (R_EES_Execute: R_EES_ENUM_CMD_REFRESH command)

The latest stored data is copied from the active block (source block) to the next block (destination block)
in the EES pool after the erase processing. This makes the copy destination block active.

(7) EEPROM emulation execution stop processing (R_EES_Execute: R_EES_ENUM_CMD_SHUTDOWN
command)

Set the EEPROM emulation operation to the stopped state (opened).

(8)   EEPROM emulation end processing (R_EES_Close)

Set the data flash memory to a state (closed) for which control is disabled to stop EEPROM emulation.

5.5   Command Operation Flowchart

The figure below shows the basic procedure to perform read and write operations for data flash by using the EES.
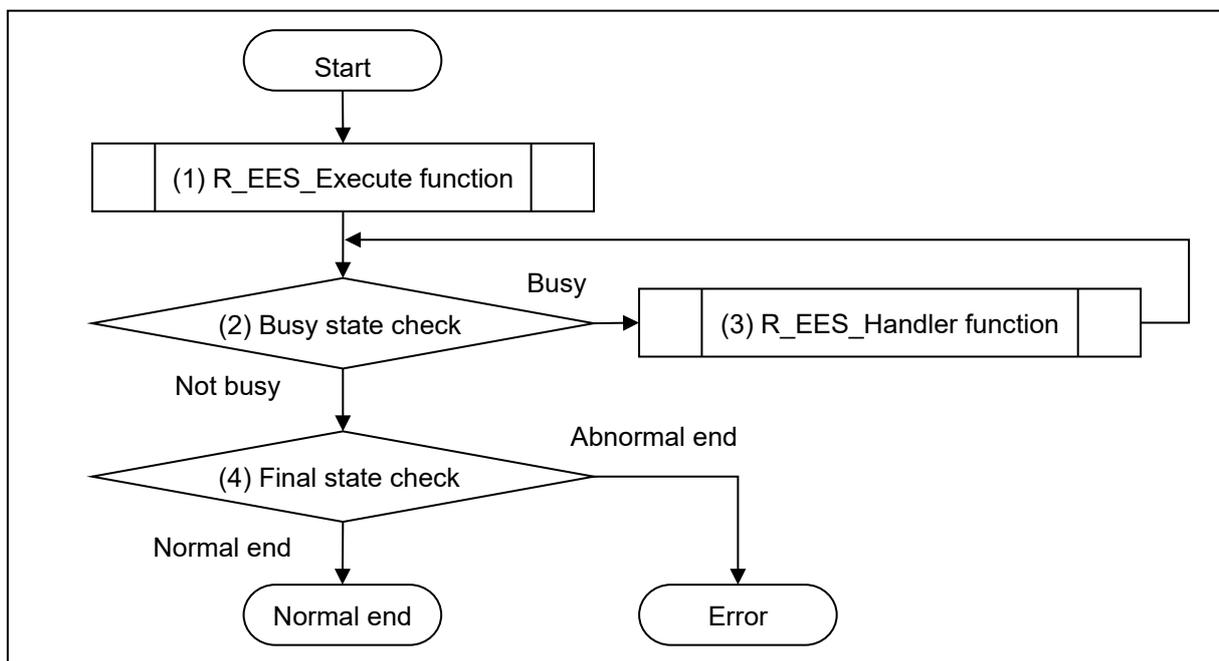

Figure 5-5   Command Operation Flowchart

(1) R_EES_Execute function

Perform operations for the data flash memory.

(2) Busy state check

Check e_status of the request structure (st_ees_request_t).

When e_status is R_EES_ENUM_RET_STS_BUSY, continue the data flash operation. If the value of e_status is other than R_EES_ENUM_RET_STS_BUSY, check the final state.

(3) R_EES_Handler function

Control the EES while it is running. By repeating the execution of the R_EES_Handler function, continue the data flash operation.

(4) Final state check

If the final state is R_EES_ENUM_RET_STS_OK, the operation ends normally. Otherwise, it will be terminated with an error.

5.6   Data Type Definitions

5.6.1   Data Types

Table 5-4 shows the data type definitions in EES RL78 Type 01.

Table 5-4   Data Type Definitions in EES RL78 Type 01

Macro Value	Type	Description
int8_t	signed char	1-byte signed integer
uint8_t	unsigned char	1-byte unsigned integer
int16_t	signed short	2-byte signed integer
uint16_t	unsigned short	2-byte unsigned integer
int32_t	signed long	4-byte signed integer
uint32_t	unsigned long	4-byte unsigned integer
bool	unsigned char	Boolean value (false = 0, true = 1)

Remark: In the C language standard C 99 and later, these data types are defined in "stdint.h" and "stdbool.h".

5.6.2   Global Variables

The following shows the global variables used in EES RL78 Type 01.

(1)   g_ar_u08_ees_descriptor[R_EES_VALUE_U08_VAR_NO + 2u]

Type/Name	uint8_t g_ar_u08_ees_descriptor[]
Default value	(uint8_t)(R_EES_VALUE_U08_VAR_NO), /* variable count */ (uint8_t)(sizeof(type_A)), /* id=1 */ (uint8_t)(sizeof(type_B)), /* id=2 */ (uint8_t)(sizeof(type_C)), /* id=3 */ (uint8_t)(sizeof(type_D)), /* id=4 */ (uint8_t)(sizeof(type_E)), /* id=5 */ (uint8_t)(sizeof(type_F)), /* id=6 */ (uint8_t)(sizeof(type_X)), /* id=7 */ (uint8_t)(sizeof(type_Z)), /* id=8 */ (uint8_t)(0x00u) /* zero terminator */
Description	Stores the data size of each data identifier (Data ID).
Definition file	r_ees_descriptor.c

(2) g_st_ees_exrfd_descriptor

Type/Name	st_ees_exrfd_descriptor_t g_st_ees_exrfd_descriptor
Default value	(uint16_t) R_EES_EXRFD_VALUE_U16_PHYSICAL_BLOCK_SIZE (uint8_t) R_EES_EXRFD_VALUE_U08_PHYSICAL_BLOCKS_PER_VIRTUAL_BLOCK (uint8_t) R_EES_EXRFD_VALUE_U08_POOL_VIRTUAL_BLOCKS

Description	Contains settings that configure the EES pool
	・uint16_t u16_ees_physical_block_size;
	    The size of one block of data flash memory (Physical block size).
	     Example: This value is fixed for RL78/G2x. (256u)
	・uint8_t u08_ees_physical_blocks_per_virtual_block;
	    The number of data flash memory blocks to set in the EES block (Number of physical blocks).
	     Example: When setting 512 bytes for EES block. Number of data flash memories. (2u)
	     Example: When setting 1024 bytes for EES block. Number of data flash memories. (4u)
	・uint8_t u08_ees_pool_virtual_blocks;
	    EES pool size (Number of virtual blocks）
	    Example: Total EES blocks. (4u)

Definition file	r_ees_descriptor.c

(3) g_ar_u16_ram_ref_table[R_EES_VALUE_U08_VAR_NO]

Type/Name	uint16_t g_ar_u16_ram_ref_table[]
Default value	-
Description	Contains reference data for each data identifier (Data ID).
Definition file	r_ees_descriptor.c

5.6.3　Enumerations

- e_ees_command (enumerated-type variable name: e_ees_command_t)
  EES executable command

Symbol Name	Value	Description
R_EES_ENUM_CMD_UNDEFINED	0x00	Undefined command (Initial value)
R_EES_ENUM_CMD_STARTUP	0x01	Startup processing
R_EES_ENUM_CMD_WRITE	0x02	Write processing
R_EES_ENUM_CMD_READ	0x03	Read processing
R_EES_ENUM_CMD_REFRESH	0x04	Refresh processing
R_EES_ENUM_CMD_FORMAT	0x06	Format processing
R_EES_ENUM_CMD_SHUTDOWN	0x07	Shutdown processing

- e_ees_ret_status (enumerated-type variable name: e_ees_ret_status_t)
- EES return values

Symbol Name	Value	Description
R_EES_ENUM_RET_STS_OK	0x00	Normal end
R_EES_ENUM_RET_STS_BUSY	0x01	Busy
R_EES_ENUM_RET_ERR_CONFIGURATION	0x82	EES configuration error
R_EES_ENUM_RET_ERR_INITIALIZATION	0x83	EES initialization error
R_EES_ENUM_RET_ERR_ACCESS_LOCKED	0x84	EEPROM emulation lock error
R_EES_ENUM_RET_ERR_PARAMETER	0x85	Parameter error
R_EES_ENUM_RET_ERR_WEAK	0x86	Weak error
R_EES_ENUM_RET_ERR_REJECTED	0x87	Reject error
R_EES_ENUM_RET_ERR_NO_INSTANCE	0x88	No instance
R_EES_ENUM_RET_ERR_POOL_FULL	0x89	Pool full error
R_EES_ENUM_RET_ERR_POOL_INCONSISTENT	0x8A	EES block Inconsistency error
R_EES_ENUM_RET_ERR_POOL_EXHAUSTED	0x8B	EES block exhaustion error
R_EES_ENUM_RET_ERR_INTERNAL	0x8C	Internal error
R_EES_ENUM_RET_ERR_FLASH_SEQ	0x8D	Flash sequencer error

- e_ees_exrfd_ret_status (enumerated-type variable name: e_ees_exrfd_ret_status_t)

  These enumeration types are used internally by EES. It does not need to be used directly by the user.

  RFD control functions for EES return values

Symbol Name	Value	Description
R_EES_EXRFD_ENUM_RET_STS_OK	0x00	Normal end
R_EES_EXRFD_ENUM_RET_STS_BUSY	0x01	Busy
R_EES_EXRFD_ENUM_RET_ERR_CONFIGURATION	0x10	Configuration error
R_EES_EXRFD_ENUM_RET_ERR_INITIALIZATION	0x11	Initialization error
R_EES_EXRFD_ENUM_RET_ERR_REJECTED	0x12	Reject error
R_EES_EXRFD_ENUM_RET_ERR_PARAMETER	0x13	Parameter error
R_EES_EXRFD_ENUM_RET_ERR_INTERNAL	0x14	Internal error
R_EES_EXRFD_ENUM_RET_ERR_MODE_MISMATCHED	0x20	Mode mismatch error
R_EES_EXRFD_ENUM_RET_ERR_CFDF_SEQUENCER	0x21	Code/data flash area sequencer error
R_EES_EXRFD_ENUM_RET_ERR_ERASE	0x22	Erase operation error
R_EES_EXRFD_ENUM_RET_ERR_BLANKCHECK	0x23	Blank check operation error
R_EES_EXRFD_ENUM_RET_ERR_WRITE	0x24	Write operation error

5.7   Specifications of API Functions

This section describes the detailed specifications of the API functions of EEPROM Emulation Software (EES) RL78 Type 01.

There are some prerequisites for using the API functions of EES RL78 Type 01 to reprogram the data flash memory. If the prerequisites are not satisfied, execution of the API functions may result in indeterminate operation.

Prerequisites:

- Execute the R_EES_Init function once before starting the use of EES functions.
- The high-speed on-chip oscillator must be active while self-programming is in progress. Execute API functions of EES RL78 Type 01 only while the high-speed on-chip oscillator is active.
- To control the data flash memory, execute API functions of EES RL78 Type 01 while access to the data flash memory is enabled. For the method of enabling access to the data flash memory, refer to **"User's Manual: Hardware"** of a target device.

The following shows the format for describing the specifications of API functions.

Description format:

Information:

Syntax	Syntax for calling this function from a C-language program	
Reentrancy	Reentrant or Non-reentrant	
Parameters (IN)	Input parameters for this function	Parameter [Value, range, meaning of the parameter, etc.]
Parameters (IN/OUT)	Input/output parameters for this function	Parameter [Value, range, meaning of the parameter, etc.]
Parameters (OUT)	Output parameters for this function	Parameter [Value, range, meaning of the parameter, etc.]
Return Value	Type of the return value from this function (Enumerated type, pointer type, etc.)	Enumerator (constant value) of the return value: Value [Meaning of the constant: Detailed description]
		Enumerator (constant value) of the return value: Value [Meaning of the constant: Detailed description]
Description	Overview of function	
Preconditions	Overview of preconditions	
Remarks	Special notes on this function	

Details of Specifications:

The operation of this function is described.

Notes:

Conditions of usage or restrictions on this function are described.

5.7.1   Specifications of API Functions for EES RL78 Type 01

This section describes the API functions used for EES RL78 Type 01.

5.7.1.1   R_EES_Init

Information:

Syntax	R_EES_FAR_FUNC e_ees_ret_status_t R_EES_Init(uint8_t i_u08_cpu_frequency);	
Reentrancy	Non-reentrant	
Parameters (IN)	uint8_t i_u08_cpu_frequency	CPU operating frequency [1 - 32(MHz)] (Target: All devices) [48 (MHz)] (Target: RL78/G24)
Parameters (IN/OUT)	N/A	
Parameters (OUT)	N/A	
Return Value	e_ees_ret_status_t	R_RFD_ENUM_RET_STS_OK: 0x00 [Normal end] R_EES_ENUM_RET_ERR_CONFIGURATION: 0x82 [EES configuration error]
Description	Initializes internal data and variables and checks the descriptor configuration.	
Preconditions	Execute this function while the high-speed on-chip oscillator is active.	
Remarks	Execute this function once before starting the use of EES functions.	

Details of Specifications:

- Set the parameter (CPU operating frequency) to the R_EES_EXRFD_Init function and execute it.

Notes:

- When the configuration for executing the EEPROM emulation such as EES pool or EES block size is abnormal, the return value will return a EES configuration error (R_EES_ENUM_RET_ERR_CONFIGURATION).
- The high-speed on-chip oscillator needs to be kept active while EEPROM emulation is in progress. Execute this function while the high-speed on-chip oscillator is active.

  * EES RL78 Type 01 does not activate or check the high-speed on-chip oscillator.
- For the parameter (i_u08_cpu_frequency), specify the integer obtained by rounding up the fraction of the CPU operating frequency that is actually used in the microcontroller.
  (Example: When the CPU operates at 4.5 MHz, specify 5 in this initialization function.)

  When the CPU operates at a frequency lower than 4 MHz, a value of 1 MHz, 2 MHz, or 3 MHz can be used but a non-integer value such as 1.5 MHz cannot be used.

  The frequency specified in the parameter (i_u08_cpu_frequency) should be the actual frequency at which the CPU operates during flash memory reprogramming; it is not necessarily that the frequency of the high-speed on-chip oscillator should be specified.

  - If the specified frequency differs from the actual CPU operating frequency, the subsequent operation is indeterminate. In this case, even if flash memory reprogramming is completed, the written data value and data retention period may not be guaranteed.
    * For the range of the CPU operating frequency, refer to "User's Manual: Hardware" of a target device.

5.7.1.2   R_EES_Open

Information:

Syntax	R_EES_FAR_FUNC e_ees_ret_status_t R_EES_Open(void);	
Reentrancy	Non-reentrant	
Parameters (IN)	N/A	
Parameters (IN/OUT)	N/A	
Parameters (OUT)	N/A	
Return Value	e_ees_ret_status_t	R_EES_ENUM_RET_STS_OK: 0x00 [Normal end] R_EES_ENUM_RET_ERR_ REJECTED: 0x87 [Reject error]
Description	EEPROM emulation preparation processing. This function makes the EEPROM emulation executable.	
Preconditions	R_EES_Init function must have finished normally.	
Remarks	-	

Details of Specifications:

- Execute the R_EES_EXRFD_Open function to make the data flash memory accessible.

Notes:

- When the R_EES_Init function is not executed and the internal variable has not been initialized, the return value will return a reject error (R_EES_ENUM_RET_ERR_REJECTED).

5.7.1.3 R_EES_Close

Information:

Syntax	R_EES_FAR_FUNC e_ees_ret_status_t R_EES_Close(void);	
Reentrancy	Non-reentrant	
Parameters (IN)	N/A	
Parameters (IN/OUT)	N/A	
Parameters (OUT)	N/A	
Return Value	e_ees_ret_status_t	R_EES_ENUM_RET_STS_OK: 0x00 [Normal end]
Description	EEPROM emulation end processing. This function makes the EEPROM emulation un-executable.	
Preconditions	-	
Remarks	-	

Details of Specifications:

- Executes the R_EES_EXRFD_Close function and finishes the EEPROM emulation.

Notes:

- If EEPROM emulation was executed, the R_EES_ENUM_CMD_SHUTDOWN command must be used to set EEPROM emulation to the stopped state (the open state).

5.7.1.4 R_EES_Execute

Information:

Syntax	R_EES_FAR_FUNC void R_EES_Execute(st_ees_request_t __near * ionp_st_ees_request);	
Reentrancy	Non-reentrant	
Parameters (IN)	N/A	
Parameters (IN/OUT)	st_ees_request_t __near * ionp_st_ees_request	Pointer to the request structure (st_ees_request_t)
Parameters (OUT)	N/A	
Return Value	N/A	
Description	EEPROM emulation execution function. Each type of processing for performing EEPROM emulation operations is specified for this function as an argument in the command format, and the processing is executed.	
Preconditions	R_EES_Init and R_EES_Open function must have finished normally.	
Remarks	-	

Details of Specifications:

- Starts processing of the command set in the Request structure.

Notes:

- The R_EES_Execute function starts command processing and then immediately returns the control to the user program. The command processing is continued by executing the R_EES_Handler function. Therefore, the R_EES_Handler function must be executed continuously until the command processing is completed.
- Execute the repeat the R_EES_Handler function while the e_status of the Request structure(st_ees_request_t) is R_EES_ENUM_RET_STS_BUSY.
- It is not allowed to call R_EES_Execute function in an interrupt service routine.

Command Execution States of R_EES_Execute/R_EES_Handler (e_ees_ret_status_t) (1/2)

Command Execution Status	Category	Description	Corresponding Commands
R_EES_ENUM_RET_STS_OK	Meaning	Normal end	All commands
	Cause	None	
	Action to be taken	None	
R_EES_ENUM_RET_STS_BUSY	Meaning	A command is being executed.	Commands other than R_EES_ENUM_CMD_SHUTDOWN
	Cause	None	
	Action to be taken	Keep calling the R_EES_Handler function until the status changes.	
R_EES_ENUM_RET_ERR_INITIALIZATION	Meaning	Initialization error	All commands
	Cause	R_EES_Init, and R_EES_Open functions have not been finished normally.	
	Action to be taken	Normally finish the R_EES_Init, and R_EES_Open functions.	
R_EES_ENUM_RET_ERR_ACCESS_LOCKED	Meaning	EEPROM emulation lock error	Commands other than R_EES_ENUM_CMD_STARTUP and R_EES_ENUM_CMD_FORMAT.
	Cause	EEPROM emulation cannot be executed.	
	Action to be taken	Make sure that the R_EES_ENUM_CMD_STARTUP command has finished normally.	
R_EES_ENUM_RET_ERR_PARAMETER	Meaning	Parameter error	All commands
	Cause	An incorrect command parameter has been specified.	
	Action to be taken	Check the specified parameter.	
R_EES_ENUM_RET_ERR_WEAK	Meaning	Found weak data in the active block header or instances.	R_EES_ENUM_CMD_STARTUP
	Cause	Write processing an active block header or stored data may have been interrupted.	
	Action to be taken	Execute the R_EES_ENUM_CMD_REFRESH command.	
R_EES_ENUM_RET_ERR_REJECTED	Meaning	Reject error	All commands
	Cause	A different command is being executed.	
	Action to be taken	Call the R_EES_Handler function to terminate the ongoing command.	

Command Execution States of R_EES_Execute/R_EES_Handler (e_ees_ret_status_t) (2/2)

Command Execution Status	Category	Description	Corresponding Commands
R_EES_ENUM_RET_ERR_ NO_INSTANCE	Meaning	No-write-data error	R_EES_ENUM_CMD_ READ
	Cause	The specified identifier data has not been written.	
	Action to be taken	Write data to the identifier specified using the R_EES_ENUM_CMD_WRITE command.	
R_EES_ENUM_RET_ERR_ POOL_FULL	Meaning	Pool full error	R_EES_ENUM_CMD_ WRITE
	Cause	There is no area that can be used to write the data.	
	Action to be taken	Execute the R_EES_ENUM_CMD_REFRESH command and restart writing data.	
R_EES_ENUM_RET_ERR_ POOL_INCONSISTENT	Meaning	EES block inconsistency error	R_EES_ENUM_CMD_ STARTUP
	Cause	An EES block has the undefined state (such as there are no active blocks).	
	Action to be taken	Execute the R_EES_ENUM_CMD_FORMAT command to initialize the EES blocks.	
R_EES_ENUM_RET_ERR_ POOL_EXHAUSTED	Meaning	EES block exhaustion error	R_EES_ENUM_CMD_ STARTUP R_EES_ENUM_CMD_ FORMAT R_EES_ENUM_CMD_ REFRESH R_EES_ENUM_CMD_ WRITE
	Cause	There are no more EES blocks that can be used to continue.	
	Action to be taken	Stop EEPROM emulation. You can try restoration by executing the R_EES_ENUM_CMD_FORMAT command (erasing all existing data) or read existing data	
R_EES_ENUM_RET_ERR_ INTERNAL	Meaning	Internal error	Commands other than R_EES_ENUM_CMD_ SHUTDOWN
	Cause	An unexpected error has occurred.	
	Action to be taken	Exit the EEPROM emulation. Check the device state.	
R_EES_ENUM_RET_ERR_ FLASH_SEQ	Meaning	Flash area sequencer error	Commands other than R_EES_ENUM_CMD_ SHUTDOWN
	Cause	EES failed to change flash memory mode or start flash sequencer.	
	Action to be taken	The EES should be stopped. Check whether flash memory operation using RFD RL78 Type 01 is executed besides operation of an EEPROM emulation.	

RENESAS

5.7.1.5 R_EES_Handler

Information:

Syntax	R_EES_FAR_FUNC void R_EES_Handler(void);	
Reentrancy	Non-reentrant	
Parameters (IN)	N/A	
Parameters (IN/OUT)	N/A	
Parameters (OUT)	N/A	
Return Value	N/A	
Description	Continuous EEPROM emulation execution processing. This function is used to check for the completion of processing while allowing processing of EEPROM emulation specified by the R_EES_Execute function to continue.	
Preconditions	R_EES_Init and R_EES_Open function must have finished normally.	
Remarks	-	

Details of Specifications:

- Continues processing the EEPROM emulation initiated by the R_EES_Execute function.

Notes:

- While "e_status" of the request structure (st_ees_request_t) is R_EES_ENUM_RET_STS_BUSY, execute this function repeatedly.
- It is not allowed to call R_EES_Handler() in an interrupt service routine.
- The command execution status of the R_EES_Handler function is set for the "st_ees_request_t * ionp_st_ees_request" used as an argument of the R_EES_Execute function. Therefore, when using the R_EES_Handler function, do not free the "st_ees_request_t * ionp_st_ees_request" variable.

5.7.1.6 R_EES_GetSpace

Information:

Syntax	R_EES_FAR_FUNC e_ees_ret_status_t R_EES_GetSpace(uint16_t __near * onp_u16_space);	
Reentrancy	Non-reentrant	
Parameters (IN)	N/A	
Parameters (IN/OUT)	N/A	
Parameters (OUT)	uint16_t __near * onp_u16_space	Pointer to variable that contains free space information for the current active block.
Return Value	e_ees_ret_status_t	R_EES_ENUM_RET_STS_OK : 0x00 [Normal end] R_EES_ENUM_RET_ERR_INITIALIZATION : 0x83 [EES initialization error] R_EES_ENUM_RET_ERR_ACCESS_LOCKED: 0x84 [EEPROM emulation lock error] R_EES_ENUM_RET_ERR_REJECTED: 0x87 [Reject error]
Description	Gets the free space of the active block.	
Preconditions	R_EES_Init and R_EES_Open function must have finished normally. R_EES_Execute function and the R_EES_ENUM_CMD_STARTUP command must be executed successfully before.	
Remarks		

Details of Specifications:

- Calculate the free space of the active block.

Notes:

- When the R_EES_Init function is not executed and the internal variable has not been initialized, the return value will return a EES initialization error (R_EES_ENUM_RET_ERR_INITIALIZATION).
- When the R_EES_ENUM_CMD_STARTUP command does not finish normally with the R_EES_Execute function, the return value will return a EEPROM emulation lock error (R_EES_ENUM_RET_ERR_ACCESS_LOCKED).
- When the R_EES_Execute function is executing a EES command, the return value will return a Reject error (R_EES_ENUM_RET_ERR_REJECTED).
- In case the EES pool is exhausted the returned space value will always be 0x0000.
- When the write operation of the "active block header" or "stored data written" may have been interrupted, 0x0000 is returned to the free space.
- When an error value is returned, the free space information is not collected.

5.7.2 RFD Control API Functions for EES

This section describes the RFD control API functions for EES. These functions are called from the EES control function. Do not call it directly from a user program.

Information:

Syntax	R_EES_FAR_FUNC e_exrfd_ret_status_t R_EES_EXRFD_Init(
	uint8_t i_u08_cpu_frequency);
Description	Initializes RFD RL78 Type 01.

Information:

Syntax	R_EES_FAR_FUNC e_ees_exrfd_ret_status_t R_EES_EXRFD_Open(void);
Description	Set the data flash control register (DFLCTL) to the state where accessing the data flash memory is permitted(DFLEN = 1).

Information:

Syntax	R_EES_FAR_FUNC e_ees_exrfd_ret_status_t R_EES_EXRFD_Close(void);
Description	Set the data flash control register (DFLCTL) to the state where access to the data flash memory is inhibited (DFLEN = 0). All ongoing EES processing stop.

Information:

Syntax	R_EES_FAR_FUNC e_ees_exrfd_ret_status_t R_EES_EXRFD_Erase(
	uint8_t i_u08_virtual_block_number);
Description	Start erasing the EES block(one virtual block).

Information:

Syntax	R_EES_FAR_FUNC e_ees_exrfd_ret_status_t R_EES_EXRFD_Write(
	uint16_t i_u16_offset_addr,
	uint8_t __near * inp_u08_write_data,
	uint16_t i_u16_size);
Description	Starts writing to the specified the data flash memory address(one byte).

Information:

Syntax	R_EES_FAR_FUNC e_ees_exrfd_ret_status_t R_EES_EXRFD_BlankCheck(
	uint16_t i_u16_offset_addr,
	uint16_t i_u16_size);
Description	Starts Blank check to the specified the data flash memory address.

Information:

Syntax	R_EES_FAR_FUNC e_ees_exrfd_ret_status_t R_EES_EXRFD_Read(
	uint16_t i_u16_offset_addr,
	uint8_t __near * onp_u08_read_data,
	uint16_t i_u16_size);
Description	Reads the specified address in the data flash memory.

Information:

Syntax	R_EES_FAR_FUNC e_ees_exrfd_ret_status_t R_EES_EXRFD_Handler(void);
Description	Continues processing of the RFD control function for EES that is executing, and confirms termination.

Information:

Syntax	static R_EES_FAR_FUNC e_ees_exrfd_ret_status_t
	r_ees_exrfd_get_seq_error_status(void);
Description	Obtain the execution result from the flash memory sequencer.

Information:

Syntax	static R_EES_FAR_FUNC e_ees_exrfd_ret_status_t r_ees_exrfd_finish_state(void);
Description	Sets the RFD control functions for EES to the end status.

Information:

Syntax	static R_EES_FAR_FUNC e_ees_exrfd_ret_status_t
	r_ees_exrfd_check_cmd_executable(void);
Description	Check the status and flags of the RFD control functions for EES.

Information:

Syntax	static R_EES_FAR_FUNC bool r_ees_exrfd_is_valid_byte_parameter(
	uint16_t i_u16_offset_addr,
	uint16_t i_u16_size);
Description	Check the parameters used by the RFD Control functions for EES.

Information:

Syntax	static R_EES_FAR_FUNC void r_ees_exrfd_clear_cmd_workarea(void);
Description	Clears the data area used by the RFD control functions for EES.

Information:

Syntax	static R_EES_FAR_FUNC void r_ees_exrfd_blankcheck_byte_req(
	uint32_t i_u32_start_addr,
	uint16_t i_u16_size);
Description	Starts Blank check to the specified the data flash memory address

5.7.3   Internal Functions for the EES

This section describes the functions used by the EES functions. These functions are internal functions called from the EES functions. Do not call it directly from a user program.

Information:

Syntax	R_EES_FAR_FUNC bool r_ees_is_valid_configuration(void);
Description	Check the EES configuration and initialize the internal status.

Information:

Syntax	R_EES_FAR_FUNC bool r_ees_is_valid_requester(st_ees_request_t __near * ionp_st_ees_request);
Description	Check "request structure" and "EES status" and update internal status.

Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_startup_state_00(void); ～ R_EES_FAR_FUNC void r_ees_fsm_startup_state_09(void);
Description	Updates the internal status for startup processing.

Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_write_state_00(void); ～ R_EES_FAR_FUNC void r_ees_fsm_write_state_04(void);
Description	Updates the internal status for write processing.

Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_read_state_00(void); ～ R_EES_FAR_FUNC void r_ees_fsm_read_state_01(void);
Description	Updates the internal status for read processing.

Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_refresh_state_00(void); ～ R_EES_FAR_FUNC void r_ees_fsm_refresh_state_17(void);
Description	Updates the internal status for refresh processing.

Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_format_state_00(void); ～ R_EES_FAR_FUNC void r_ees_fsm_format_state_11(void);
Description	Updates the internal status for format processing.

Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_shutdown_state_00(void);
Description	Execute the shutdown processing of the EEPROM emulation.

Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_exrfd_cmd_erase_state_00(void);
Description	Start the erase processing.

Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_exrfd_cmd_bw_state_00(void);
Description	Starts the blank check and write processing.

Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_exrfd_cmd_inner_blankcheck_state_00(void);
Description	Start internal processing of the blank check.

Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_exrfd_cmd_write_state_00(void);
Description	Start the write processing.

Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_exrfd_cmd_inner_write_state_00(void);
Description	Start internal processing of the write.

Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_exrfd_cmd_read_state_00(void);
Description	Start the read processing.

Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_exrfd_cmd_state_01(void);
Description	Proceed with the internal processing of the executed RFD control functions for EES.

Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_exit_state(void);
Description	Dummy processing.

Information:

Syntax	static R_EES_FAR_FUNC uint8_t r_ees_calculate_next_a_flag(uint8_t i_u08_a_flag_value);
Description	Calculates the value of the A flag.

Information:

Syntax	static R_EES_FAR_FUNC void r_ees_fsm_finish_command(void);
Description	Terminates the execution command.

Information:

Syntax	static R_EES_FAR_FUNC void r_ees_fsm_swap_acvive_block_info(void);
Description	Swaps the active block information.

Information:

Syntax	static R_EES_FAR_FUNC bool r_ees_fsm_exrfd_cmd_detect_fatal_error(e_ees_exrfd_ret_status_t i_e_ees_exrfd_ret_value);
Description	Check the results of the RFD control function for the EES for errors that make the EES unsustainable.

Information:

Syntax	static R_EES_FAR_FUNC e_ees_block_status_t r_ees_fsm_get_ees_block_status(void);
Description	Obtains the state of the EES block.

6.   Sample Programs

This chapter describes the sample programs provided together with EES RL78 Type 01. This chapter is explained in the sample program example for RL78/G23. When using a device other than RL78/G23, read "G23" to the target device.

6.1   File Structure

6.1.1   Folder Structure

Figure 6-1 shows an example of using RL78/G23. The installed "sample" folder contains a folder for each device group (e.g. RL78_G23, RL78_G24). Read the folder name "RL78_G23" of the sample of RL78/G23 as the folder name of a target device.

    The folder name in the case of using RL78/G24: "RL78_G24"

When using the sample programs, include only the folder for the target device.
Figure 6-1 shows the structure of sample program folders.
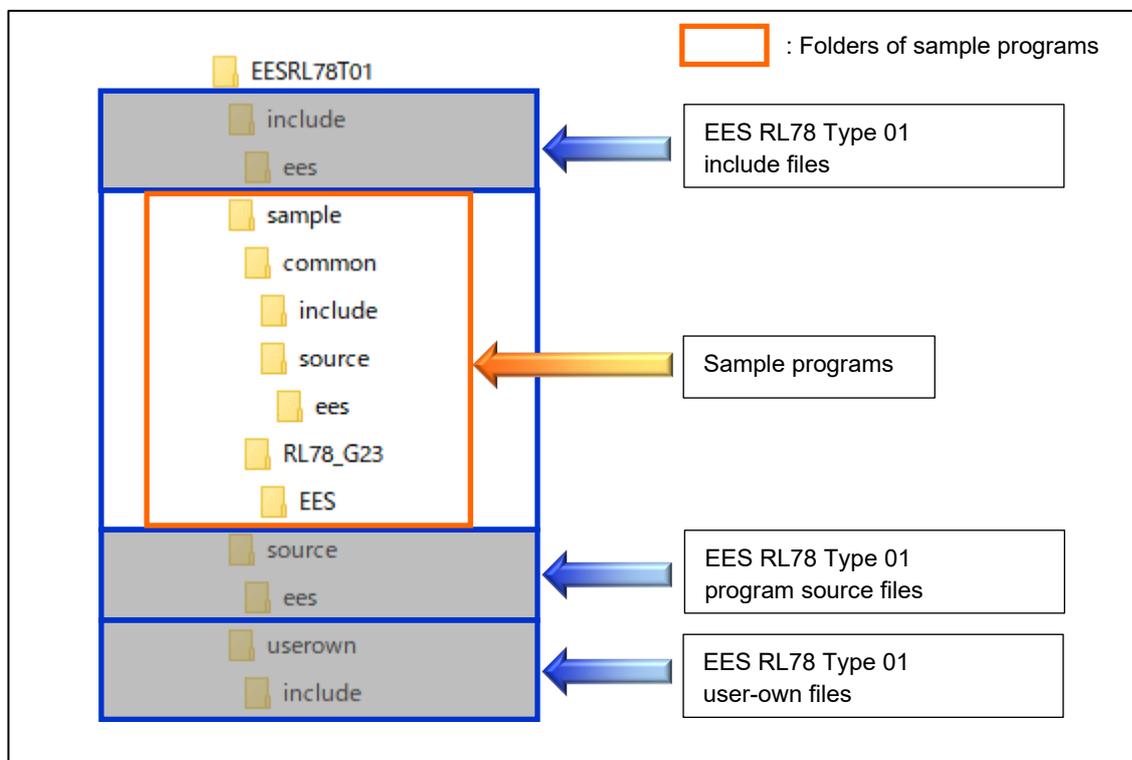
Figure 6-1 Structure of Sample Program Folders

6.1.2 List of Files

6.1.2.1 List of Source Files

Table 6-1 shows the program source file in the "sample\common\source\ees\" folder.

Table 6-1 Program Source File in the "sample\common\source\ees\" Folder

No.	Source File Name	Description
1	sample_control_ees.c	This file contains the functions for controlling the EEPROM emulation.

Table 6-2 shows the program source file of the main processing in the "sample\RL78_G23" folder.

 "sample\RL78_G23\EES\[compiler name]\source\" folder

Table 6-2 Program Source File of the Main Processing

No.	Source File Name	Description
1	main.c	Sample file of the main processing functions

6.1.2.2 List of Header Files

Table 6-3 shows the program header files in the "sample\common\include\" folder.

Table 6-3 Program Header Files in the "sample\common\include\" Folder

No.	Header File Name	Description
1	sample_control_ees.h	This file defines the prototype declarations of the sample functions for controlling the EEPROM emulation.
2	sample_ees_defines.h	This file defines the macros of the sample functions for controlling the EEPROM emulation.
3	sample_ees_memmap.h	This file defines the macros that describes the sections used by the sample program that controls the EEPROM emulation.

6.2 Data Type Definitions

6.2.1 Macro Defines

- Frequency setting macro

CPU frequency used in the sample program.

Symbol Name	Value	Description
SAMPLE_VALUE_U08_CPU_FREQUENCY	32u	CPU frequency (RL78_G23 folder)
	48u	CPU frequency (RL78_G24 folder)

6.3   Sample Program Functions

Table 6-5 shows the sample program functions.

Table 6-4   List of Sample Program Functions

	API Function Name	Outline
1	main	Executes the main processing of the sample program for controlling the EES.
2	Sample_EES_Control	Write and read EES blocks according to the basic procedure for using EES.

6.3.1   Sample Program for Controlling the EEPROM Emulation

The EES RL78 Type 01 rewrite control sample follows the basic operation procedure for using EES and performs the rewrite and read processing of EES block.

Note: During EES command processing, the data in the data flash memory cannot be referenced. Copy the data to be referenced within the function to RAM in advance, and reference them in RAM.

Operating conditions (Example of a sample program for RL78/G23):

- CPU operating frequency: 32 MHz

  (The high-speed on-chip oscillator clock (HOCO) is used for the main system clock.)

Figure 6-2 shows a flowchart of the main processing of the sample program for the EES.

6.3.1.1   main Function
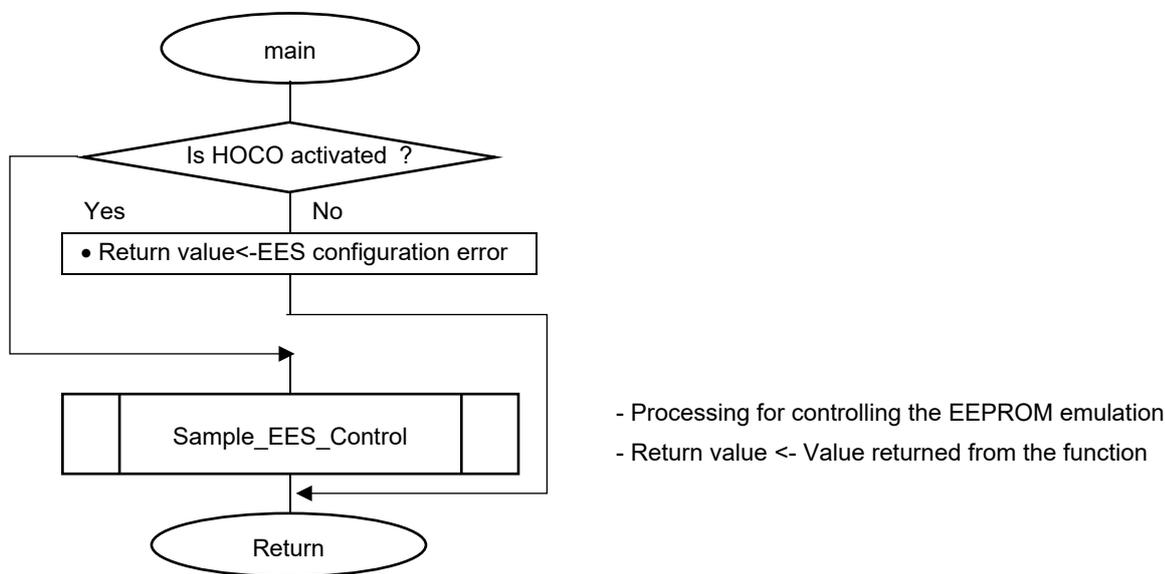
Figure 6-2   Flowchart of the Main Processing of the Sample Program for Controlling the EES.

6.3.1.2 Sample_EES_Control Function

- Figure 6-3 shows the pre-processing required to use the EES and the write and read processing flow.
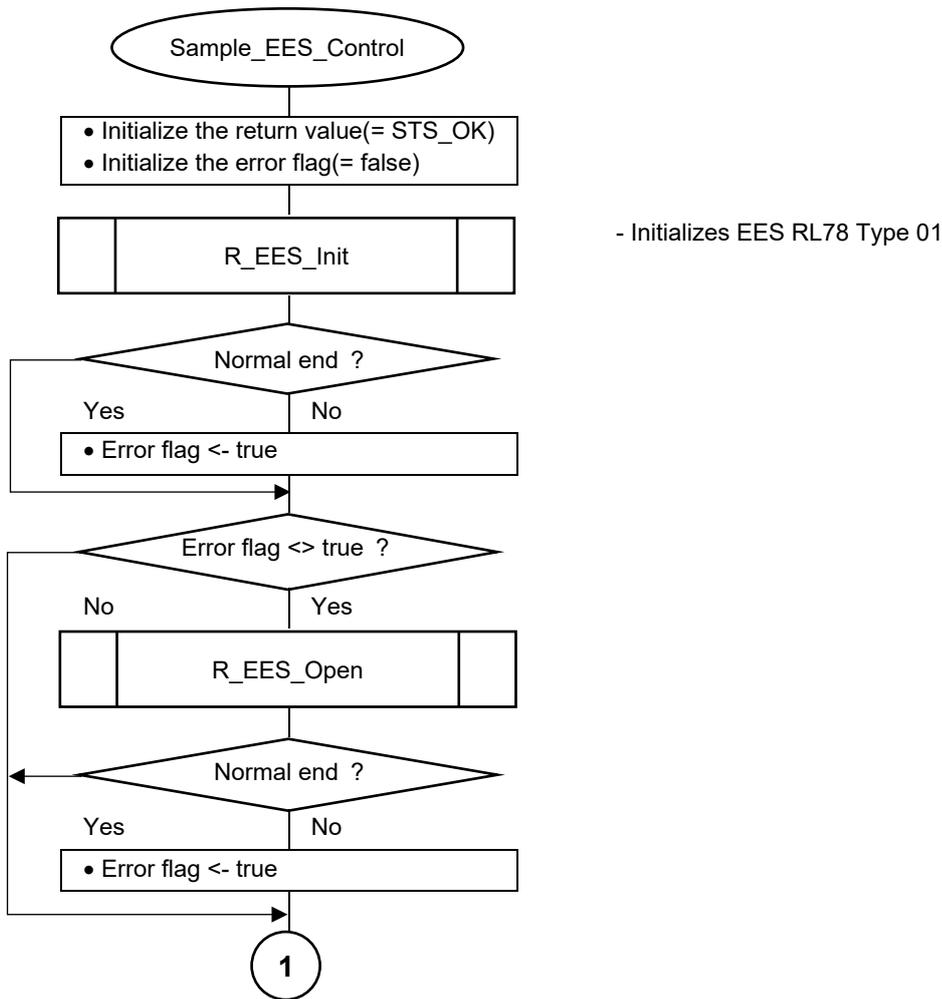
Figure 6-3   Flowchart of Sample Processing for Controlling EEPROM Emulation (1/5)

- EEPROM emulation execution startup processing.
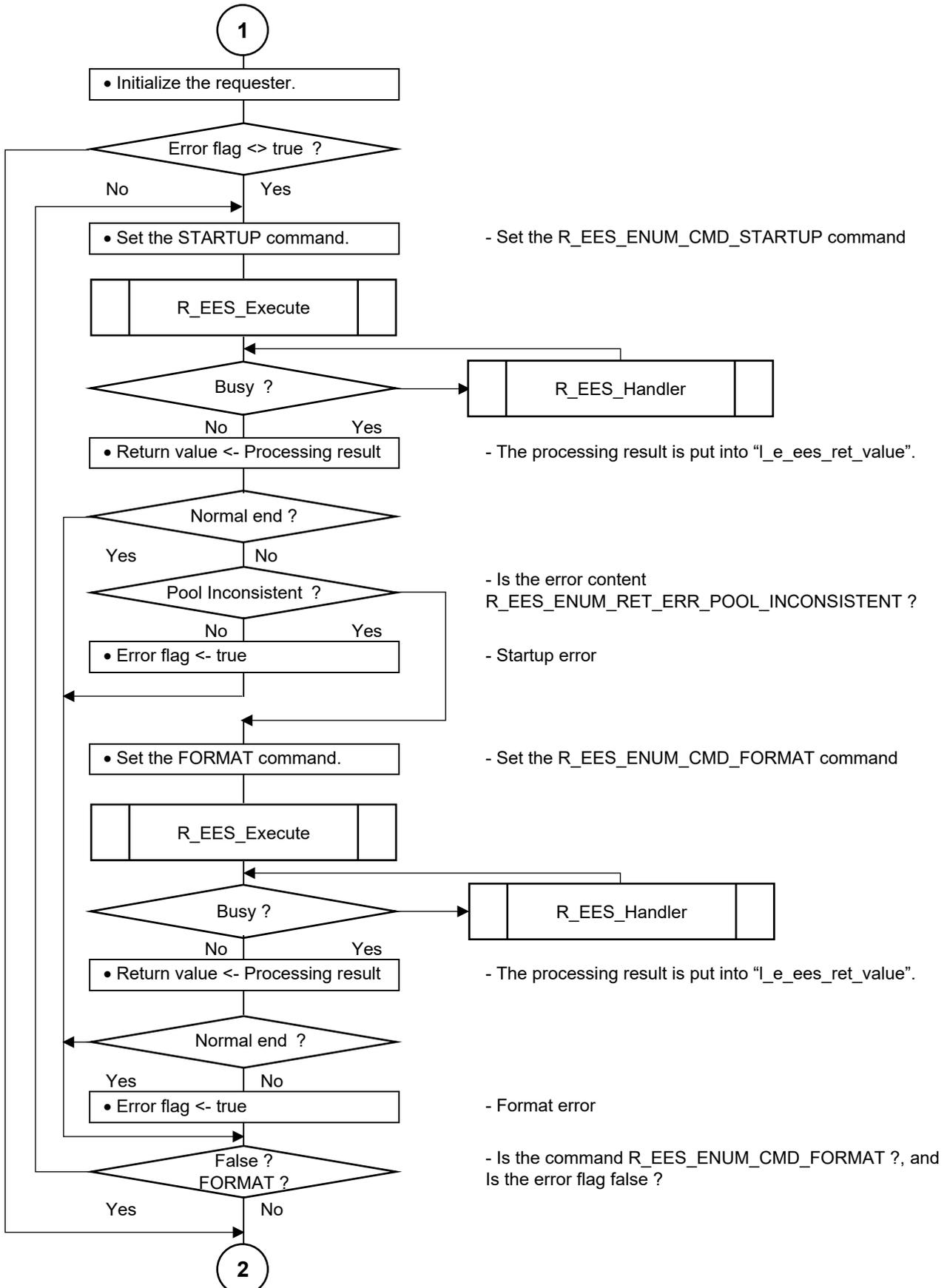
Figure 6-4   Flowchart of Sample Processing for Controlling EEPROM Emulation (2/5)

- EEPROM emulation data write processing.
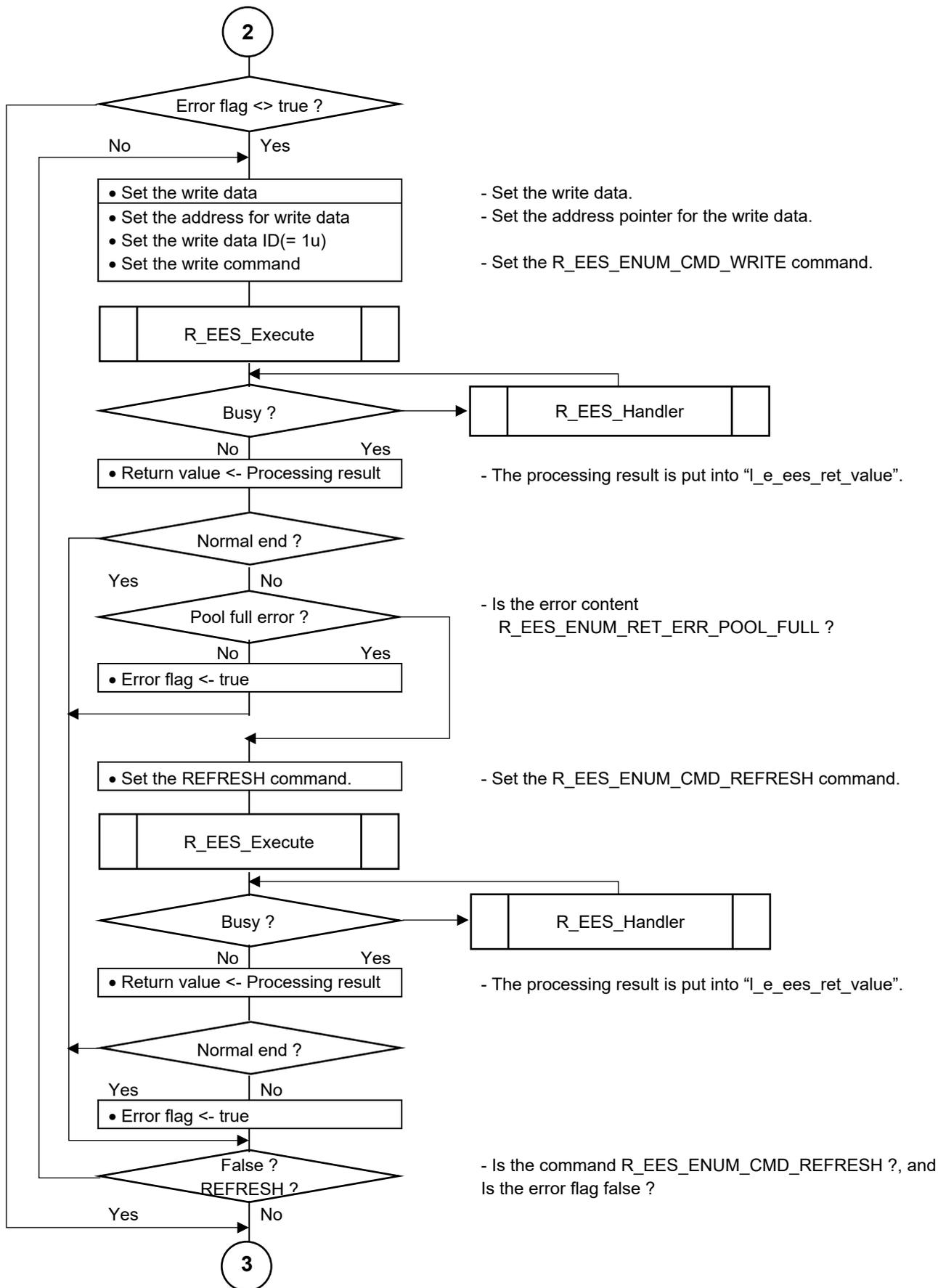
Figure 6-5   Flowchart of Sample Processing for Controlling EEPROM Emulation (3/5)

• EEPROM emulation data read processing.
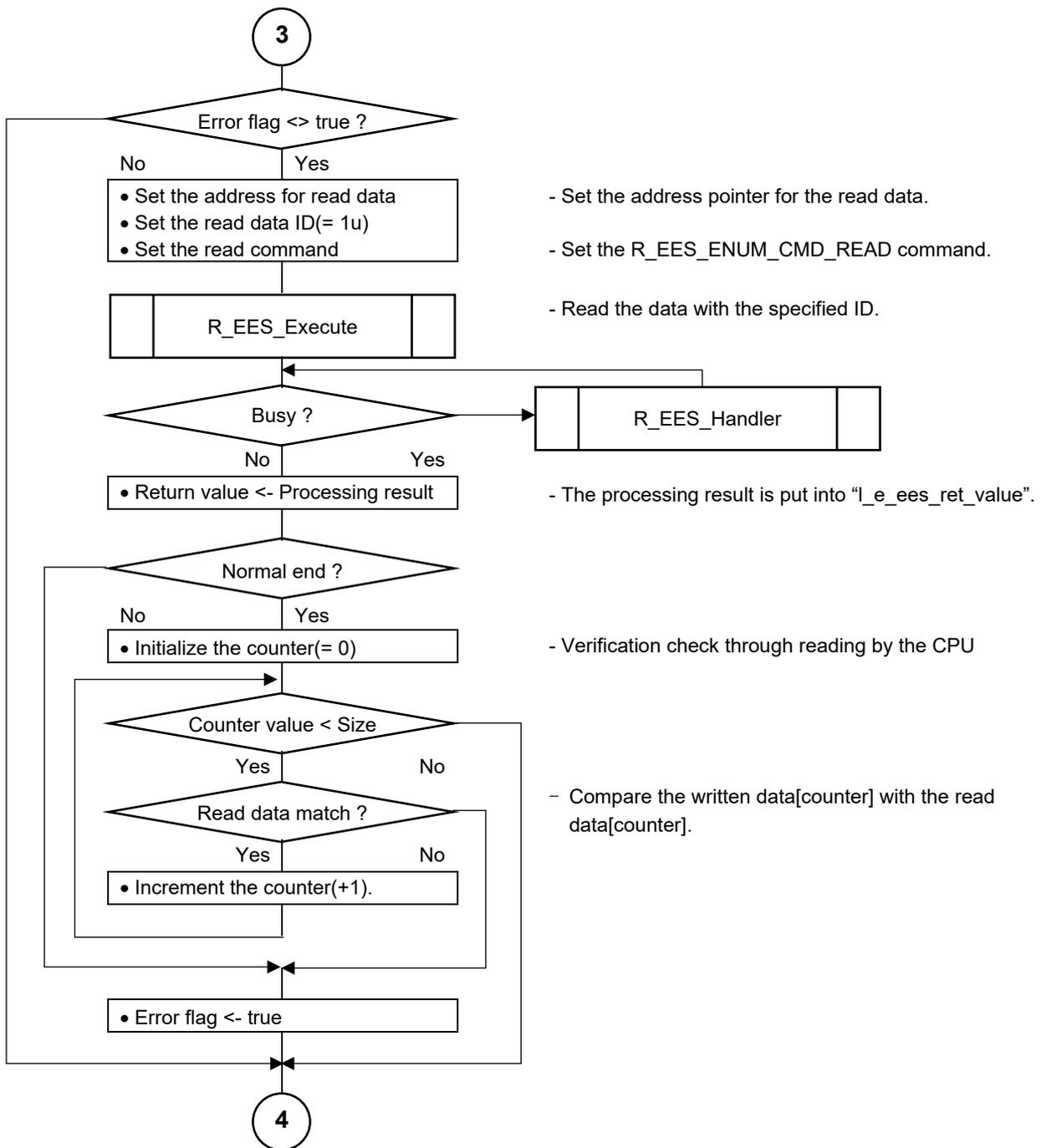
Figure 6-6   Flowchart of Sample Processing for Controlling EEPROM Emulation (4/5)

- EEPROM emulation shutdown processing.
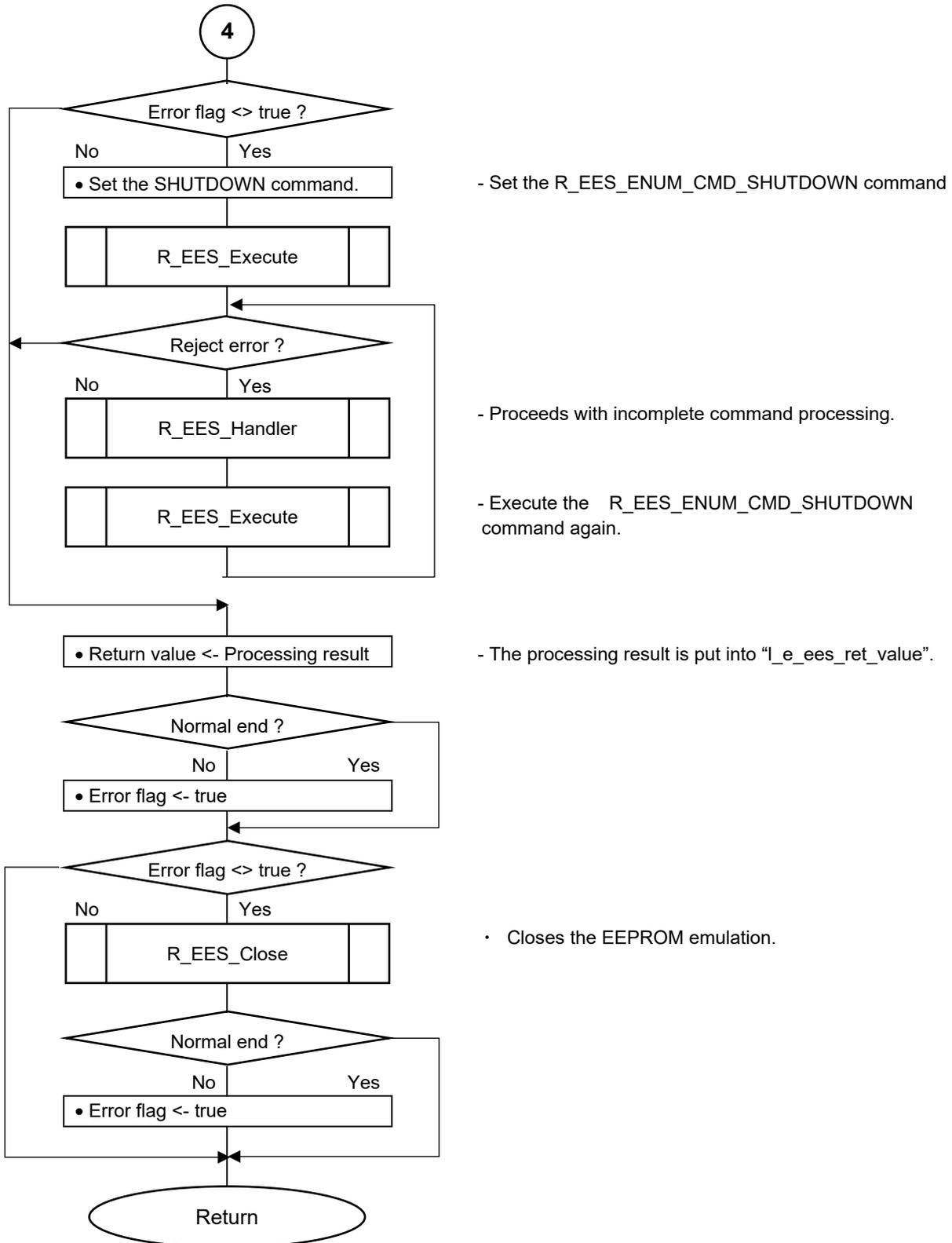
Figure 6-7   Flowchart of Sample Processing for Controlling EEPROM Emulation (5/5)

Note: Error handling and user processing for normal completion are omitted.

6.4 Specifications of Sample Program Functions

This section describes the specifications of the functions in the sample programs for EES RL78 Type 01. The sample programs for EEPROM emulation are examples of basic processing. The functions in the sample programs can be used as reference for developing an application program.

Please be sure to thoroughly check the operation of the developed application program.

6.4.1 Sample Program Functions for Controlling the EEPROM Emulation

6.4.1.1 main

Information:

Syntax	int main(void);	
Reentrancy	Non-reentrant	
Parameters (IN)	N/A	
Parameters (IN/OUT)	N/A	
Parameters (OUT)	N/A	

Return Value	int
	
	(e_ees_ret_status_t)
		R_EES_ENUM_RET_STS_OK : 0x00
		  [Normal end]
		R_EES_ENUM_RET_STS_BUSY : 0x01
		  [Busy]
		R_EES_ENUM_RET_ERR_CONFIGURATION : 0x82
		  [EES configuration error]
		R_EES_ENUM_RET_ERR_INITIALIZATION : 0x83
		  [EES initialization error]
		R_EES_ENUM_RET_ERR_ACCESS_LOCKED : 0x84
		  [EEPROM emulation lock error]
		R_EES_ENUM_RET_ERR_PARAMETER : 0x85
		  [Parameter error]
		R_EES_ENUM_RET_ERR_WEAK : 0x86
		  [Weak error]
		R_EES_ENUM_RET_ERR_REJECTED : 0x87
		  [Reject error]
		R_EES_ENUM_RET_ERR_NO_INSTANCE : 0x88
		  [No instance]
		R_EES_ENUM_RET_ERR_POOL_FULL : 0x89
		  [Pool full error]
		R_EES_ENUM_RET_ERR_POOL_INCONSISTENT : 0x8A
		  [EES block Inconsistency error]
		R_EES_ENUM_RET_ERR_POOL_EXHAUSTED : 0x8B
		  [EES block exhaustion error]
		R_EES_ENUM_RET_ERR_INTERNAL : 0x8C
		  [Internal error]
		R_EES_ENUM_RET_ERR_FLASH_SEQ : 0x8D
		  [Flash sequencer error]

Description	Executes the main processing of the sample program for controlling the EES.	
Preconditions	-	
Remarks	-	

6.4.1.2 Sample_EES_Control

Information:

Syntax	R_EES_FAR_FUNC e_ees_ret_status_t Sample_EES_Control();	
Reentrancy	Non-reentrant	
Parameters (IN)	N/A	
Parameters (IN/OUT)	N/A	
Parameters (OUT)	N/A	
Return Value	e_ees_ret_status_t	R_EES_ENUM_RET_STS_OK : 0x00 　[Normal end] R_EES_ENUM_RET_STS_BUSY : 0x01 　[Busy] R_EES_ENUM_RET_ERR_CONFIGURATION : 0x82 　[EES configuration error] R_EES_ENUM_RET_ERR_INITIALIZATION : 0x83 　[EES initialization error] R_EES_ENUM_RET_ERR_ACCESS_LOCKED : 0x84 　[EEPROM emulation lock error] R_EES_ENUM_RET_ERR_PARAMETER : 0x85 　[Parameter error] R_EES_ENUM_RET_ERR_WEAK : 0x86 　[Weak error] R_EES_ENUM_RET_ERR_REJECTED : 0x87 　[Reject error] R_EES_ENUM_RET_ERR_NO_INSTANCE : 0x88 　[No instance] R_EES_ENUM_RET_ERR_POOL_FULL : 0x89 　[Pool full error] R_EES_ENUM_RET_ERR_POOL_INCONSISTENT : 0x8A 　[EES block Inconsistency error] R_EES_ENUM_RET_ERR_POOL_EXHAUSTED : 0x8B 　[EES block exhaustion error] R_EES_ENUM_RET_ERR_INTERNAL : 0x8C 　[Internal error] R_EES_ENUM_RET_ERR_FLASH_SEQ : 0x8D 　[Flash sequencer error]
Description	Write and read EES blocks according to the basic procedure for using EES.	
Preconditions	-	
Remarks	When the verification check of the read data results in an error, it is not reflected in the return value.	

6.5   Precautions in Case of Using Sample Program

- The precautions in the case of using RL78/G24.

Only the case which sets an option byte(000C2H/040C2H) to 0xF0 and uses the clock frequency of CPU at 24 MHz is necessary for the following countermeasures. Modify into the comments or delete so that a part of sample program for RL78/G24 may not compile.

If a red character part is compiled, prefetch buffer will become valid and will operate at 48 MHz.

    Target folder:
      \EESRL78T01\sample\RL78_G24\EES\[Compiler name]\source\

    Target file:
      CC-RL and LLVM: hdwinit.c
      IAR: low_level_init.c

The following red character parts are the examples which modified the source code to the comment.

```
/* Start HOCO. It must be started before flash control. */
HIOSTOP = 0u;

/* Check CPU frequency in the user option byte (0x000C2). */
/* 0xF0 : HS mode 48 MHz */
//if (0xF0u == (*(volatile unsigned char __far *)0x000C2u))
//{
//      /* Set CPU frequency 48 MHz (Enables the prefetch buffer). */
//      HOCODIV = 0x00u;
//      PFBE    = 1u;
//      FIHSEL  = 1u;
//
//      /* Confirm the switching status flag. */
//      while (1u == FIHST)
//      {
//          /* No operation */
//      }
//}
//else
//{
//      /* No operation */
//}
```

7. Creating a Sample Project for EES RL78 Type 01

EES RL78 Type 01 includes a sample program to control EEPROM emulation. The compilers which can be used by EES RL78 Type 01 are a CC-RL compiler, an IAR compiler and a LLVM compiler. Users can create a sample project using the Integrated Development Environment (IDE) corresponding to each compiler.

The target sample programs differ in each device (e.g. RL78_G23, RL78_G24). This section is explained in the sample program example for RL78/G23. If you are using another device on the RL78/G23, change the G23 description to the target device. Section address settings must be changed by referring to the user's manual for the target device. In addition, Because the flash memory control scheme varies depending on the target device, the classification macro must be configured in the Integrated Development Environment (IDE). The setting method is described in "7.1.3.2 The Setting of User Definition Macro"(CC-RL), "7.2.3.2 The Setting of User Definition Macro"(IAR) and "7.3.3.2 The Setting of User Definition Macro"(LLVM).

If the RL78/G22 is used, the RL78/G23 sample program is available.

Notes   1: **The target Integrated Development Environment (IDE) and the compiler are premised on using the version for RL78/G2x. Be sure to use them, after confirming that RL78/G2x are target products.**

        2: **EES RL78 Type 01 uses the RFD RL78 Type 01 to control the data flash memory. However, it is not included in the EES RL78 Type 01 installer, RFD RL78 Type 01 must be installed before registering to the project. It describes the RFD RL78 Type 01 files and sections needed to register the project, however for more information on RFD RL78 Type 01, refer to the RFD RL78 Type 01 User's Manual.**

7.1 Creating a Project in the Case of Using a CC-RL Compiler

CS+ or e^2 studio can be used for a RENESAS CC-RL compiler as an IDE. EES RL78 Type 01 and RFD RL78 Type 01 are registered and built in the project created by the IDE. An example of creating a sample project in case each IDE is used is shown. Because to understand a CC-RL compiler and each IDE, it is necessary to refer to the user's manual of each tool product.

7.1.1   Example of Creating a Sample Project

(1) An example of creating a sample project which used CS+ (IDE)

・The CS+ starts and from the [Project] menu, select [Create New Project...], the "Create Project" window

will open.

 - Select the product of "RL78/G23 (ROM: 128 Kbytes)" - "R7F100GLGxFB(64pin)" as [Using

  microcontroller].

 - Select "Application(CC-RL)" as [Kind of project].

 - [Project name] is temporarily set to "EESRL78T01_PJ01".

 - When you click the [Create] button, the new project is created.
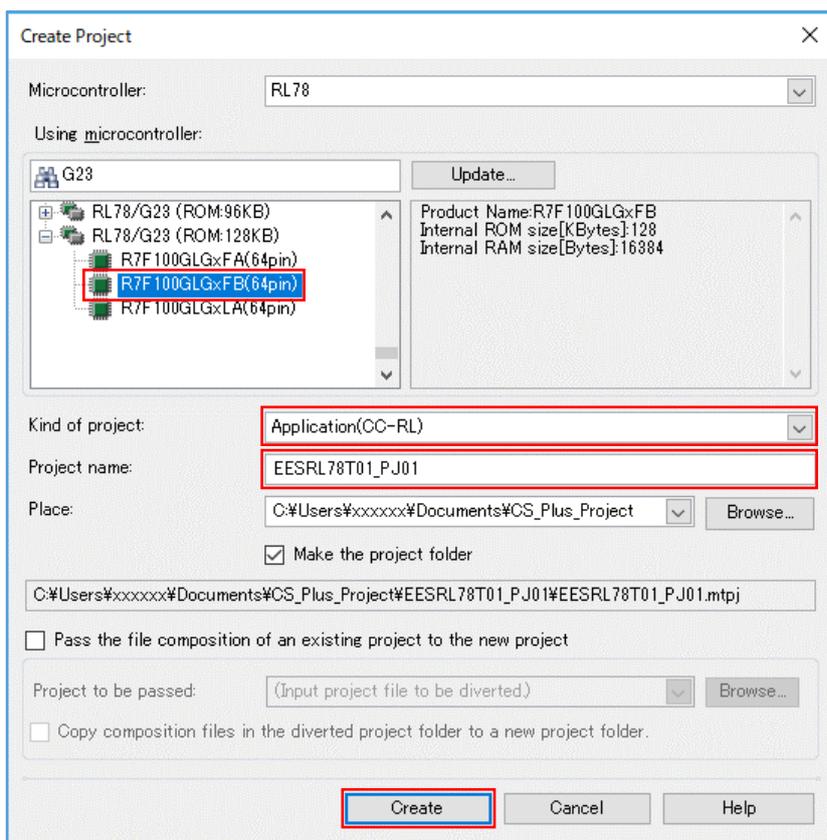
(2) An example of creating a sample project which used e^2 studio (IDE)

・The e^2 studio starts and from the [File] menu, select [New] – [C/C++ Project], the "Templates for New C/C++ Project" window will open.
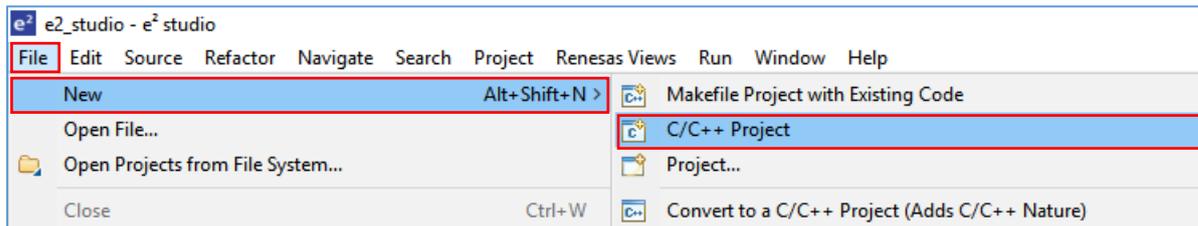
・Select [Renesas CC-RL C Executable Project] displayed after selection in [Renesas RL78], and press "next" button.
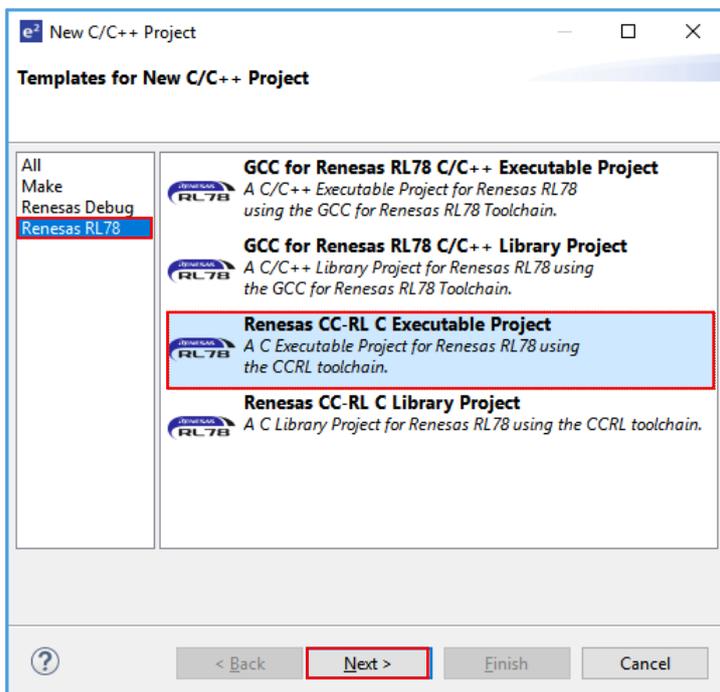
・Input "project name" on "New Renesas CC-RL Executable Project" window, and press "next" button. [Project name] is temporarily set to "EESRL78T01_PJ01".
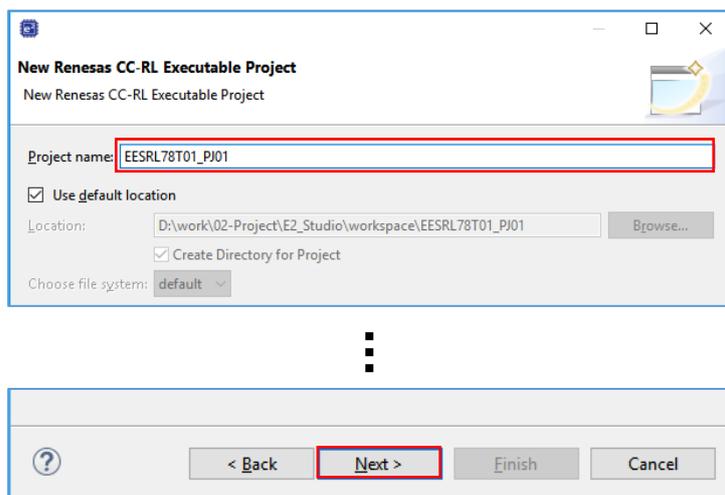
・Select the [Target Device] of [Device Settings], and select "RL78 - G23" - "RL78 - G23 64pin" - "R7F100GLGxFB".

・It is a premise that E2 Lite is selected as a debugging tool and on-chip debugging is executed. Put a check mark to "Create Hardware Debug Configuration" by [Configurations]. And select "E2 Lite(RL78)".

・Press "Finish" button.
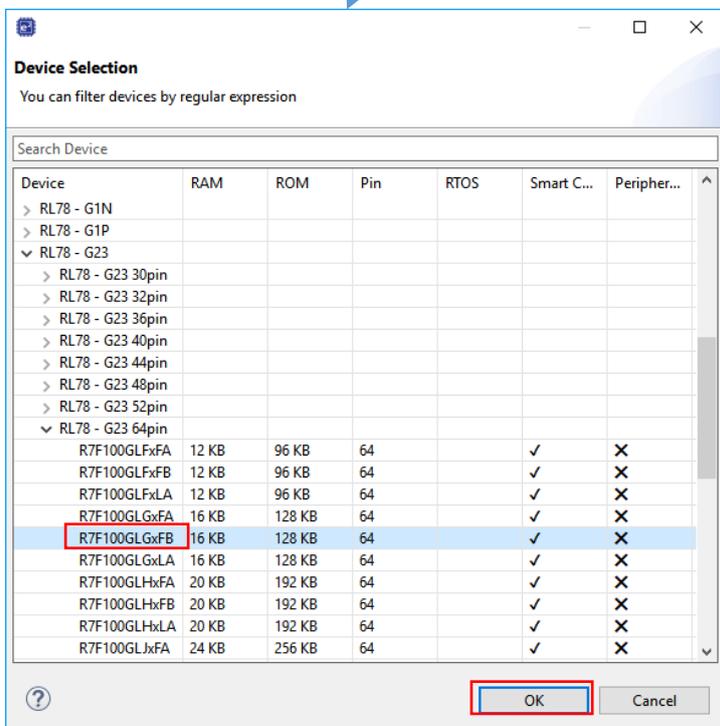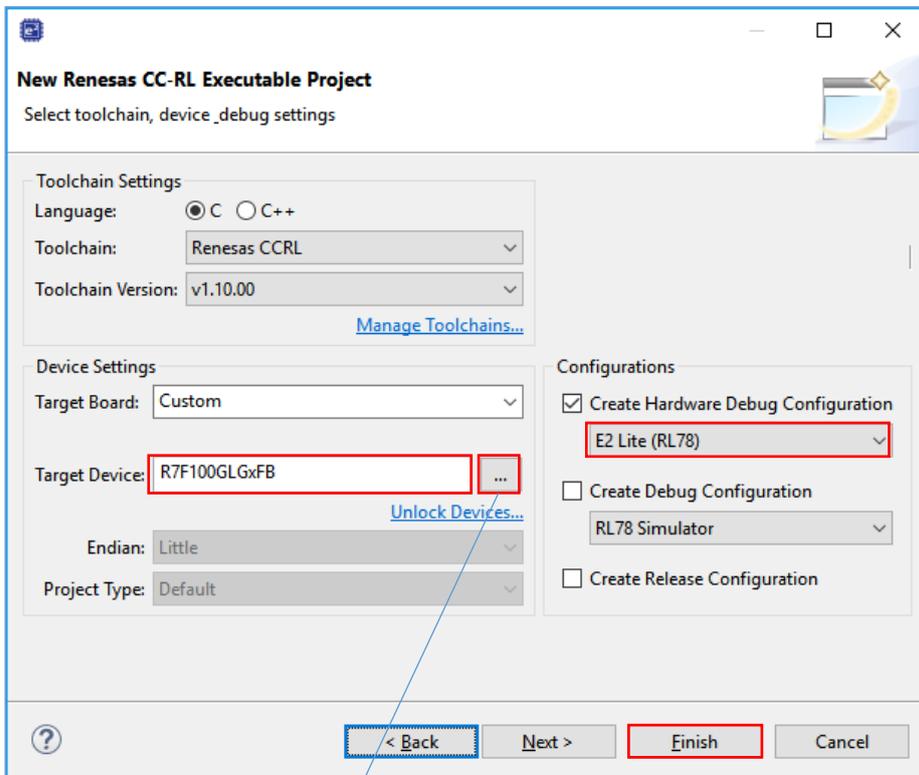
7.1.2   Example of Registration of Target Folders and Target Files

Using EES RL78 Type 01, when execute EEPROM emulation the example which registers necessary files is shown. Each folder of a "EESRL78T01" source program file is "include", "source", "userown", and "sample". As other registration methods, after all the folders of "include", "source", "userown", and "sample" are registered, unnecessary files and folders can be removed using the function of "Remove from Project"(CS+) or [Resource Configuration] – [Exclude from Build] (e^2 studio).
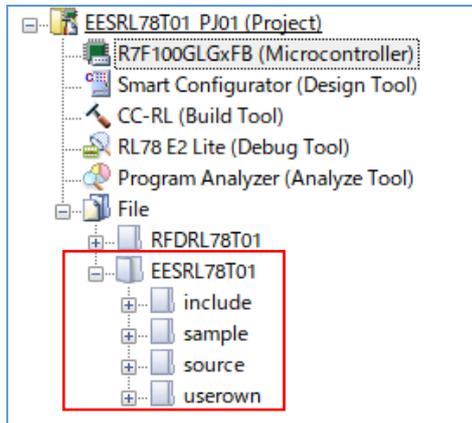
The registration tree screen of EES (CS+)	The registration tree screen of EES (e^2 studio)
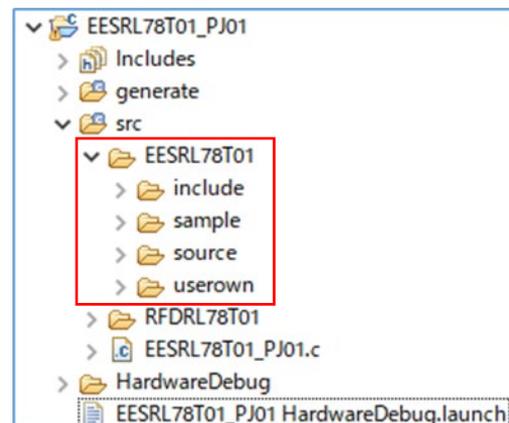
・Registration of the latest I/O header file(iodefine.h) outputted to target products by IDE

"iodefine.h" is an I/O header file which CS+ or e^2 studio outputs to target products. Replacing instead of "iodefine.h" included in EES RL78 Type 01 is recommended. Registration of target folders and target files is implemented. Then, a user replaces "iodefine.h" which IDE outputted with "iodefine.h" included in EES RL78 Type 01.

The folder to which an I/O header file (iodefine.h) is outputted by IDE :
  - CS+ : [Project name] folder
  - e^2 studio : [Project name]/generate folder

The folder with which a user replaces the "iodefine.h" file :
  - CS+ : \[Project name]\EESRL78T01\sample\RL78_G23\EES\CCRL\include
  - e^2 studio : \[Project name]\src\EESRL78T01\sample\RL78_G23\EES\CCRL\include

・Exclusion of the file automatically added by the function of IDE.
  There are files added automatically in the created project. The same file as these exists also in the "sample" folder of EES RL78 Type 01. Therefore, using the function of IDE, Select those files from tree and excludes from a project.
  - CS+ : Click the right mouse button for the file of tree. And exclude target file using "Remove from Project" function. Targets are "cstart.asm, hdwinit.asm, stkinit.asm, main.c, and iodefine.h" in [project name] folder.
  - e^2 studio : Clicks the right mouse button for the file of tree. And on the [Settings] screen displayed by the "Properties", put a check mark to [Exclude resource from build] and exclude a target file (target folder). (Exclusion of a folder is also possible)
  Target files are cstart.asm, hdwinit.asm, iodefine.h, and stkinit.asm in a [Project name]/generate folder.
  And [Project name] .c ("EESRL78T01_PJ01.c") in a [Project name]/src folder is a target.
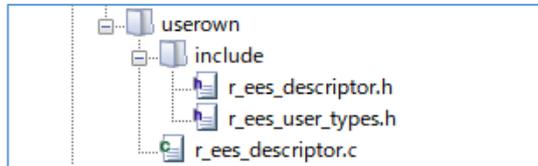
(1) Registration the EES RL78 Type 01 target folders and target files.

The folders ("include", "source", "userown", "sample") and source program file which are included in EES RL78 Type 01 to register are shown below.
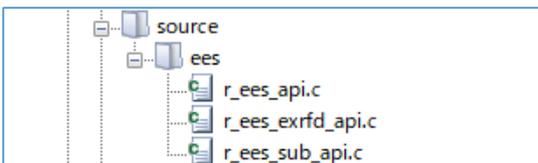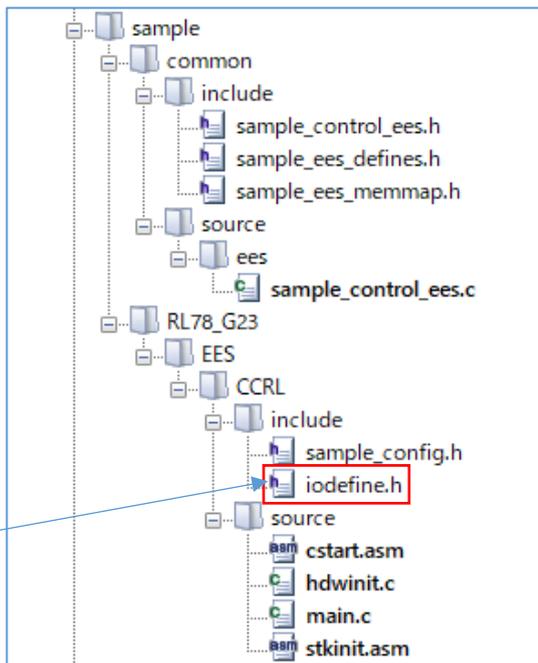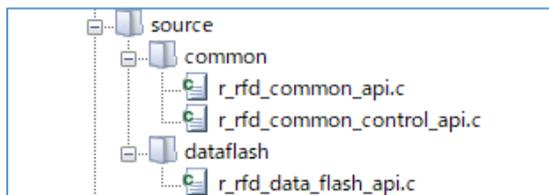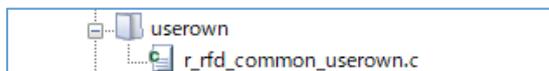
in the "include" folder

```
include
  ees
    r_ees.h
    r_ees_compiler.h
    r_ees_defines.h
    r_ees_device.h
    r_ees_memmap.h
    r_ees_types.h
    r_type_defs.h
  r_ees_api.h
  r_ees_exrfd_api.h
  r_ees_sub_api.h
```

in the "source" folder

```
source
  ees
    r_ees_api.c
    r_ees_exrfd_api.c
    r_ees_sub_api.c
```

in the "userown" folder

```
userown
  include
    r_ees_descriptor.h
    r_ees_user_types.h
  r_ees_descriptor.c
```

in the "sample" folder

```
sample
  common
    include
      sample_control_ees.h
      sample_ees_defines.h
      sample_ees_memmap.h
    source
      ees
        sample_control_ees.c
  RL78_G23
    EES
      CCRL
        include
          sample_config.h
          iodefine.h
        source
          cstart.asm
          hdwinit.c
          main.c
          stkinit.asm
```
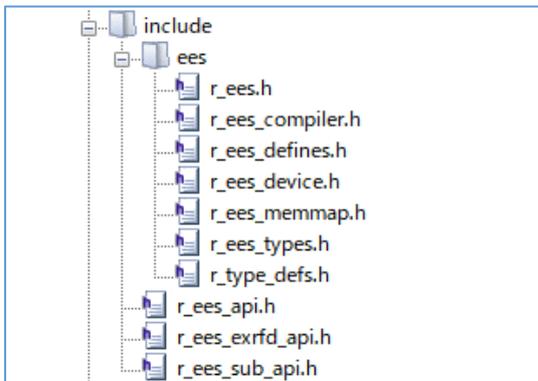
> Transpose to "iodefine.h" outputted by CS+ or e^2 studio.

(2) Registration the RFD RL78 Type 01 target folders and target files.

The folders ("include", "source", "userown") and source program file which are included in RFD RL78 Type 01 to register are shown below.

in the "include" folder

```
include
  rfd
    r_rfd.h
    r_rfd_compiler.h
    r_rfd_device.h
    r_rfd_memmap.h
    r_rfd_types.h
    r_typedefs.h
  r_rfd_common_api.h
  r_rfd_common_control_api.h
  r_rfd_common_userown.h
  r_rfd_data_flash_api.h
```

in the "source" folder

```
source
  common
    r_rfd_common_api.c
    r_rfd_common_control_api.c
  dataflash
    r_rfd_data_flash_api.c
```

in the "userown" folder

```
userown
  r_rfd_common_userown.c
```
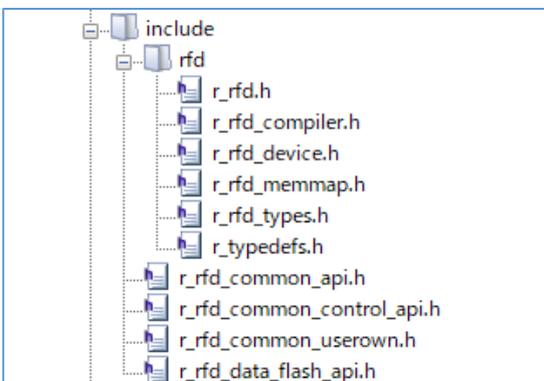
7.1.3　Build Tool Settings

Set IDE setting necessary in order to build EES RL78 Type 01 using a CC-RL compiler.

CS+ : Click the right mouse button for the "CC-RL(Build tool)" in a tree, and select "Property". And set each
　　　setting of the build tool in the displayed window.

e² studio : Click the right mouse button for the project("EESRL78T01_PJ01") in a tree, and select
　　　"Properties". And set each setting of the build tool in the displayed window.

7.1.3.1　Include Path Settings

・Setting of the include path on CS+ inputs path in "Common Options" tab.
　- Input the Include directory path in the "Path Edit" window displayed by selection of [Frequently Used
　　Options(for Compile)] - [Additional include paths].

(1) EES RL78 Type 01 include path

```
EESRL78T01\include
EESRL78T01\include\ees
EESRL78T01\sample\common\include
EESRL78T01\sample\RL78_G23\EES\CCRL\include
EESRL78T01\userown\include
```

(2) RFD RL78 Type 01 include path

```
RFDRL78T01\include
RFDRL78T01\include\rfd
```
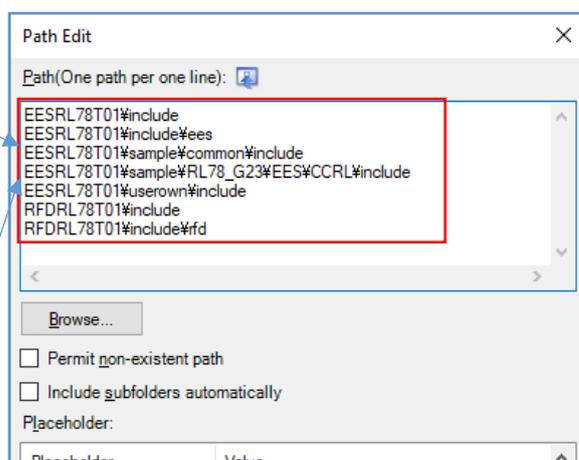

・Setting of the include path on e² studio inputs path in "Properties" window.
　- Input the Include directory path in the window displayed by selection of "C/C++ Build" [Settings] -
　　"Compiler" [Source].

(1) EES RL78 Type 01 include path

```
${ProjDirPath}\src\EESRL78T01\include
${ProjDirPath}\src\EESRL78T01\include\ees
${ProjDirPath}\src\EESRL78T01\sample\common\include
${ProjDirPath}\src\EESRL78T01\sample\RL78_G23\EES\CCRL\include
${ProjDirPath}\src\EESRL78T01\userown\include
```

(2) RFD RL78 Type 01 include path

```
${ProjDirPath}\src\RFDRL78T01\include
${ProjDirPath}\src\RFDRL78T01\include\rfd
```
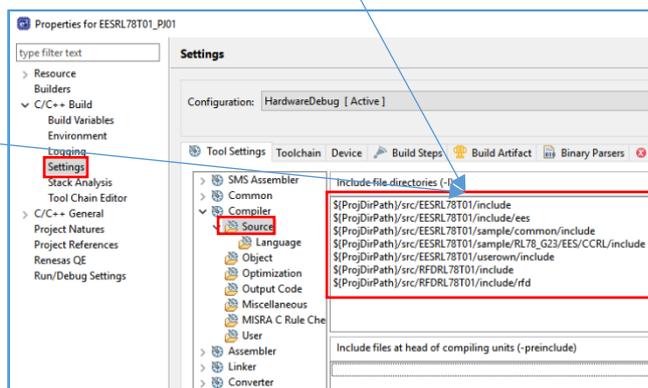
7.1.3.2 The Setting of User Definition Macro

- On CS+, the macro for flash memory control system classification is defined in "Common Options" tab.
  - Define the following macro in the "Text Edit" window displayed by selection of [Frequently Used Options(for Compile)] - [Macro definition]. Definition macro differs by each device to be used.

  Macros defined when using RL78/G23 or RL78/G22:
  R_RFD_MCU_FLASH_T01_CATEGORY01

  Macros defined when using RL78/G24:
  R_RFD_MCU_FLASH_T01_CATEGORY02
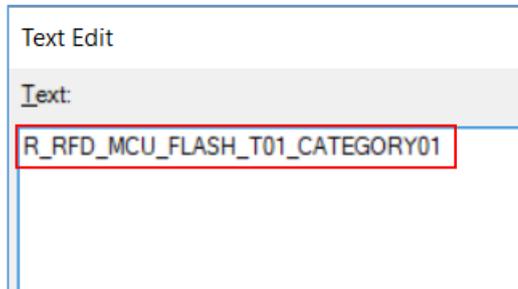
- On e^2 studio, the macro for flash memory control system classification is defined in "Properties" window.
  - Define the following macro in the "Macro Definition (-D)" displayed by selection of "C/C++ Build" [Settings] – "Compiler" [Source]. Definition macro differs by each device to be used.

  Macros defined when using RL78/G23, or RL78/G22:
  R_RFD_MCU_FLASH_T01_CATEGORY01

  Macros defined when using RL78/G24:
  R_RFD_MCU_FLASH_T01_CATEGORY02
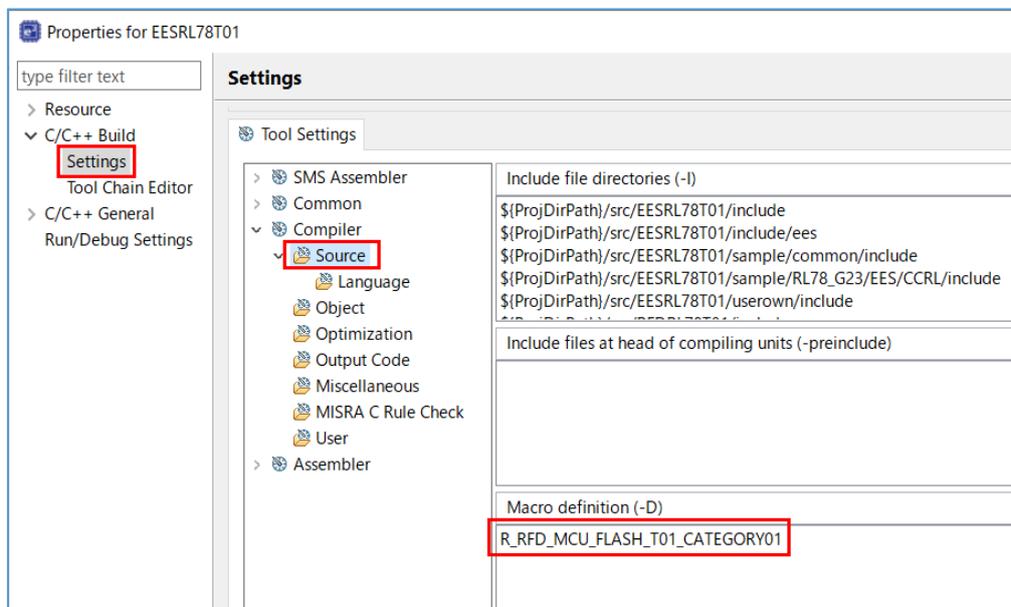
Note : A compile error will be outputted if macro is not defined.

7.1.3.3 Device Item Settings

・Setting of the device Items on CS+ inputs in the "Link Options" tab.

  - Setting the [Device] items

Select "Yes (-OCDBG)" in [Set enable/disable on-chip debug by link option].
  Note : The example of a setting on condition of on-chip debugging execution.

Input the "85" into [Option byte values for OCD]. (Example of permission of operation for on-chip debugging)
  Note : Be sure to confirm the contents of "User option byte" of the chapter of "Option Bytes", and "On-chip debug option byte" on the user's manual of a target device. And describe the set value used with user application.

Select "Yes(Specify address range)(-OCDBG_MONITOR=<Address range>)" in [Set debug monitor area]. Set "1FE00-1FFFF" to [Range of debug monitor area].
  Note : The user needs to input the range of the area which the debugger uses with reference to description of the user's manual for a target device. And please refer to "Memory Spaces Allocated for Use by the Monitor Program for Debugging" in "Allocation of Memory Spaces to User Resources" on a user's manual.

Select "Yes(-USER_OPT_BYTE)" in [Set user option byte].
Set "6EFFE8" to [User option byte value]. (WDT stop, LVD reset mode, HS mode /32MHz [The example for RL78/G23])
 **Note : Be sure to confirm the contents of "User option byte" of the chapter of "Option Bytes", and "User option bytes" on the user's manual of a target device. And describe the set value used with user application.**
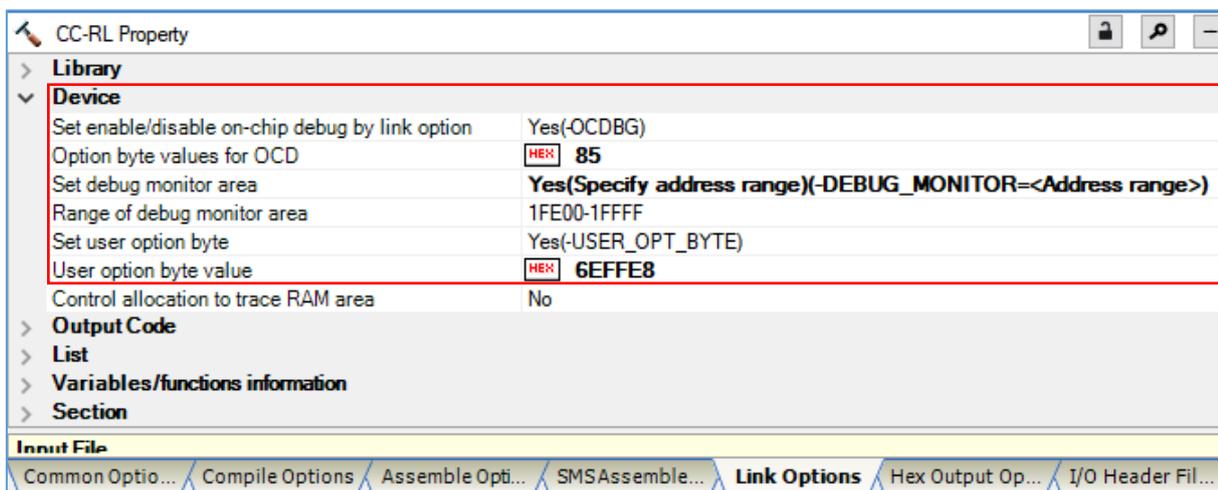
・Setting of the device Items on e^2 studio inputs in the "Properties" window.

  - Select "C/C++ Build" [Settings] - "Linker" [Device]. And set device items on the displayed screen.

    Put in a check mark to [Secure memory area of OCD monitor(-debug_monitor)] in the screen.
      Note : The example of a setting on condition of on-chip debugging execution.

    Set "1FE00-1FFFF" to [Memory area(-debug_monitor=<start address>-<end address>)].
      Note : The user needs to input the range of the area which the debugger uses with reference to description of the user's manual for a target device. And please refer to "Memory Spaces Allocated for Use by the Monitor Program for Debugging" in "Allocation of Memory Spaces to User Resources" on a user's manual.

    Put a check mark to [Set user option byte(-user_opt_byte)].
    Set "6EFFE8" to [User option byte value(-user_opt_byte=<value>)]. (WDT stop, LVD reset mode, HS mode /32MHz [The example for RL78/G23])
      Note : Be sure to confirm the contents of "User option byte" of the chapter of "Option Bytes", and "User option bytes" on the user's manual of a target device. And describe the set value used with user application.

    Put a check mark to [Set enable /disable on-chip debug by link option(-ocdbg)].
      Note : The example of a setting on condition of on-chip debugging execution.

    Input the "85" into [On-chip debug control value(-ocdbg=<value>)]. (Example of permission of operation for on-chip debugging)
      Note : Be sure to confirm the contents of "User option byte" of the chapter of "Option Bytes", and "On-chip debug option byte" on the user's manual of a target device. And describe the set value used with user application.
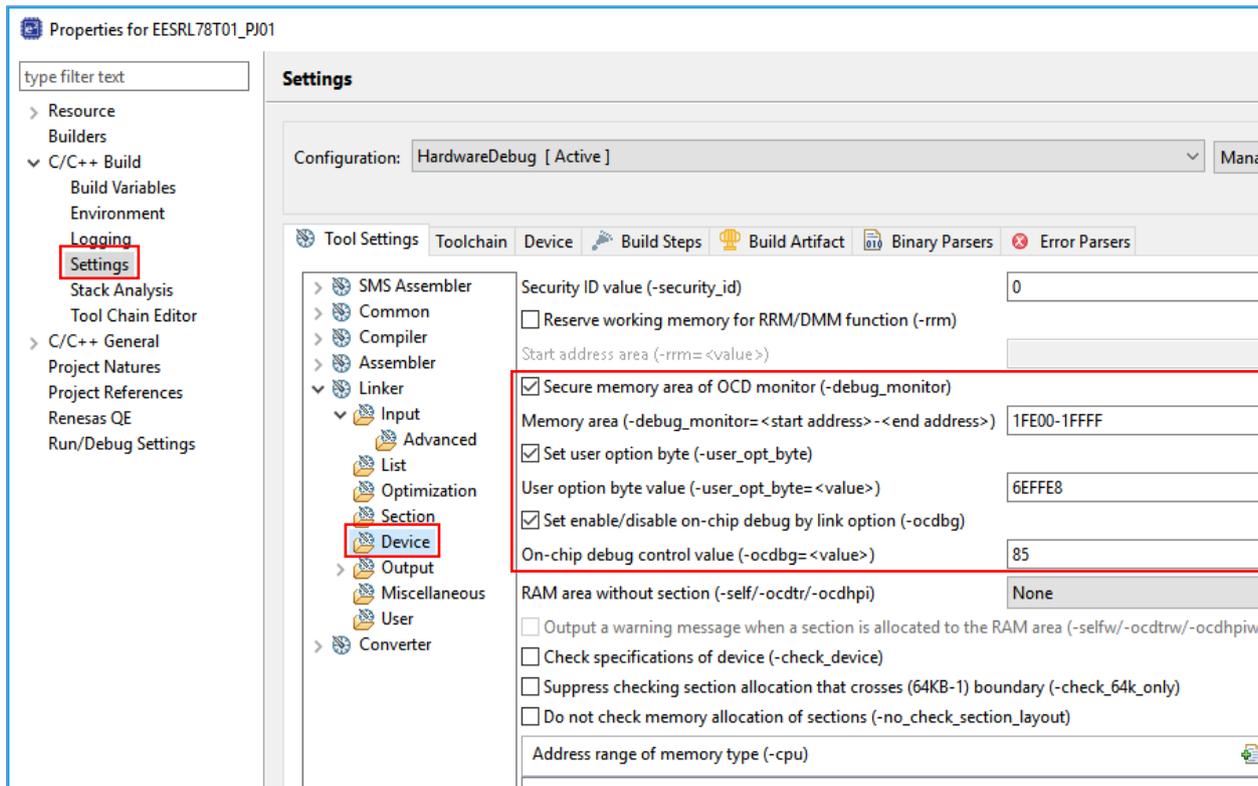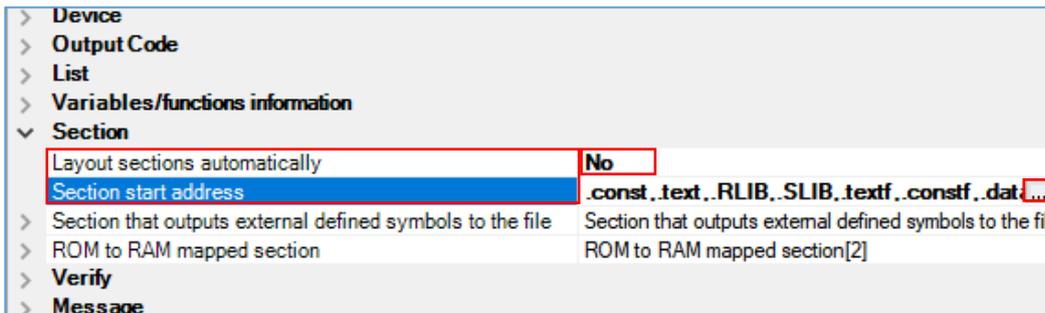
7.1.3.4 Section Item Settings

・Setting of the section Items on CS+ inputs in the "Link Options" tab.
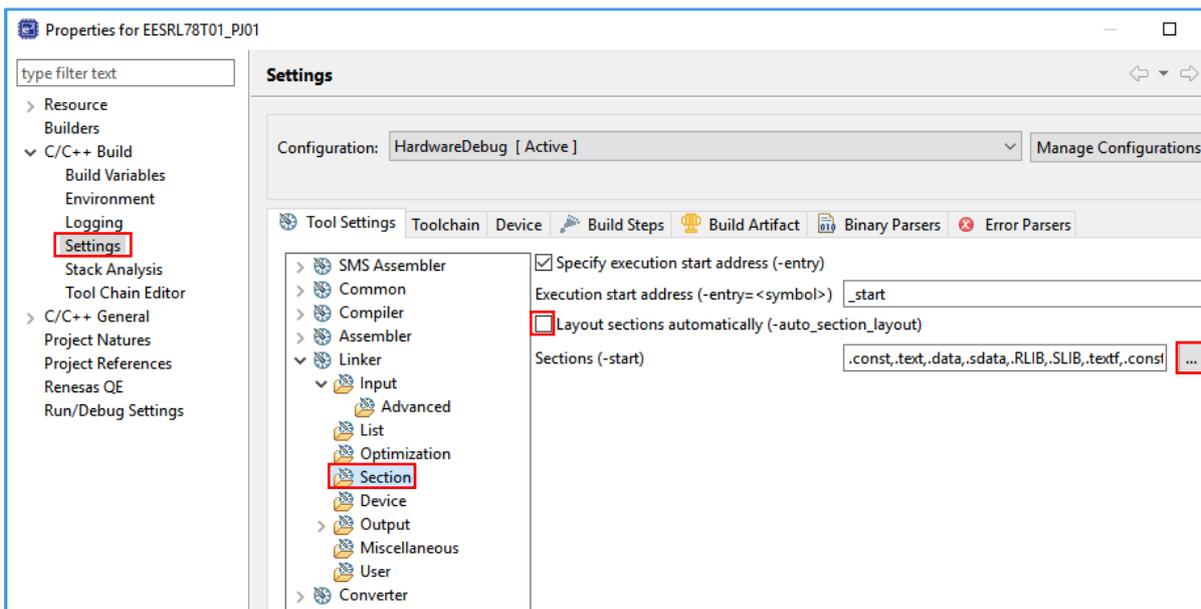
  - Setting the [Section] items

    Set "No" to [Layout sections automatically]. And sections come to be displayed on [Section start address]. Press the "⬚" button of the right-hand side which sections are displaying, and a "Section settings" screen is displayed.

・Setting of the section Items on e^2 studio inputs in the "Properties" window.

  - Select "C/C++ Build" [Settings] - "Linker" [Section]. And set section items on the displayed screen.

    Remove a check mark to [Layout sections automatically(-auto_section_layout)]. Press the "⬚" button of the right-hand side which sections are displaying, and a "Section viewer" screen is displayed.

・Section setting operation for CS+ and e^2 studio

Set "0x03000" to a top address.
Add the sections defined by "#pragma section" in EES RL78 Type 01 to the program area (code flash memory) and the RAM area. Refer to "Table 2-10 Sections Used in EES" for the details of each section.

Note : In this description, it is a premise to select a medium model as Memory Model of Compile Options. (It is the same as the "auto select" in R7F100GLG)
Copy processing of the sections from ROM to RAM is executed in a cstart.asm file. Refer to the user's manual of CC-RL for the section name of each program when a "small model" is selected.

(1) The addition of the sections for EEPROM emulation

・The addition of the sections for EEPROM emulation on CS+

Add sections necessary for code flash memory reprogramming on a "Section Settings" screen. It also includes a section for the RFD RL78 Type 01.

Add to the program area : RFD_DATA_n, RFD_CMN_f, RFD_DF_f, EES_CODE_f, SMP_EES_f, EES_CNST_f

Add to the RAM area : .stack_bss, RFD_DATA_nR, EES_VAR_n, SMP_VAR_n

Be sure to return [Layout sections automatically] to "Yes", after pressing the "OK" button.

Press the right-hand side " ⊡ " button by [ROM to RAM mapped section], display the "Text Edit" screen, and add the section for copying to RAM from ROM.

・The addition of the sections for EEPROM emulation on e² studio

Add sections necessary for EEPROM emulation on a "Section Viewer". It also includes a section for the RFD RL78 Type 01.

Add to the program area : RFD_DATA_n, RFD_CMN_f, RFD_DF_f, EES_CODE_f, SMP_EES_f, EES_CNST_f
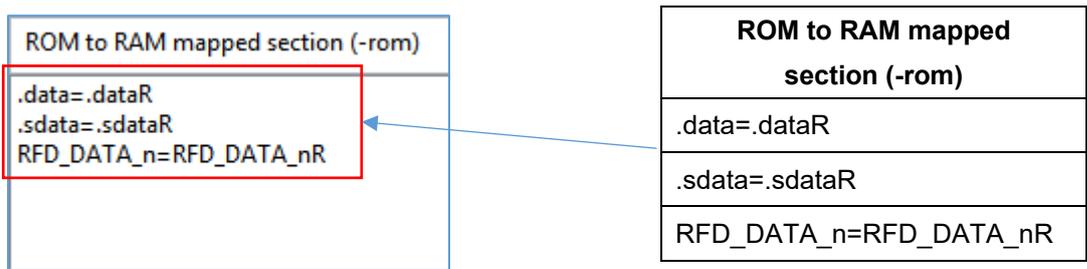
Add to the RAM area : .stack_bss, RFD_DATA_nR, EES_VAR_n, SMP_VAR_n
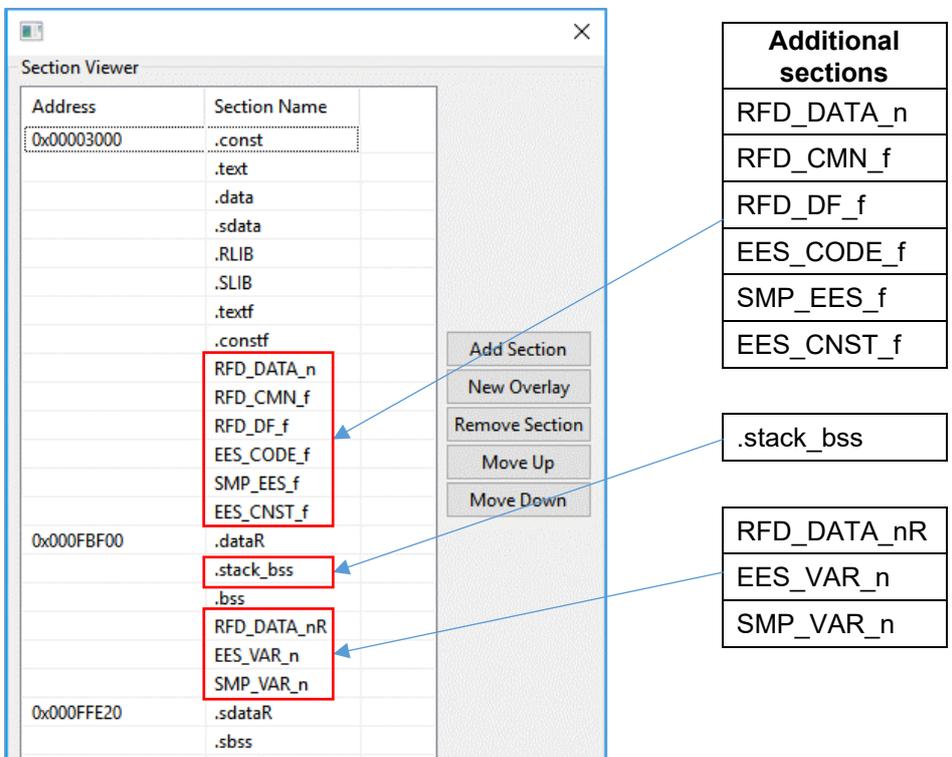
Be sure to put a check mark to [Layout sections automatically (-auto_section_layout)], after pressing the "OK" button.
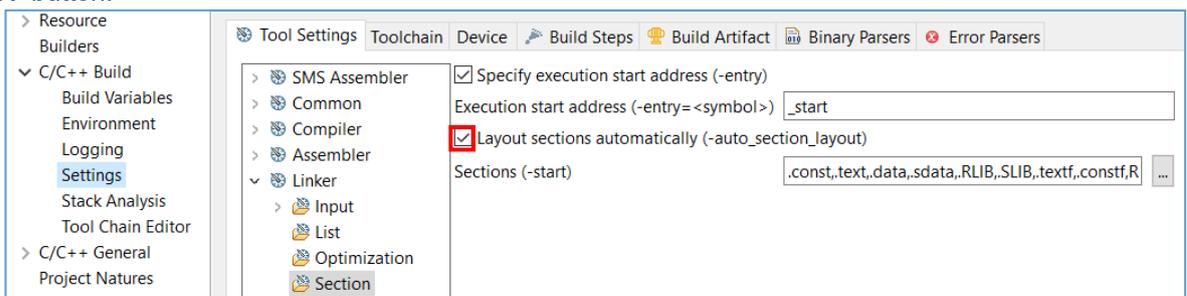
Select "C/C++ Build" [Settings] - "Linker" [Output], display the "ROM to RAM mapped section (-rom)" screen, and add the section for copying to RAM from ROM.

7.1.4   Debug Tool Settings

This section describes the contents of connection setting on a target board necessary in order to execute on-chip debugging. As a debugging tool, it is a premise that E2 Lite is selected. Refer to the user's manual for each IDE for the details of other debugging tool setting.

On CS+, right-click a mouse by "RL78 simulator (Debug Tool)" [initial setting] of a tree. And select the "RL78 E2 Lite" by "Using Debug Tool" displayed there. And a "RL78 E2 Lite Property" screen is displayed, and select each tab, and perform debugging tool setting.
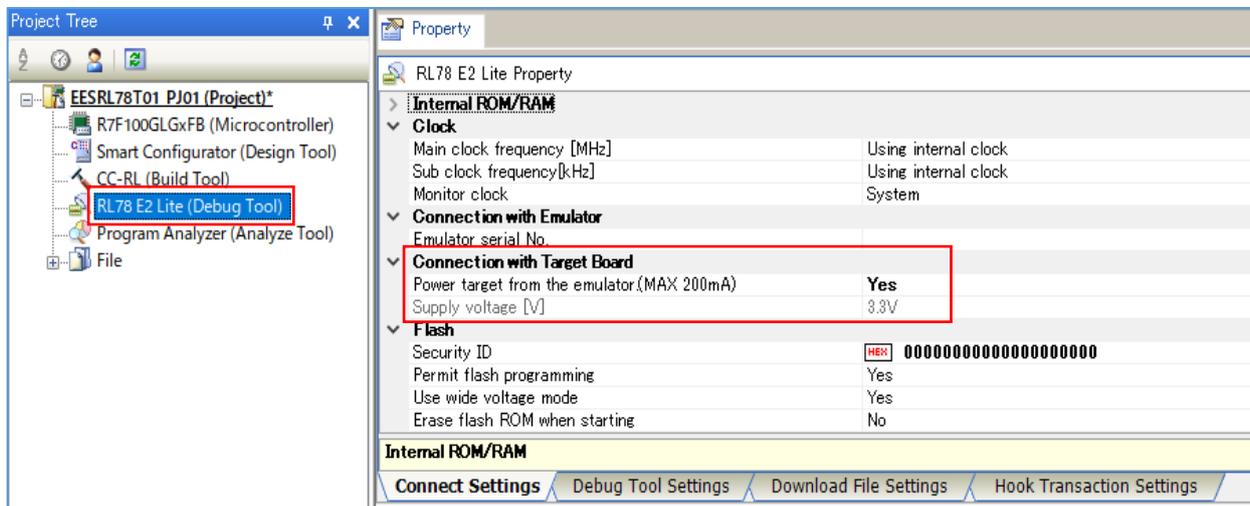
On e^2 studio, right-click a mouse in the target project of a tree. Selection of [Debug As] - [Debug Configurations…] will display the "Debug Configurations" screen. On the tree of a screen, select the target project ("EESRL78T01_PJ01 HardwareDebug") of [Renesas GDB Hardware Debugging]. And the displayed "Debugger" tab performs debugging tool setting.

> **Note: The power is already supplied to the target board, or when power supply capacity is insufficient, the emulator including E2 Lite may be unable to supply power to a target board. Be sure to refer to "the user's manual and Additional Document for User's Manual (Notes on Connection of RL78)" for the emulator for target devices, and use an emulator.**

7.1.4.1   Setting of Connection with Target Board

・On CS+, set up the connection with target board(via E2 Lite) with "Connect Settings" tab.

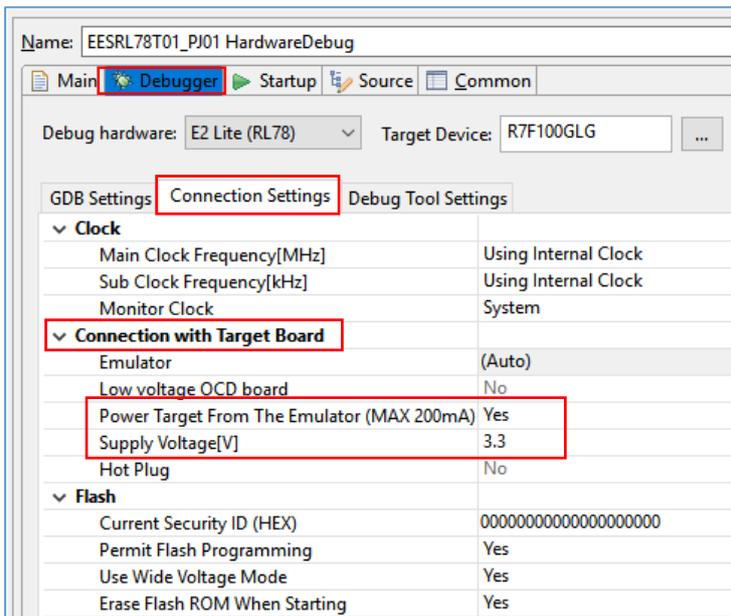 - [Connection with Target Board] item

    In order to let power supply(Supply voltage : 3.3V) from E2 Lite to a target board, it is necessary to set "Yes" to [Power target from the emulator (MAX 200mA)].

・On e^2 studio, set up the connection with target board(via E2 Lite) with "Connection Settings" tab.

  - [Connection with Target Board] item

   In order to let power supply(Supply Voltage : 3.3V) from E2 Lite to a target board, it is necessary to set "Yes" to [Power Target From The Emulator (MAX 200mA)].

Name: EESRL78T01_PJ01 HardwareDebug

| Main | Debugger | Startup | Source | Common |

Debug hardware: E2 Lite (RL78)   Target Device: R7F100GLG [...]

GDB Settings | Connection Settings | Debug Tool Settings

∨ **Clock**	
Main Clock Frequency[MHz]	Using Internal Clock
Sub Clock Frequency[kHz]	Using Internal Clock
Monitor Clock	System
∨ **Connection with Target Board**	
Emulator	(Auto)
Low voltage OCD board	No
Power Target From The Emulator (MAX 200mA)	Yes
Supply Voltage[V]	3.3
Hot Plug	No
∨ **Flash**	
Current Security ID (HEX)	000000000000000000000
Permit Flash Programming	Yes
Use Wide Voltage Mode	Yes
Erase Flash ROM When Starting	Yes

## 7.2   Creating a Project in the Case of Using IAR Compiler

IAR Embedded Workbench can be used for a IAR compiler as an IDE. EES RL78 Type 01 and RFD RL78 Type 01 are registered and built in the project created by the IDE. An example of creating a sample project in case each IDE is used is shown. Because to understand a IAR compiler and each IDE, it is necessary to refer to the user's manual of each tool product.

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7.2.1   Example of Creating a Sample Project

(1) An example of creating a sample project which used IAR Embedded Workbench (IDE)

・The IAR Embedded Workbench starts and from the [Project] menu, select [Create New Project...], the

"Create Project" window will open.

- Select the "C" as [project template].

- When you click the [OK] button, the "Save As" window will open.
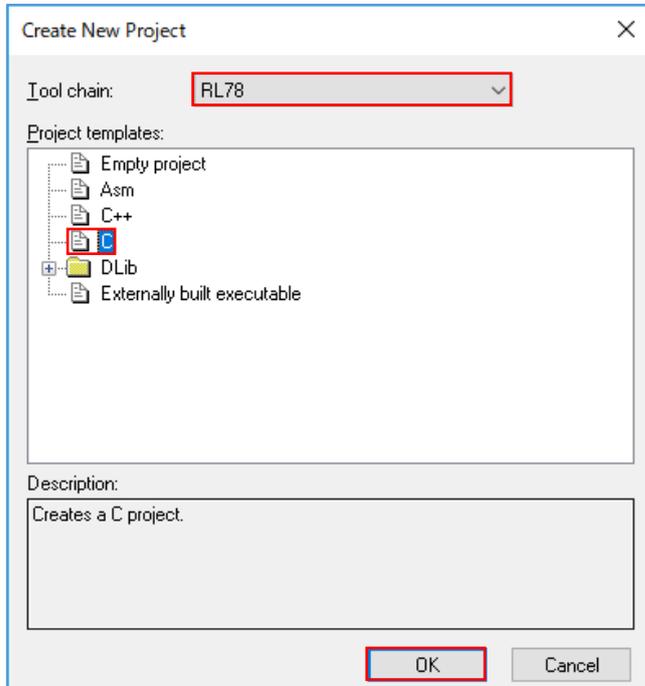
- Create "EESRL78T01_PJ01" folder temporarily, and move into a folder.

- The Project File name is temporarily set to "EESRL78T01_PJ01".
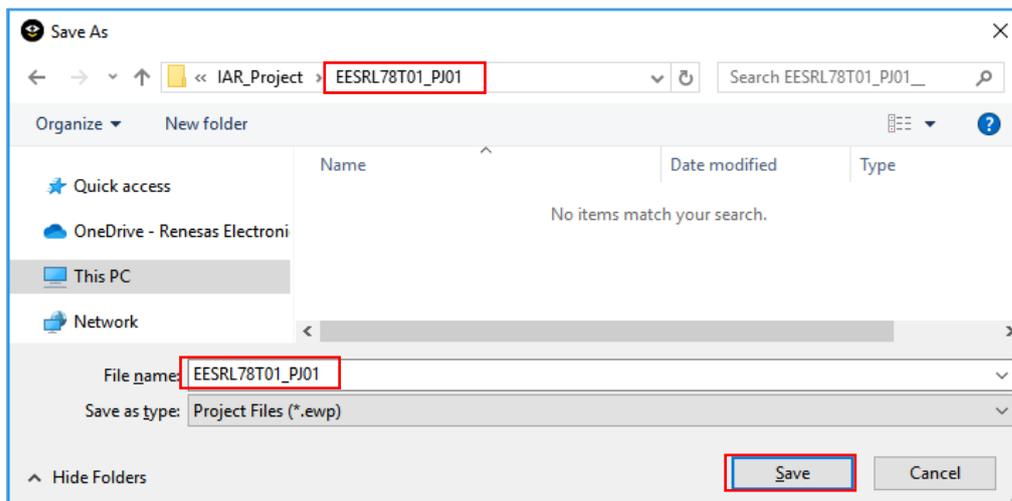
(2) Selection of a target device

・On IAR Embedded Workbench, I click the right mouse button of the project ("EESRL78T01_PJ01 - Debug") in a tree. When an "Options" is selected, the "Options for node [Project name]" window is displayed.
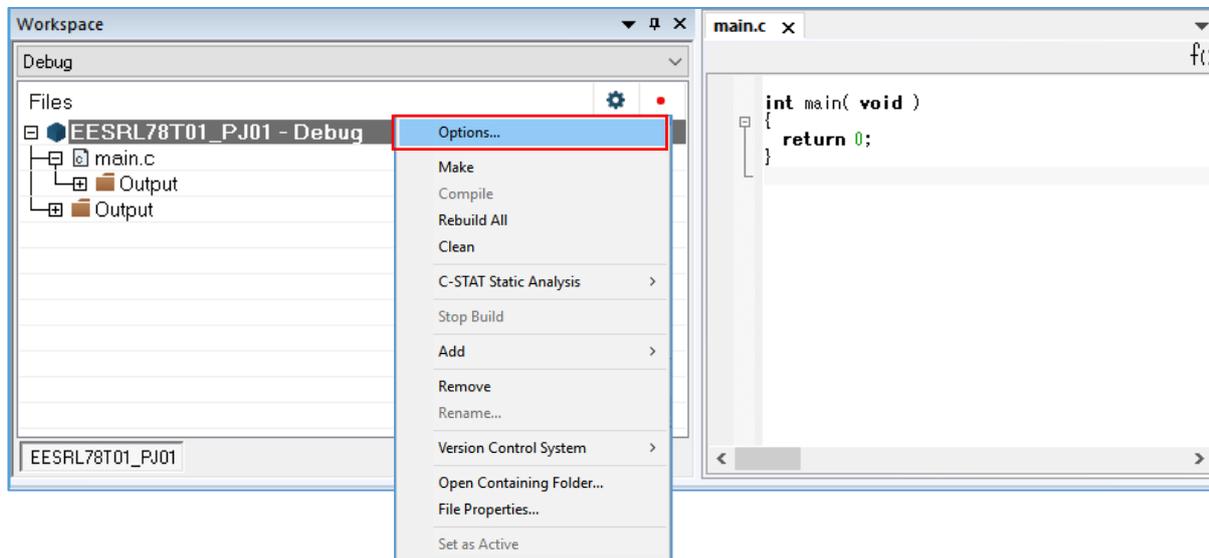
- Input setting in the [General Options] - [Target] tab of "Options for node [Project name]" window.

- Press " 📋 " button of [Device]. And Select "RL78 - G23" - "RL78 - R7F100GLG". Select "Far" as [Code model] and select "Near" as [Data model].
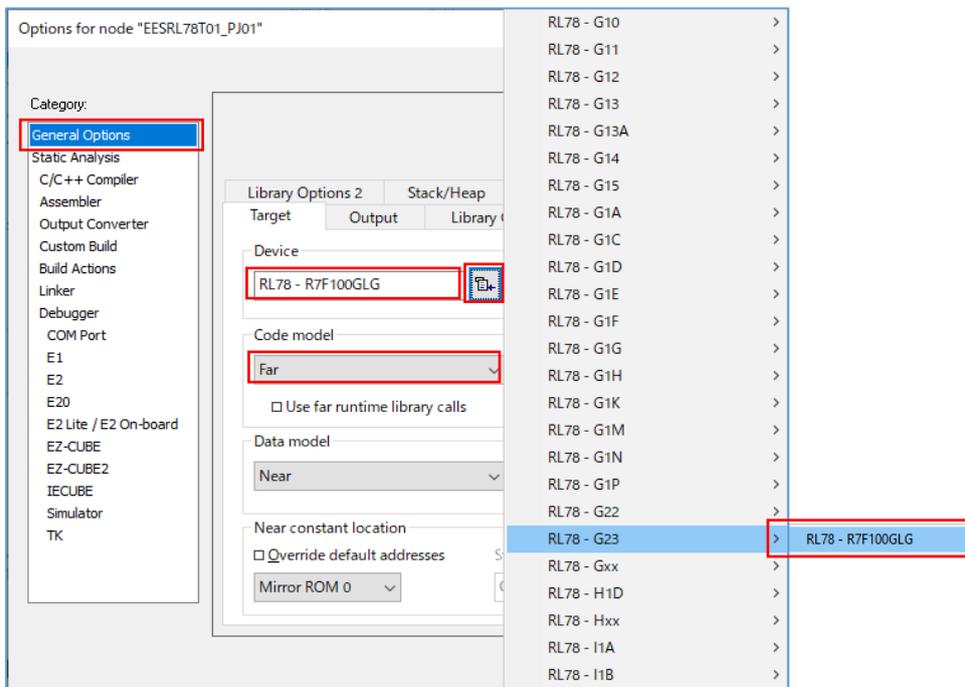
### 7.2.2   Example of Registration of Target Folders and Target Files

This describes an example of file registration required to execute EEPROM emulation.

Instead of registering a folder by IAR Embedded Workbench, select [Add Group] of the [Project] menu, and add a group. The example into which I add the group of the same structure as the folder for EES RL78 Type 01 and RFD RL78 Type 01, and files are registered is shown.

The following example shows (1) EES RL78 Type 01 and (2) RFD RL78 Type 01 groups added:
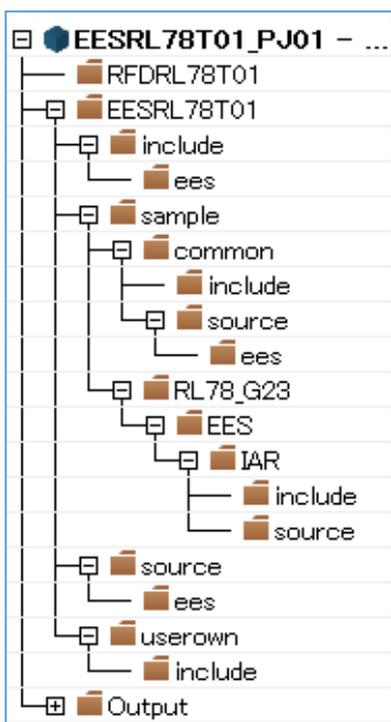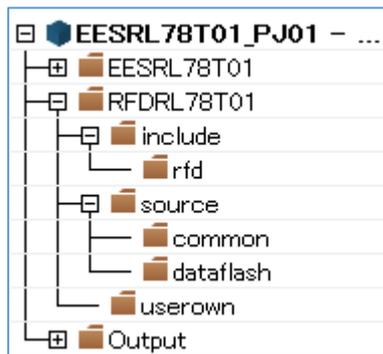
(1) EES RL78 Type 01   (2) RFD RL78 Type 01

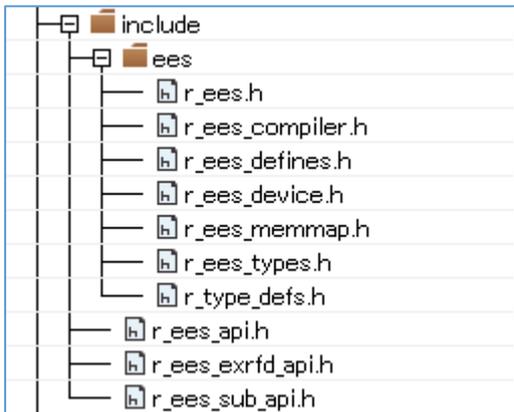・ Exclusion of the file automatically added by the function of IDE.

   There are files added automatically in the created project. The same file as these exists also in the "sample" folder of EES RL78 Type 01. Therefore, using the function of IDE, Select those files from tree and excludes from a project.

    - IAR Embedded Workbench : Clicks the right mouse button for the file of tree. And exclude the target "main.c" file by "Remove" function.
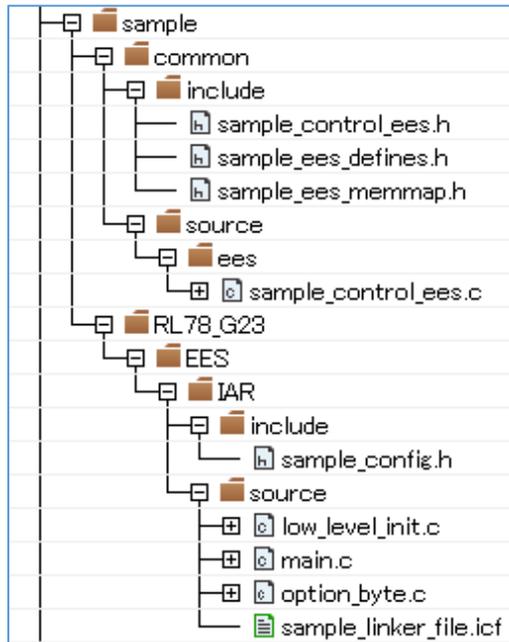
(1) Registration of the EES RL78 Type 01 files.

The groups ("include", "source", "userown", "sample") and source program file which are included in EES
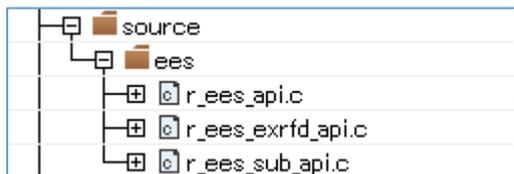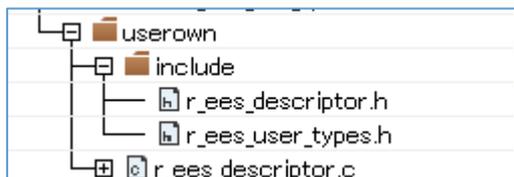RL78 Type 01 to register are shown below.

in the "include" group

```
include
  ees
    r_ees.h
    r_ees_compiler.h
    r_ees_defines.h
    r_ees_device.h
    r_ees_memmap.h
    r_ees_types.h
    r_type_defs.h
  r_ees_api.h
  r_ees_exrfd_api.h
  r_ees_sub_api.h
```

in the "source" group

```
source
  ees
    r_ees_api.c
    r_ees_exrfd_api.c
    r_ees_sub_api.c
```

in the "userown" group

```
userown
  include
    r_ees_descriptor.h
    r_ees_user_types.h
  r_ees_descriptor.c
```

in the "sample" group

```
sample
  common
    include
      sample_control_ees.h
      sample_ees_defines.h
      sample_ees_memmap.h
    source
      ees
        sample_control_ees.c
  RL78_G23
    EES
      IAR
        include
          sample_config.h
        source
          low_level_init.c
          main.c
          option_byte.c
          sample_linker_file.icf
```
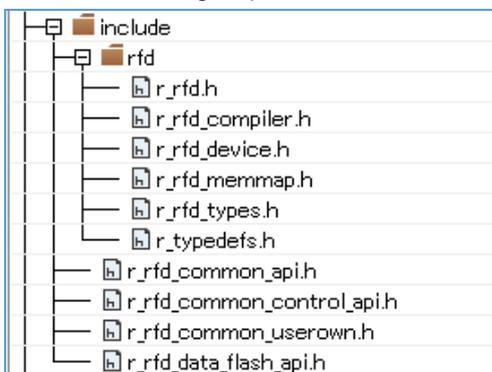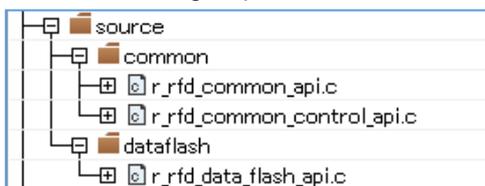
(2) Registration of the RFD RL78 Type 01 files

The groups ("include", "source", "userown") and source program file which are included in RFD RL78
Type 01 to register are shown below.

in the "include" group

```
include
  rfd
    r_rfd.h
    r_rfd_compiler.h
    r_rfd_device.h
    r_rfd_memmap.h
    r_rfd_types.h
    r_typedefs.h
  r_rfd_common_api.h
  r_rfd_common_control_api.h
  r_rfd_common_userown.h
  r_rfd_data_flash_api.h
```

in the "source" group

```
source
  common
    r_rfd_common_api.c
    r_rfd_common_control_api.c
  dataflash
    r_rfd_data_flash_api.c
```

in the "userown" group

```
userown
  r_rfd_common_userown.c
```

7.2.3 Integrated Development Environment(IDE) Settings

Set IDE setting necessary in order to build EEPROM emulation using an IAR compiler.

IAR Embedded Workbench : Click the right mouse button for the project("EESRL78T01_PJ01") in a tree, and select "Options". And set each setting of the "Category" in the displayed window.

7.2.3.1 Include Path Settings

・Setting of the include path on IAR Embedded Workbench selects "C/C++ Compiler" of "Category", and inputs path in "Preprocessor" tab.

  - Input the Include directory path in the "Edit Include Directories" window displayed by selection of [Additional include directories: (one per line)].
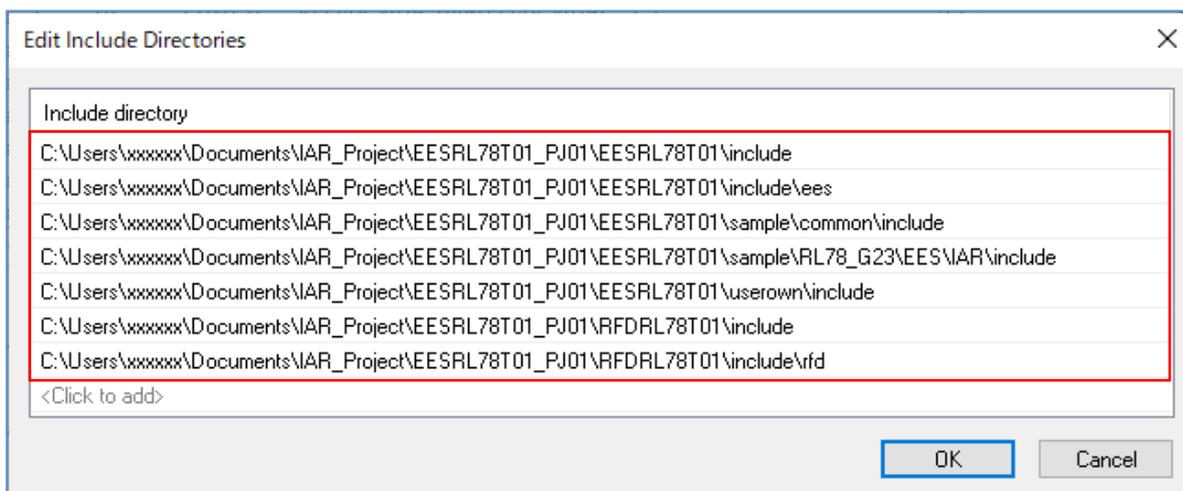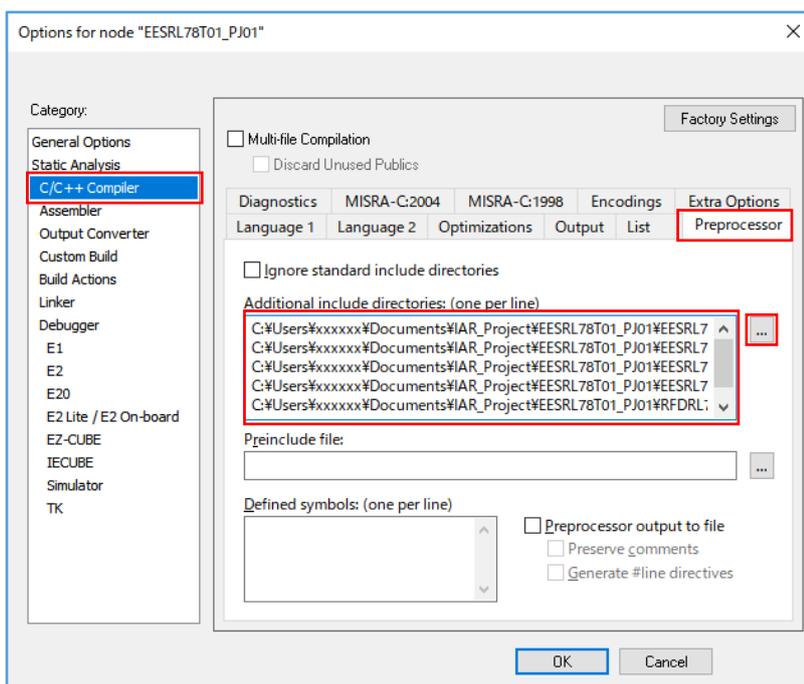
- The example of directory path setting.

   It is the example when the project director is placed in "C:\Users\xxxxxx\Documents\IAR_Project\".

(1) EES RL78 Type 01 include directories

   C:\Users\xxxxxx\Documents\IAR_Project\EESRL78T01_PJ01\EESRL78T01\include

   C:\Users\xxxxxx\Documents\IAR_Project\EESRL78T01_PJ01\EESRL78T01\include\ees

   C:\Users\xxxxxx\Documents\IAR_Project\EESRL78T01_PJ01\EESRL78T01\sample\common\include

   C:\Users\xxxxxx\Documents\IAR_Project\EESRL78T01_PJ01\EESRL78T01\sample\RL78_G23\EES\IAR\include

   C:\Users\xxxxxx\Documents\IAR_Project\EESRL78T01_PJ01\EESRL78T01\userown\include

(2) RFD RL78 Type 01 include directories

   C:\Users\xxxxxx\Documents\IAR_Project\EESRL78T01_PJ01\RFDRL78T01\include

   C:\Users\xxxxxx\Documents\IAR_Project\EESRL78T01_PJ01\RFDRL78T01\include\rfd

Note : About the path setting of include directories.

When the project is copied in the case appointed by the absolute path, the setup is needed again. It is possible to appoint a relative path ($PROJ_DIR$) so that it can be used, even if it copies the project. Refer to each reference manual of IAR Embedded Workbench about how to appoint the relative path.

7.2.3.2 The Setting of User Definition Macro

・On IAR Embedded Workbench, the macro for flash memory control system classification is defined in "Preprocessor" tab.

- Define the following macro in the column of [Defined symbols: (one per line)]. Definition macro differs by each device to be used.
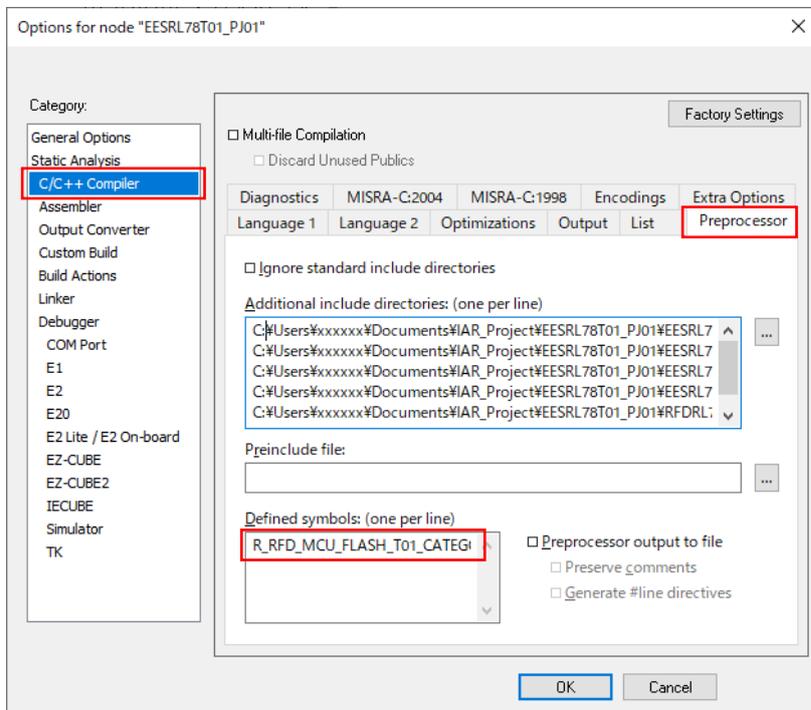
Macros defined when using RL78/G23 or RL78/G22:

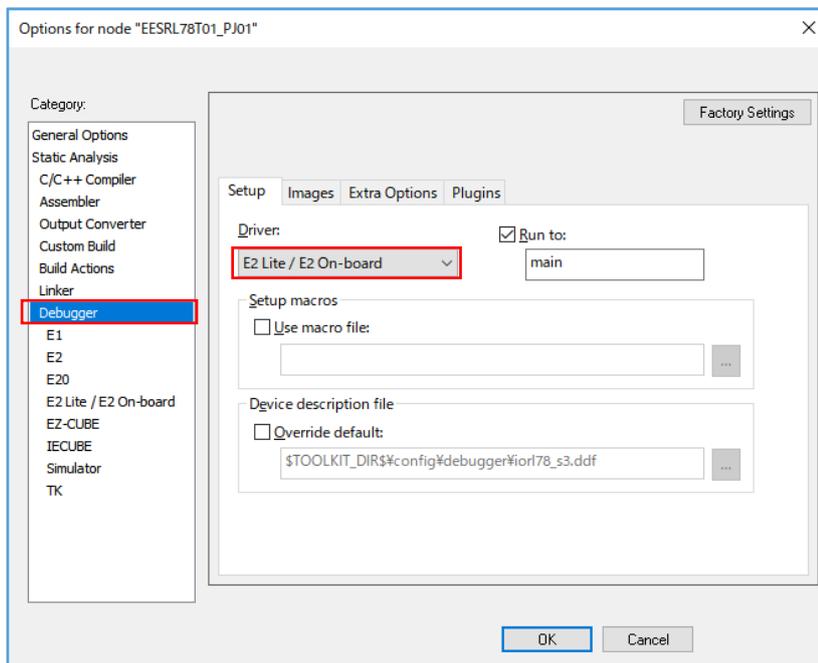   **R_RFD_MCU_FLASH_T01_CATEGORY01**

Macros defined when using RL78/G24:

   R_RFD_MCU_FLASH_T01_CATEGORY02

   Note : A compile error will be outputted if macro is not defined.

7.2.3.3　Debugger Settings

・Select "E2 Lite/E2 On-Board" from [Driver] of [Debugger] – [Setup] tab on the assumption that on-chip debugging is implemented.
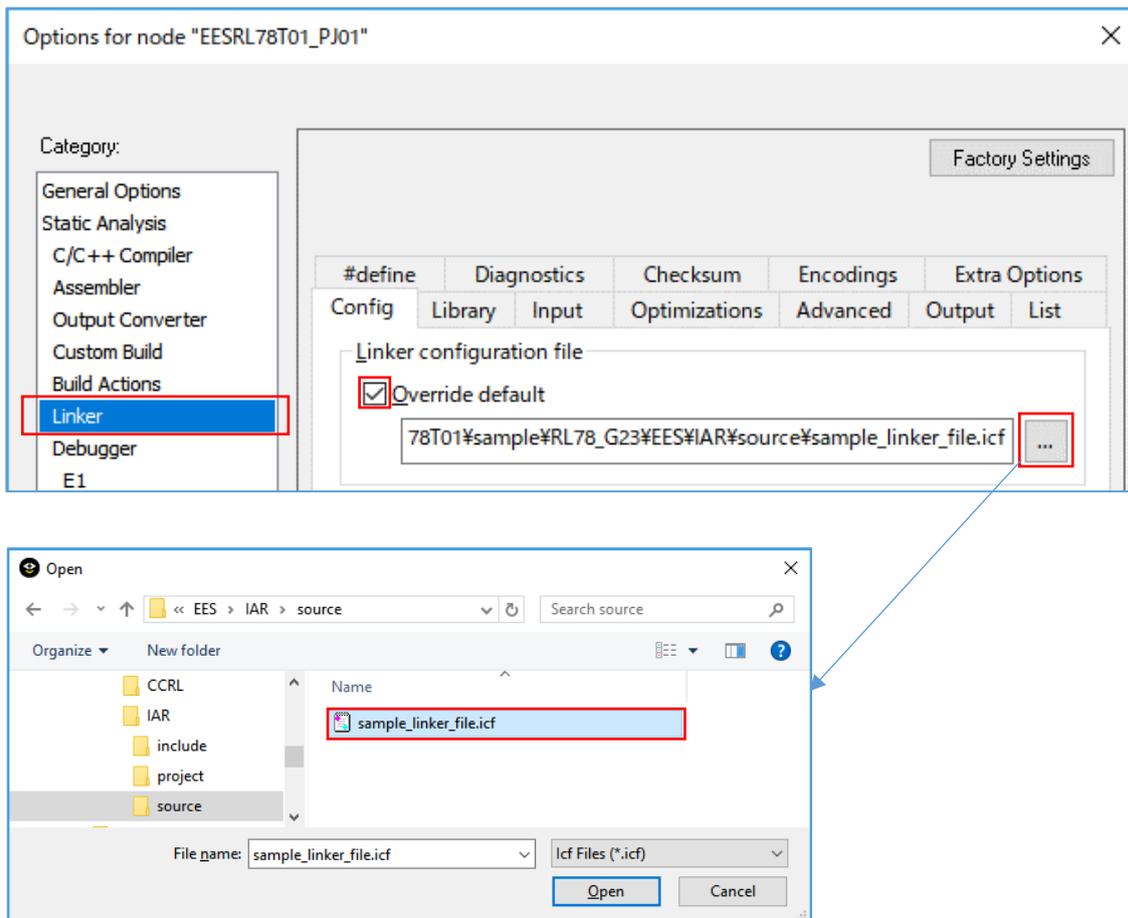

Note : Refer to each reference manual of IAR Embedded Workbench about the other items to be set.

7.2.4   Linker Configuration File(.icf) Settings

On IAR Embedded Workbench, Linker configuration file (*. icf) describes link setting executed by building. Select "Options" by the click right mouse button of project with tree. Select [Linker] by "Category" in the displayed window, And put a check mark to "Override default" of the [Config] tab. Select Linker configuration file (*. icf) in the "Open" window of " " button. Select the "sample_linker_file.icf" file prepared for EES RL78 Type 01.

- sample_linker_file.icf (\sample\RL78_G23\EES\IAR\source\)

Note : Refer to each reference manual of IAR Embedded Workbench about the descriptive content of Linker configuration file, and the details of the description method.

7.2.4.1   Section Settings

The outline of the section added to Linker configuration file (*. icf) currently prepared by EES RL78 Type 01
explained.

> **Note : Refer to each reference manual of IAR Embedded Workbench about the section setting
> method and the detail of functions for Linker configuration file.**

(1) The addition of the sections for EES RL78 Type 01.
    Add the initial value of each section of EES_CODE, SMP_EES, and EES_CNST to ROM area
    (ROM_far).

    - The additional section of the ROM_far area:
      EES_CODE, SMP_EES, EES_CNST

    - The additional section of RAM_near area:
      EES_VAR, SMP_VAR

(2) The addition of the sections for RFD RL78 Type 01.
    Add the initial value of each section of RFD_DATA, RFD_CMN, and RFD_DF to ROM area (ROM_far). It
    is necessary to copy RFD_DATA to the section of RAM area (RAM_near).

    - The additional section of the ROM_far area (The program and The data for copying to RAM area to be
     placed in ROM area):
     RFD_DATA_init, RFD_CMN, RFD_DF

    - The additional section of RAM_near area (Data copied from ROM area):
     RFD_DATA

7.2.4.2 Option Bytes Settings

The Option bytes definition of RL78 is described in Linker configuration file (*. icf) of IAR Embedded
Workbench attachment or the sample_linker_file.icf file prepared for EES RL78 Type 01. The Option Bytes
value for EES RL78 Type 01 is described by the "option_byte.c" file.

> **Note : Refer to each reference manual of IAR Embedded Workbench about the option bytes
> setting method for Linker configuration file.**

The example of an Option Bytes definition of Linker configuration file for EES RL78 Type 01 (*. icf).

```
define block OPT_BYTE with size = 4   { R_OPT_BYTE,
                                        ro section .option_byte,
                                        ro section OPTBYTE };
                          |
place at address mem:0x000C0          { block OPT_BYTE };
```

The example of description of the Option Bytes value in an "option_byte.c" file.

```
#pragma location = "OPTBYTE"
__root const unsigned char option_bytes[4] = {
    0x6E,    /* 01101110 */
             /* |||||||| */
             /* |||||||+-- Watchdog timer       */
             /* |||||||    operation stopped    */
             /* |||||||    in HALT/STOP mode     */
             /* ||||+++--- Watchdog timer        */
             /* ||||       overflow time is      */
             /* ||||       2^17 / fIL =          */
             /* ||||       3478.26 ms            */
             /* |||+------ Watchdog timer        */
             /* |||        operation disabled    */
             /* |++------- 100% window open      */
             /* |          period                */
             /* +--------- Interval interrupt    */
             /*            is not used           */
    0xFF,    /* 11111111 */
             /*        | */
             /*        +-- LVD reset mode */
    0xE8,    /* HS mode 32 MHz */
    0x85     /* OCD: enables on-chip debugging function */
};
```

- Description of user option byte value:

   The value of User option byte (000C0H-000C2H) in "option_byte.c" file is "0x6EFFE8".
   (WDT stop, LVD reset mode, HS mode /32MHz [The example for RL78/G23])

   The value of on-chip debug option byte(000C3H/040C3H) in "option_byte.c" file is "0x85".
   (The example of enable on-chip debug operation)

> **Note : Be sure to confirm the contents of "User option byte" of the chapter of "Option Bytes",
> and "On-chip debug option byte" by the user's manual of a target device. And describe the
> set value used with user application.**

7.2.5   On-chip Debug Settings

After executing building of a target project, connect E2 Lite, select [Download and Debug] from [Project] menu, and start debugging.

7.2.5.1 Example of How to Deal with Connection Errors

Explain the common examples of how to deal with an error which happened by connection in on-chip run debug. This is the case when an ID code mismatch or power failure occurs.

> **Note : In cases where a target cannot be connected by other causes, please confirm each reference manual from [Help] of IAR Embedded Workbench.**

When selecting [Download and Debug] and starting debugging, an "E2 Lite hardware setting" screen may be displayed. The cause may be ID code mismatch or power setting error.

- In the case of the ID code mismatch:

    "Cannot verify the ID code." etc. may be displayed as a message. In this case, put a check mark to "Erase flash before next ID check" of the [ID Code] in an "E2 Lite HardwareSetup" window, and continue. And the flash memory is erased and debugger may be connected.

- In the case of power setting error:

    Initial setting of "Power supply" is "Target". When supplying power supply from E2 Lite, select "3V" by the pull down menu for "Power supply".

> **Caution: Be sure not to set "3V"(supply power from E2 Lite), when the power is supplied to the target.**
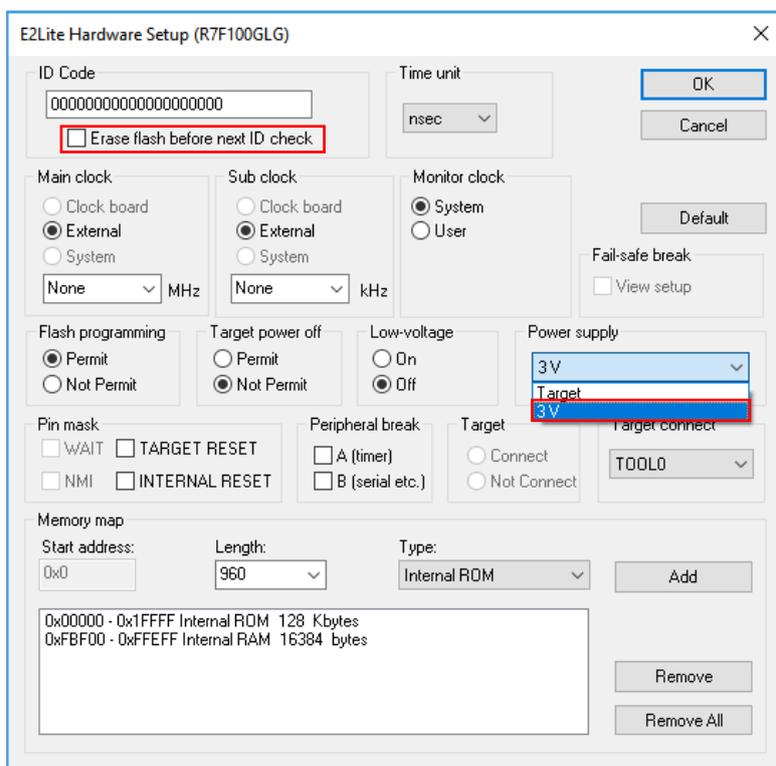
7.3   Creating a Project in the Case of Using LLVM Compiler

e^2 studio can be used for a LLVM compiler as an IDE. EES RL78 Type 01 and RFD RL78 Type 01 are registered and built in the project created by the IDE. An example of creating a sample project in case e^2 studio is used is shown. Because to understand a LLVM compiler and e^2 studio, it is necessary to refer to the user's manual of each tool product.
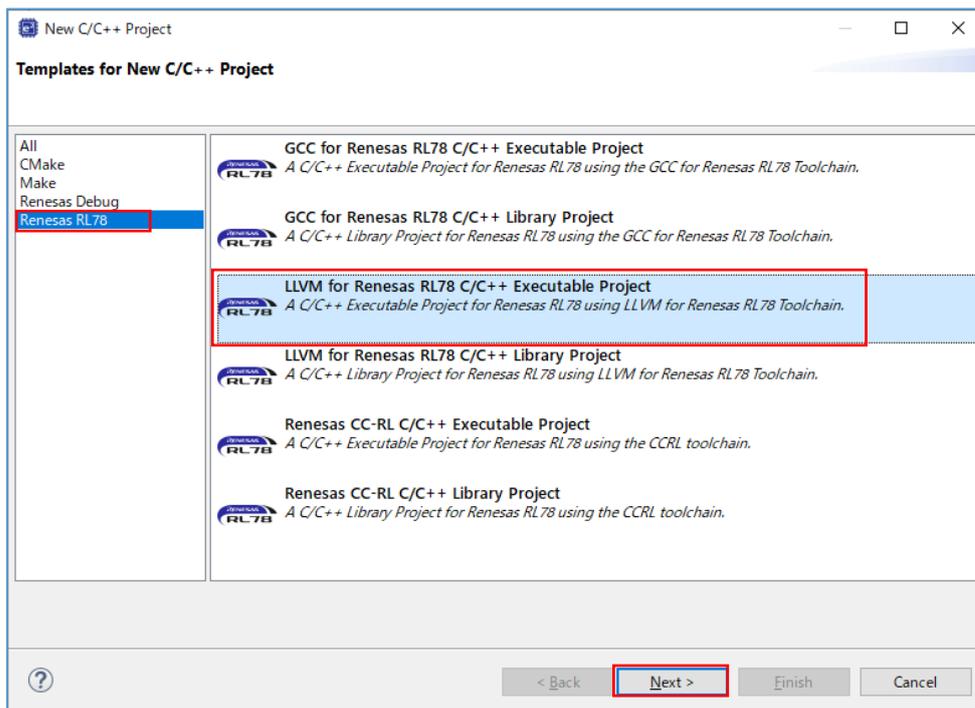
7.3.1   Example of Creating a Sample Project

An example of creating a sample project which used e^2 studio (IDE)

・The e^2 studio starts and from the [File] menu, select [New] – [C/C++ Project], the "Templates for New

C/C++ Project" window will open.
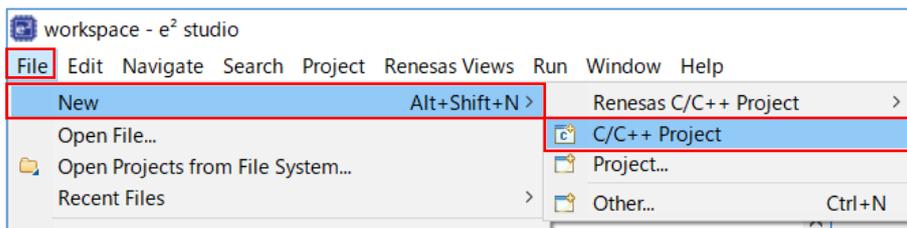
・Select [LLVM for Renesas RL78 C/C++ Executable Project] displayed after selection in [Renesas RL78],

and press "Next" button.

・Input "Project name" on "New LLVM for Renesas RL78 Executable Project" window, and press "Next" button. [Project name] is temporarily set to "EESRL78T01_PJ01".
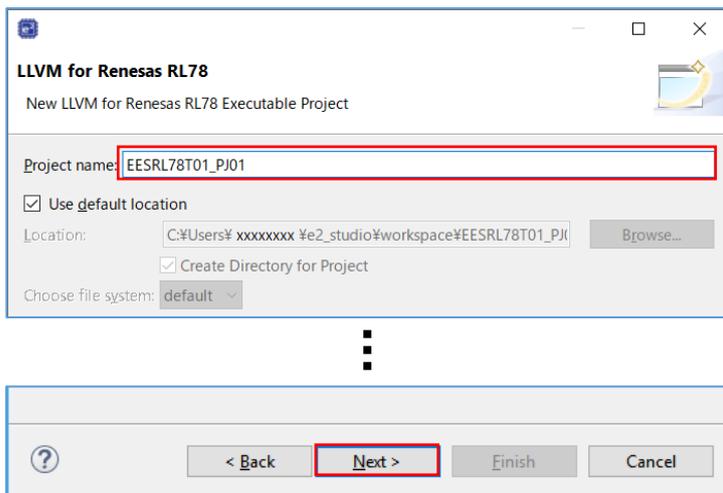
・Select the [Target Device] of [Device Settings], and select "RL78 - G23" – "RL78 - G23 64pin" -
"R7F100GLGxFB".
・It is a premise that E2 Lite is selected as a debugging tool and on-chip debugging is executed. Put a check
mark to "Create Hardware Debug Configuration" by [Configurations]. And select "E2 Lite (RL78)".
・Press "Next" button.
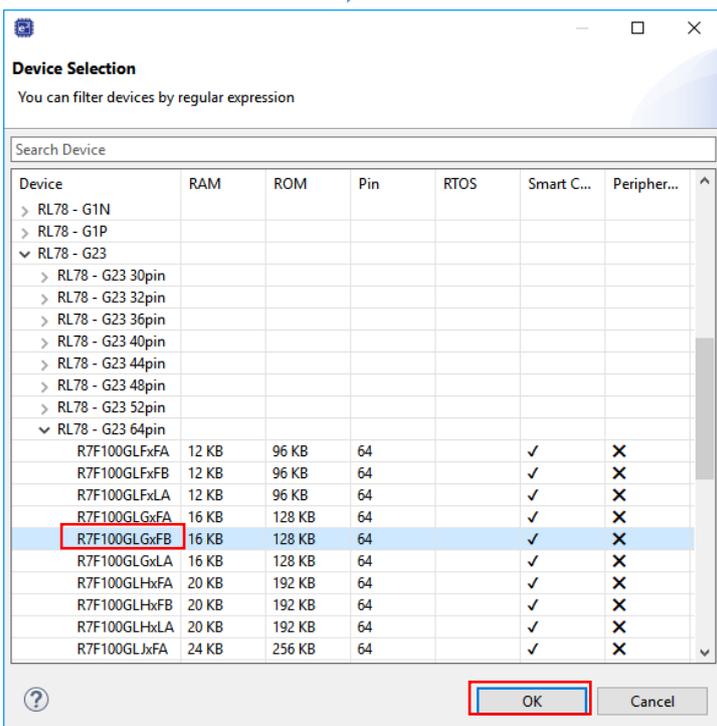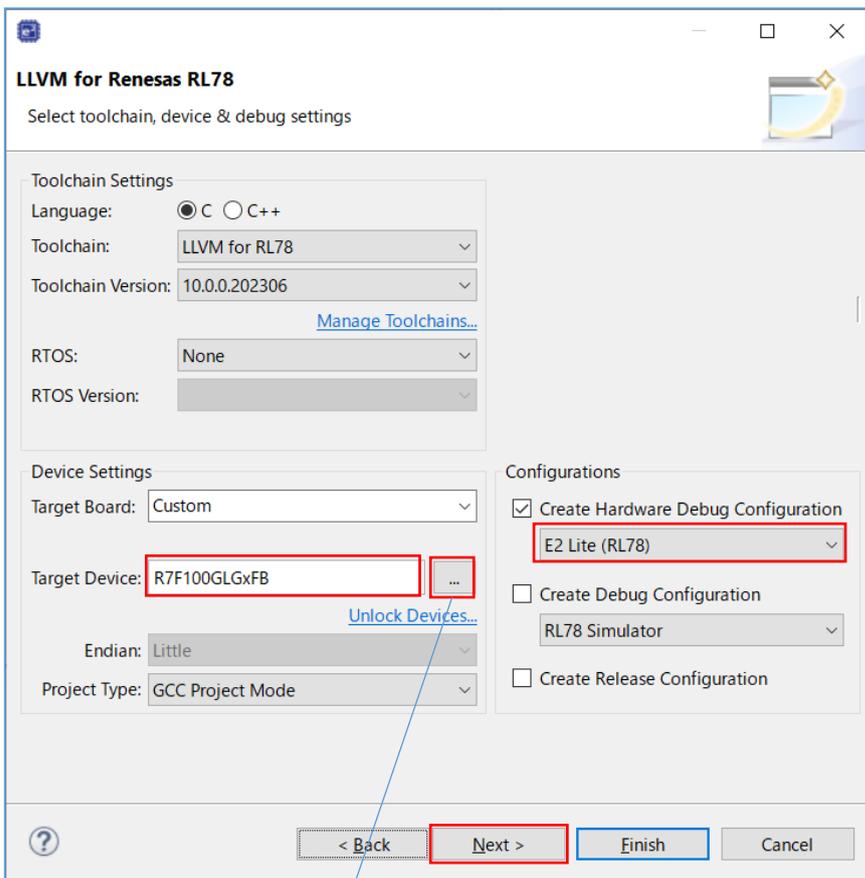
・Uncheck the "Use Smart Configurator".

・Press the [Finish] button.
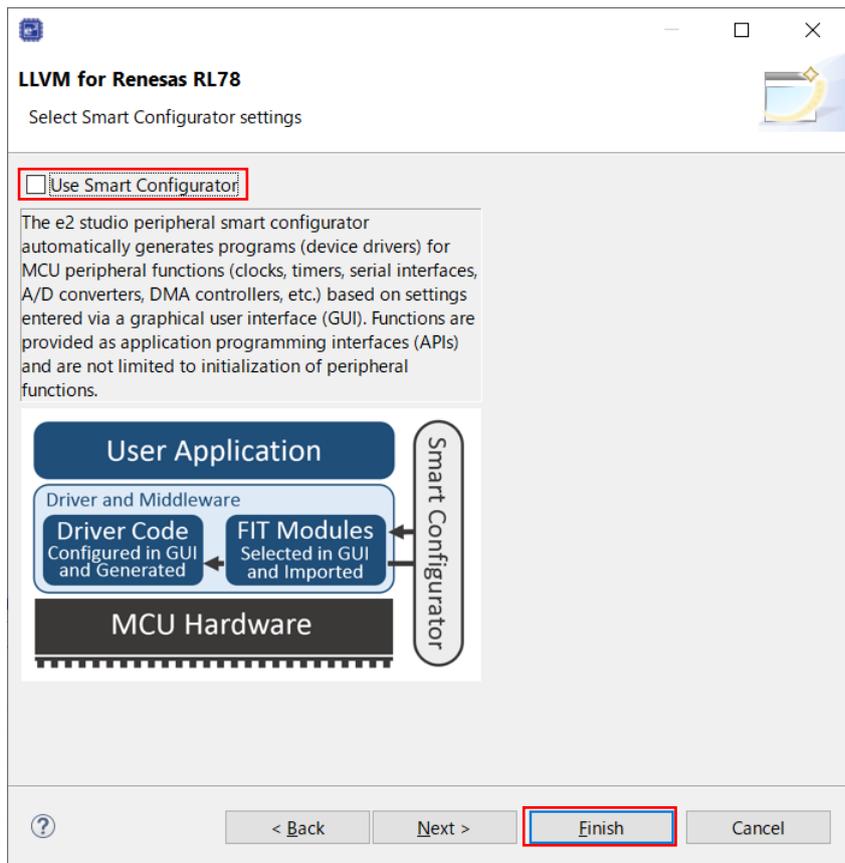
7.3.2   Example of Registration of Target Folders and Target Files

Using EES RL78 Type 01, when execute EEPROM emulation the example which registers necessary files is shown. Each folder of a "EESRL78T01" source program file is "include", "source", "userown", and "sample".

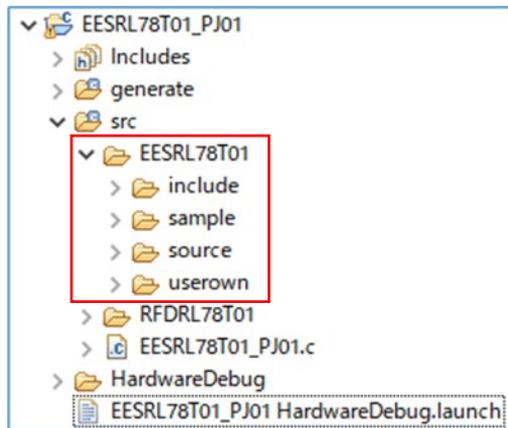As other registration methods, after all the folders of "include", "source", "userown", and "sample" are registered, unnecessary files and folders can be removed using the function of [Resource Configuration] – [Exclude from Build].

The registration tree screen of EES RL78 Type01(e² studio)

Note : Register the "generate" folder output by e² studio as necessary.

・Registration of the latest I/O header file outputted to target products by e² studio

"iodefine.h" and "iodefine_ext.h" are an I/O header file which e² studio output to target products. Replacing instead of "iodefine.h" and "iodefine_ext.h" included in EES RL78 Type 01 is recommended. Registration of target folders and target files are implemented. Then, a user replaces "iodefine.h" and "iodefine_ext.h" which IDE outputted with "iodefine.h" and "iodefine_ext.h" included in EES RL78 Type 01.

・Registration of the vector table file outputted to target products by e² studio

"interrupt_handlers.h", "inthandler.c" and "vects.c" are files that contain vector tables that e² studio outputs for the target product. Since it depends on the product, please replace "interrupt_handlers.h", "inthandler.c" and "vects.c" included in EES RL78 Type 01.
When these are replaced, change the option byte values in the "vects.c" file. Refer to "7.3.4 Option Bytes Settings" for details on setting option byte values.

The folder to which "iodefine.h", "iodefine_ext.h", "interrupt_handlers.h", "inthandler.c" and "vects.c" files are outputted by e² studio:

   - [Project name]/generate

The folder with which a user replaces the "iodefine.h", "iodefine_ext.h" and "interrupt_handlers.h" files:

   - \[Project name]\src\EESRL78T01\sample\RL78_G23\EES\LLVM\include

The folder with which a user replaces the "inthandler.c" and "vects.c" files:

   - \[Project name]\src\EESRL78T01\sample\RL78_G23\EES\LLVM\source

・Exclusion of the file automatically added by the function of e^2 studio.

There are files added automatically in the created project. The same files as these exists also in the "sample" folder of EES RL78 Type 01. Therefore, using the function of e^2 studio, select those files from tree and excludes from a project.

- e^2 studio: Clicks the right mouse button for the file of tree. And on the [Settings] screen displayed by the "Properties", put a check mark to [Exclude resource from build] and exclude a target file (target folder). (Exclusion of a folder is also possible)

The "hwinit.c", "linker_script.ld", "start.S" and "typedefine.h" in the [project name]/generate folder, and [project name].c (in this case "EESRL78T01_PJ01.c") in the [project name]/src folder are not used in EES RL78 Type 01. Therefore, exclude those from the project.

(1) Registration the EES RL78 Type 01 target folders and target files.

The folders ("include", "source", "userown", "sample") and source program file which are included in EES RL78 Type 01 to register are shown below.

in the "include" folder

```
v include
  v ees
    > r_ees_compiler.h
    > r_ees_defines.h
    > r_ees_device.h
    > r_ees_memmap.h
    > r_ees_types.h
    > r_ees.h
    > r_type_defs.h
  > r_ees_api.h
  > r_ees_exrfd_api.h
  > r_ees_sub_api.h
```

in the "source" folder

```
v source
  v ees
    > r_ees_api.c
    > r_ees_exrfd_api.c
    > r_ees_sub_api.c
```
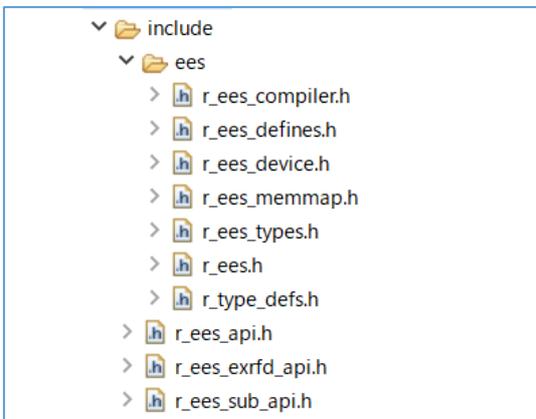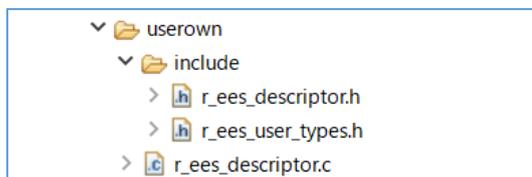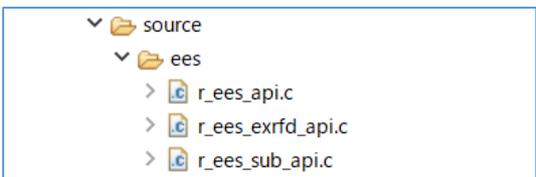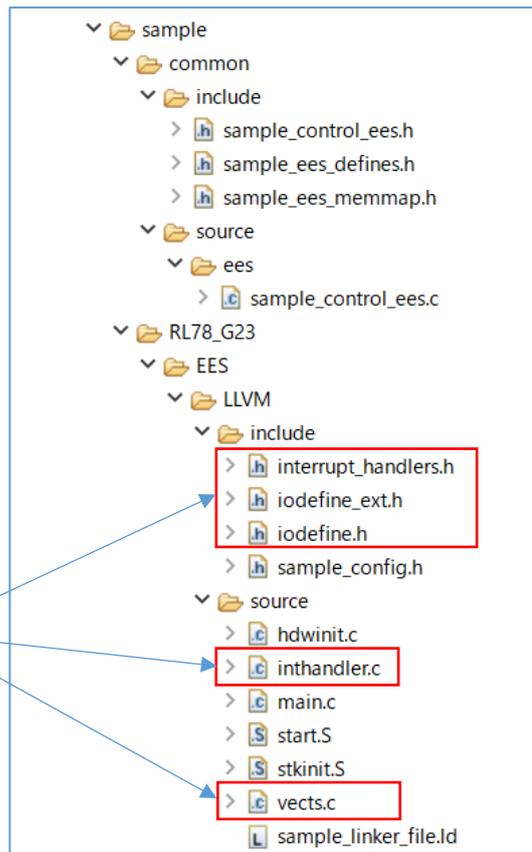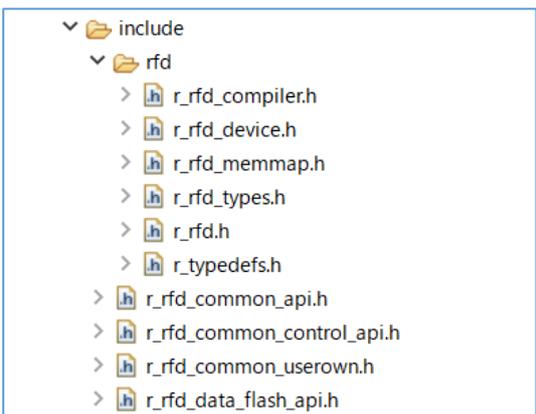
Transpose to "iodefine.h", "iodefine_ext.h", "interrupt_handlers.h", "inthandler.c" and "vects.c" outputted by e² studio.
* **"vects.c"** should change the option byte value.

in the "userown" folder

```
v userown
  v include
    > r_ees_descriptor.h
    > r_ees_user_types.h
  > r_ees_descriptor.c
```

in the "sample" folder

```
v sample
  v common
    v include
      > sample_control_ees.h
      > sample_ees_defines.h
      > sample_ees_memmap.h
    v source
      v ees
        > sample_control_ees.c
  v RL78_G23
    v EES
      v LLVM
        v include
          > interrupt_handlers.h
          > iodefine_ext.h
          > iodefine.h
          > sample_config.h
        v source
          > hdwinit.c
          > inthandler.c
          > main.c
          > start.S
          > stkinit.S
          > vects.c
          L sample_linker_file.ld
```

(2) Registration the RFD RL78 Type 01 target folders and target files.

The folders ("include", "source", "userown") and source program file which are included in RFD RL78 Type 01 to register are shown below.

in the "include" folder

```
v include
  v rfd
    > r_rfd_compiler.h
    > r_rfd_device.h
    > r_rfd_memmap.h
    > r_rfd_types.h
    > r_rfd.h
    > r_typedefs.h
  > r_rfd_common_api.h
  > r_rfd_common_control_api.h
  > r_rfd_common_userown.h
  > r_rfd_data_flash_api.h
```

in the "source" folder

```
v source
  v common
    > r_rfd_common_api.c
    > r_rfd_common_control_api.c
  v dataflash
    > r_rfd_data_flash_api.c
```

in the "userown" folder

```
v userown
  > r_rfd_common_userown.c
```

7.3.3 Build Tool Settings

Set e^2 studio setting necessary in order to build EES RL78 Type 01 using a LLVM compiler.
Click the right mouse button for the project ("EESRL78T01_PJ01") in a tree, and select "Properties". And set each setting of the build tool in the displayed window.

7.3.3.1 Include Path Settings

・Setting of the include path on e^2 studio inputs path in "Properties" window.
 - Input the include directory path in the window displayed by selection of "C/C++ Build" [Settings] -
  "Compiler" [Includes].

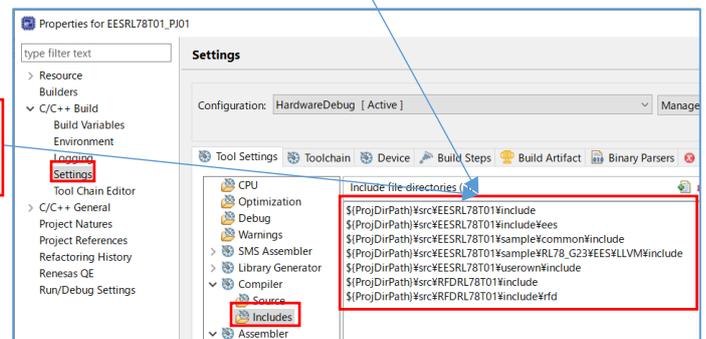(1) EES RL78 Type 01 include path

> ${ProjDirPath}\src\EESRL78T01\include
> ${ProjDirPath}\src\EESRL78T01\include\ees
> ${ProjDirPath}\src\EESRL78T01\sample\common\include
> ${ProjDirPath}\src\EESRL78T01\sample\RL78_G23\EES\LLVM\include
> ${ProjDirPath}\src\EESRL78T01\userown\include

(2) RFD RL78 Type 01 include path

> ${ProjDirPath}\src\RFDRL78T01\include
> ${ProjDirPath}\src\RFDRL78T01\include\rfd

7.3.3.2 The Setting of User Definition Macro

- On e^2 studio, the macro for flash memory control system classification is defined in "Properties" window.
  - Define the following macro in the "Macro Defines (-D)" displayed by selection of "C/C++ Build"
  [Settings] – "Compiler" [Includes]. Definition macro differs by each device to be used.

Macros defined when using RL78/G23, or RL78/G22:

R_RFD_MCU_FLASH_T01_CATEGORY01

Macros defined when using RL78/G24:

R_RFD_MCU_FLASH_T01_CATEGORY02
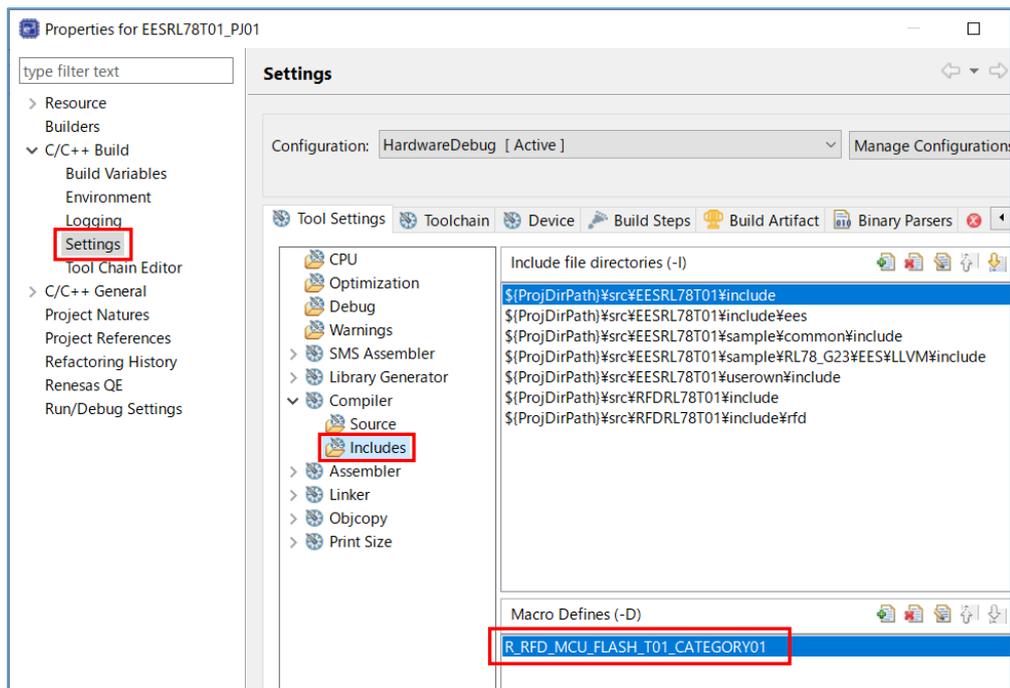
Note : A compile error will be outputted if macro is not defined.

7.3.3.3　Linker Script File (.ld) Settings

On LLVM, linker script file (*.ld) describes link setting executed by building. Click the right mouse button for the project ("EESRL78T01_PJ01") in a tree, and select "Properties". And set each setting of the build tool in the displayed window. Input the include linker script file path in the window displayed by selection of "C/C++ Build" [Settings] – "Linker" [Source].

Input the path to the "sample_linker_file.ld" file contained in the EES RL78 Type 01 sample program.

The linker script file (*.ld) for EES RL78 Type 01 is as follows:

- sample_linker_file.ld (\sample\RL78_G23\EES\LLVM\source\)
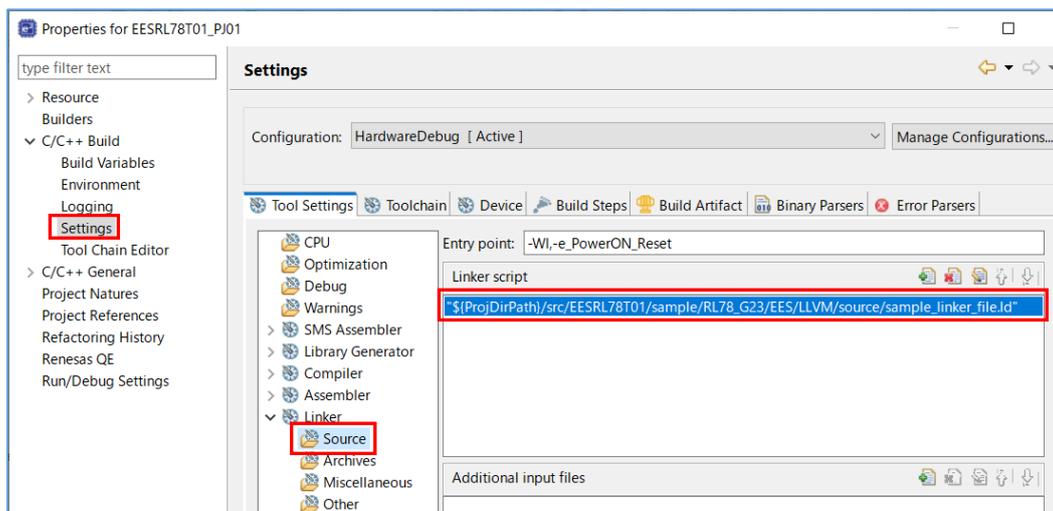
Note : Refer to each reference manual of LLVM about the descriptive content of linker script file, and the details of the description method.

7.3.3.4 Section Settings

The setting outline of the section item described to linker script file (*.ld) of EES RL78 Type 01.

(1) The sections for EES RL78 Type 01.

- The section of code to be placed in the ROM area:

  EES_CODE, SMP_EES

  (EES_ROM_CODE)

- The section of const data to be placed in the ROM area:

  EES_CNST

- The section of data to be placed in the RAM area:

  EES_VAR, SMP_VAR

(2) The sections for RFD RL78 Type 01.

- The section of code to be placed in the ROM area:

  RFD_CMN, RFD_DF

  (RFD_ROM_CODE)

- Section of data that is copied from the ROM area to the RAM are:

  RFD_DATA

Note: When using the LLVM compiler, the compiler may automatically add subsections with different names when common processing is detected within the same section. Therefore, the following sections are added to the description in the sample_linker_file.ld file.

     EES_XXXX.* and SMP_XXXX.* ("XXXX" = "CODE", "EES", "VAR" or "CNST")

**Examples of subsections that could be added: EES_CODE.outlined-functions (etc.)
Refer to each reference manual of LLVM about the section setting method and the detail of functions for linker script file.**

7.3.4   Option Bytes Settings

"Option Bytes" settings when using the LLVM compiler are set in the "vects.c" file.

Target file name: vects.c

  - \[Project name]\src\EESRL78T01\sample\RL78_G23\EES\LLVM\source\vects.c

Description of user option byte value:

In the "vects.c" file provided in the sample program, the option byte value and user option byte value are set in "Option_Bytes" as follows.

[The example for RL78/G23]

"0x6e, 0xff, 0xe8, 0x85" (WDT stop, LVD reset mode, HS mode/32MHz, Enable on-chip debug operation)

```
#include "interrupt_handlers.h"

extern void PowerON_Reset (void);

const unsigned char Option_Bytes[]    __attribute__ ((section (".option_bytes"))) = {
     0x6e, 0xff, 0xe8, 0x85
};
```

Note : Be sure to confirm the contents of "User option byte" of the chapter of "Option Bytes", and "On-chip debug option byte" by the user's manual of a target device. And describe the set value used with user application.

7.3.5 Debugger Settings

This section describes the contents of connection setting on a target board necessary in order to execute on-chip debugging. As a debugging tool, it is a premise that E2 Lite is selected. Refer to the user's manual for IDE for the details of other debugging tool setting.

On e^2 studio, right-click a mouse in the target project of a tree. Selection of [Debug As] - [Debug Configurations…] will display the "Debug Configurations" screen. On the tree of a screen, select the target project ("EESRL78T01_PJ01 HardwareDebug") of [Renesas GDB Hardware Debugging]. And the displayed "Debugger" tab performs debugging tool setting.

> **Note: The power is already supplied to the target board, or when power supply capacity is insufficient, the emulator including E2 Lite may be unable to supply power to a target board. Be sure to refer to "the user's manual and Additional Document for User's Manual (Notes on Connection of RL78)" for the emulator for target devices, and use an emulator.**

・On e^2 studio, set up the connection with target board(via E2 Lite) with "Connection Settings" tab.

  - [Connection with Target Board] item

    In order to let power supply(Supply Voltage : 3.3V) from E2 Lite to a target board, it is necessary to set "Yes" to [Power Target From The Emulator (MAX 200mA)].
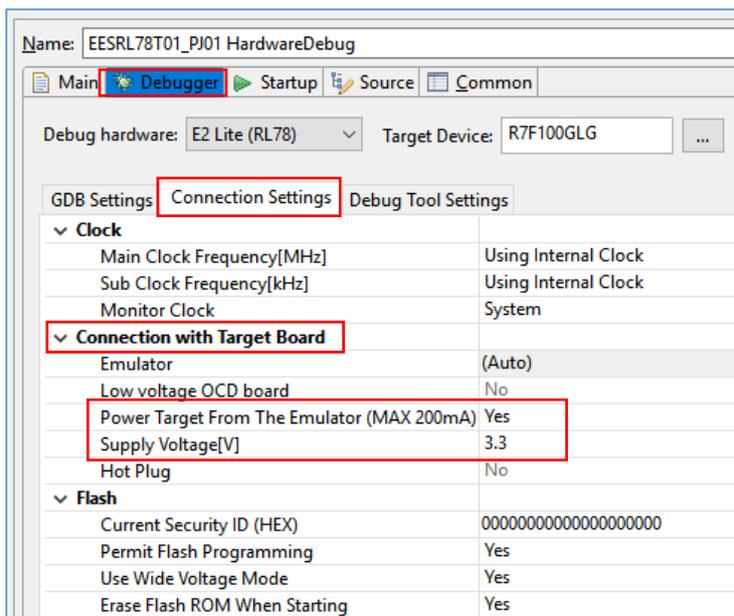
7.4   Configurations Modify Procedure for Changing Device

When using devices other than those targeted by the EES RL78 Type 01 sample program, ROM, RAM, and data flash memory sizes are different, so section addresses and some of the sample programs must be modified. This section describes the procedure to modify and where to modify.

Target device in a "sample" folder:
- "RL78_G23" folder [CATEGORY01]. Target device for the prepared file:

  RL78/G23 (R7F100GLG ROM: 128 Kbytes, RAM: 16 Kbytes, DF: 8 Kbytes)
- "RL78_G24" folder [CATEGORY02]. Target device for the prepared file :

  RL78/G24 (R7F101GLG ROM: 128 Kbytes, RAM: 12 Kbytes, DF: 4 Kbytes)

To modify the setting values, refer to "Renesas Flash Driver and EEPROM Emulation Software for RL78 Target MCU List - General-Purpose" (here after "Target MCU List") and change into the set value which suited the device used.

If the folder name of the target device group exists in the "sample" folder, use that folder. If the folder name of the target device group does not exist, the folder of the device with the same "CATEGORY" number described in the target MCU list is used. A "RL78_G22" sample folder does not exist in the case which uses RL78/G22. Therefore, use "RL78_G23" folder for RL78/G23 of the same "CATEGORY01".

- The extract of a target MCU list

Target MCUs

MCU Group	Code Flash memory		User RAM		Data Fl				[R-7] END_BLOCK	[R-8] CATEGORY	Target MCU name
	Size (bytes)	Start/End Address	Size (bytes)	Start/End Address	Size (bytes)	S		M			
RL78/G22	32K	0x00000 - 0x07FFF	4K	0xFEF00 - 0xFFEFF	2K	0x			16	01	R7F102GxC (x = 4, 6, 7, 8, A, B, C, E, F, G)
	64K	0x00000 - 0x0FFFF	4K	0xFEF00 - 0xFFEFF	2K	0x			32	01	R7F102GxE (x = 4, 6, 7, 8, A, B, C, E, F, G)
RL78/G23	96K	0x00000 - 0x17FFF	12K	0xFCF00 - 0xFFEFF	8K	0x			48	01	R7F100GxF (x = A, B, C, E, F, G, J, L)
	128K	0x00000 - 0x1FFFF	16K	0xFBF00 - 0xFFEFF	8K	0x			64	01	R7F100GxG (x = A, B, C, E, F, G, J, L, M, P)
	192K	0x00000 - 0x2FFFF	20K	0xFAF00 - 0xFFEFF	8K	0x			96	01	R7F100GxH (x = A, B, C, E, F, G, J, L, M, P)
	256K	0x00000 - 0x3FFFF	24K	0xF9F00 - 0xFFEFF	8K	0x			128	01	R7F100GxJ (x = A, B, C, E, F, G, J, L, M, P, S)
	384K	0x00000 - 0x5FFFF	32K	0xF7F00 - 0xFFEFF	8K	0x			192	01	R7F100GxK (x = F, G, J, L, M, P, S)
	512K	0x00000 - 0x7FFFF	48K	0xF3F00 - 0xFFEFF	8K	0x			256	01	R7F100GxL (x = F, G, J, L, M, P, S)
	768K	0x00000 - 0xBFFFF	48K	0xF3F00 - 0xFFEFF	8K	0x			384	01	R7F100GxN (x = F, G, J, L, M, P, S)
RL78/G24	64K	0x00000 - 0x0FFFF	12K	0xFCF00 - 0xFFEFF	4K	0x			32	02	R7F101GxE (x = 6, 7, 8, A, B, E, F, G, J, L)
	128K	0x00000 - 0x1FFFF	12K	0xFCF00 - 0xFFEFF	4K	0x			64	02	R7F101GxG (x = 6, 7, 8, A, B, E, F, G, J, L)

An example of referencing the Target MCU List and an example of where to modify is shown below.

- Example of reference of the Target MCU List

For example, when modifying the setting value indicated by [R-1] (the start address of RAM) as shown in the following figure. Here, refer to the setting value of the start address [R-1] (RAM Start Address) of RAM shown in the Target MCU List and set the value of RL78/G22(R7F102GGE).

Example of where to modify the start address of RAM: RL78/G23(R7F100GxG RAM: 16 Kbytes).

[R-1] →

	EES_CODE_f
	SMP_EES_f
	EES_CNST_f
0xFBF00	.dataR
	.stack_bss

Example of setting the start address value of RAM when using RL78/G22 (R7F102GxE RAM: 4 Kbytes).

	EES_CODE_f
	SMP_EES_f
	EES_CNST_f
0xFEF00	.dataR
	.stack_bss

The value to be set in [R-1] refers to the Target MCU List and sets the start address value of RAM of the target device.

In the column "Target MCU name" of the Target MCU List, search for the row for R7F102GxE. Next, find the cell in the [R-1] column that intersects the row of R7F102GxE.

- Example of displaying the "Target MCU List"

MCU Group	Code Flash memory		User RAM		Data Flash memory		[R-1]	[R-2]	[R-3]	[R-4]	[R-5]	[R-6]	[R-7]	[R-8]	Target MCU name
	Size (bytes)	Start/End Address	Size (bytes)	Start/End Address	Size (bytes)	Start/End Address	RAM Start Address	ROM End Address 1	ROM End Address 2	Data Flash End Address	OCD_ROM	Trace_RAM	END_BLOCK	CATEGORY	
RL78/G22	32K	0x00000 - 0x07FFF	4K	0xFEF00 - 0xFFEFF	2K	0xF1000 - 0xF17FF	0xFEF00	0x07FFF	-	0xF17FF	0x7E00	0xFF300	16	01	R7F102GxC (x = 4, 6, 7, 8, A, B, C, E, F, G)
	64K	0x00000 - 0x0FFFF	4K	0xFEF00 - 0xFFEFF	2K	0xF1000 - 0xF17FF	0xFEF00	0x0FFFF	-	0xF17FF	0xFE00	0xFF300	32	01	R7F102GxE (x = 4, 6, 7, 8, A, B, C, E, F, G)

Since "0xFEF00" applies, the setting value of [R-1] is RL78/G22 (R7F102GxE) value "0xFEF00".

[R-1]	[R-2]	[R-3]	[R-4]	[R-5]	[R-6]	[R-7]	[R-8]	Target MCU name
RAM Start Address	ROM End Address 1	ROM End Address 2	Data Flash End Address	OCD_ROM	Trace_RAM	END_BLOCK	CATEGORY	
0xFEF00	0x07FFF	-	0xF17FF	0x7E00	0xFF300	16	01	R7F102GxC (x = 4, 6, 7, 8, A, B, C, E, F, G)
0xFEF00	0x0FFFF	-	0xF17FF	0xFE00	0xFF300	32	01	R7F102GxE (x = 4, 6, 7, 8, A, B, C, E, F, G)

- Example of where to modify

Points that need to be modified from the RL78/G23 (R7F100GLG) settings are listed from "7.3.1".

Points that need to be modified are indicated with "**[R-x] →**". Refer to the Target MCU List to find the appropriate [R-x] setting for your device. Enter the searched value in [R-x]. (x = 1, 2, 3…)

- Example of modifying section settings (start address of RAM)

(CS+: CC-RL compiler):

Setting for RL78/G23(RAM: 16 Kbytes)

Example: R7F100GxG

Setting for RL78/G22(RAM: 4 Kbytes)

Example: R7F102GGE

7.4.1 CC-RL Compiler Environment Settings

Points of modifies and examples of modifies when using the CC-RL compiler environments (CS+ and e^2 studio) are described.

7.4.1.1 Section Settings

Modify the start address of the RAM area in the section settings.

This example shows the change from RL78/G23 (R7F100GLG) to RL78/G22 (R7F102GGE).

Since the RAM size is changed from 16 Kbytes to 4 Kbytes, modify the start address of RAM from "0xFBF00" to "0xFEF00".

  Note: For the start address of the RAM for each product, refer to "R-1" column in the Target MCU List.

- Example of modifying section settings (start address of RAM) in CS+:

Setting for RL78/G23(RAM: 16 Kbytes)
Example: R7F100GLG
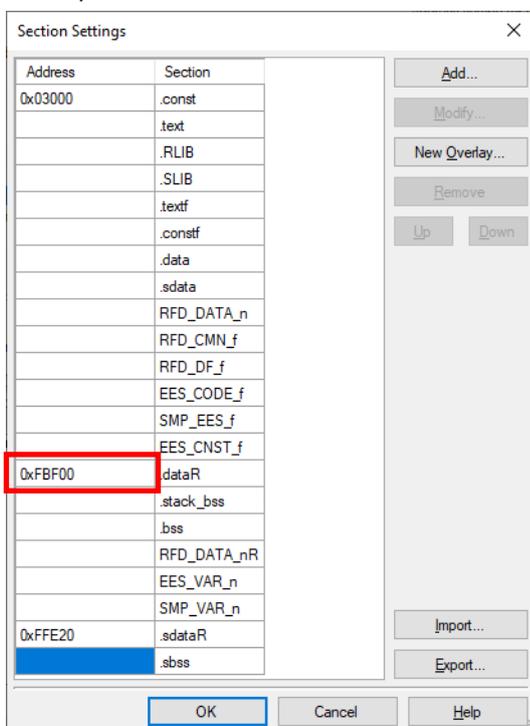
Setting for RL78/G22(RAM: 4 Kbytes)
Example: R7F102GGE

- Example of modifying section settings (start address of RAM) in e^2 studio:

Setting for RL78/G23(RAM: 16 Kbytes)
Example: R7F100GLG

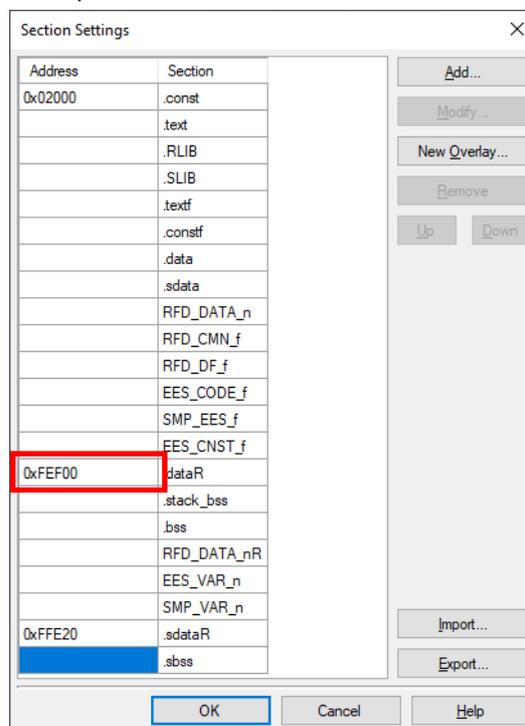| Address	Section Name
0x00003000	.const
	.text
	.data
	.sdata
	.RLIB
	.SLIB
	.textf
	.constf
	RFD_DATA_n
	RFD_CMN_f
	RFD_DF_f
	EES_CODE_f
	SMP_EES_f
	EES_CNST_f
0x000FBF00	.dataR
	.stack_bss
	.bss
	RFD_DATA_nR
	EES_VAR_n
	SMP_VAR_n
0x000FFE20	.sdataR
	.sbss

[R-1] → 0x000FBF00

Buttons: Add Section, New Overlay, Remove Section, Move Up, Move Down, Import..., Export...

Setting for RL78/G22(RAM: 4 Kbytes)
Example: R7F102GGE

Address	Section Name
0x00002000	.const
	.text
	.data
	.sdata
	.RLIB
	.SLIB
	.textf
	.constf
	RFD_DATA_n
	RFD_CMN_f
	RFD_DF_f
	EES_CODE_f
	SMP_EES_f
	EES_CNST_f
0x000FEF00	.dataR
	.stack_bss
	.bss
	RFD_DATA_nR
	EES_VAR_n
	SMP_VAR_n
0x000FFE20	.sdataR
	.sbss

Buttons: Add Section, New Overlay, Remove Section, Move Up, Move Down, Import..., Export...

7.4.1.2 Debug Settings

When using a device other than the one targeted by the sample program, the range of the debug monitor area when using the debugger is different.

   - The start of the "debug monitor area" address sets the address obtained by subtracting "511 bytes (0x1FF)" from the end address of the ROM area. If the end address is "0x1FFFF", set it to "0x1FE00".

This example shows the modify from RL78/G23 (R7F100GLG) to RL78/G22 (R7F102GGE).
   - Set the debug monitor area range to "0x0FE00 - 0x0FFFF".

Note: For information on The start address of the "debug monitor area" for each product, refer to "[R-5]" column in the Target MCU List.

   - To set the debug monitor area in CS+, select the [Device] on the "Link Options" tab.

     Setting for RL78/G23 (ROM: 128 Kbytes)　　Example: R7F100GLG
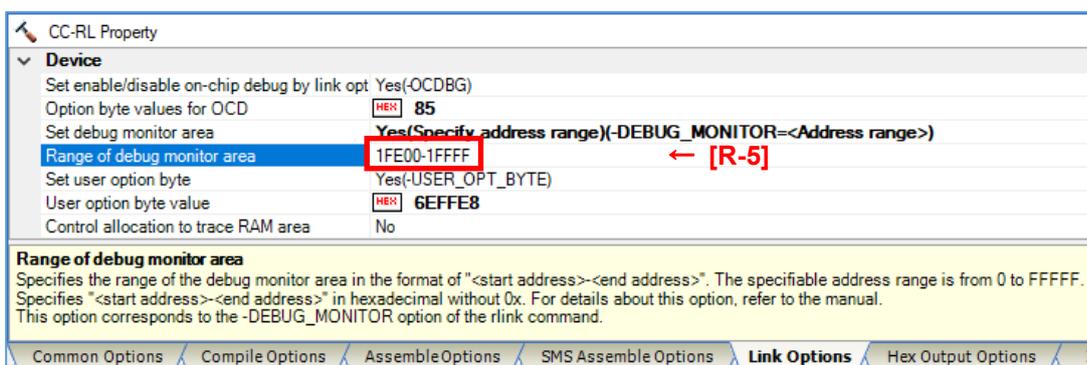
     Setting for RL78/G22 (ROM: 64 Kbytes)　　Example: R7F102GGE
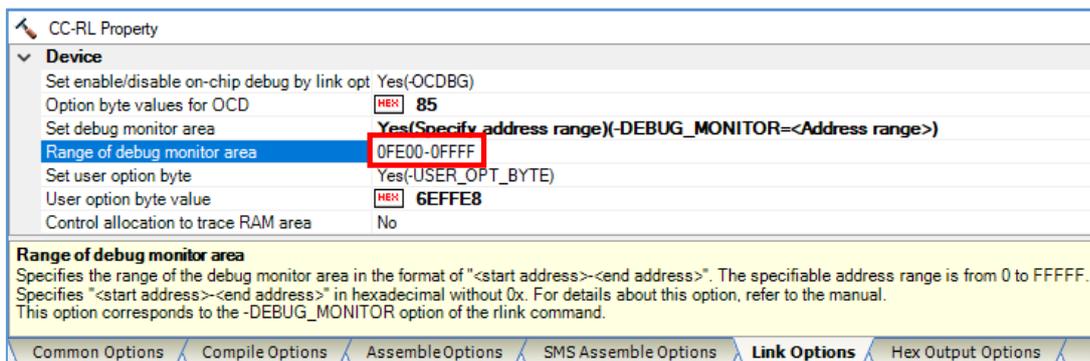
- To set the debug monitor area in e² studio, select the [Device] in the "Linker".

Setting for RL78/G23 (ROM: 128 Kbytes)   Example: R7F100GLG
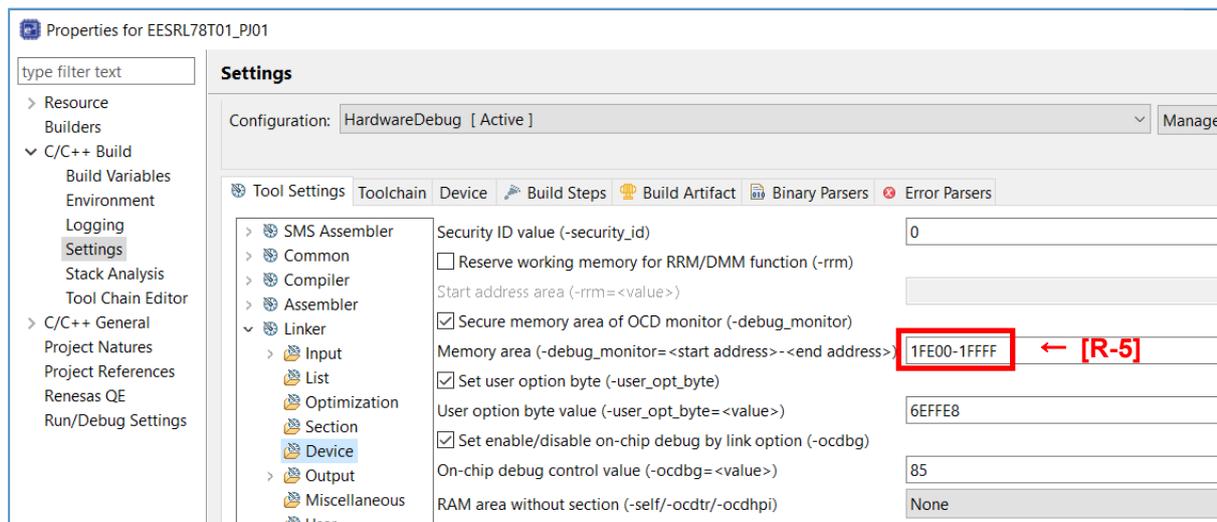
Setting for RL78/G22 (ROM: 64 Kbytes)   Example: R7F102GGE
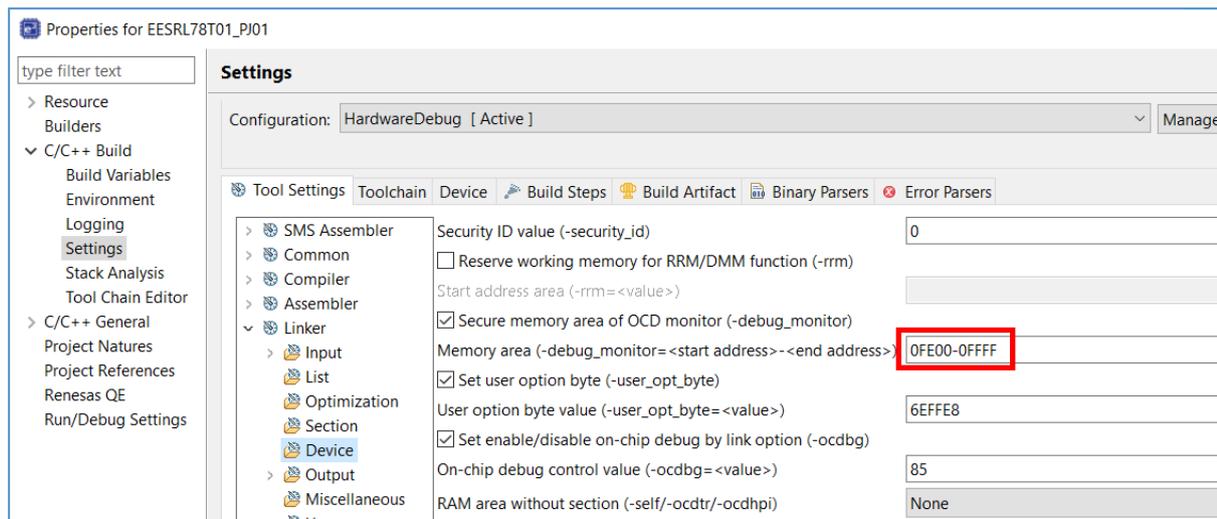
7.4.2   IAR Compiler Environment Settings

Points of modifies and examples of modifies when using the IAR compiler environment (Embedded Workbench) is described.

7.4.2.1   Setting Up Header Files for Target Device

The "main.c" and "low_level_init.c" provided with EES RL78 Type 01 includes the header files for the target device "RL78/G23: R7F100GLG". When using other RL78/G23 products or RL78/G22 products, the included header file must be changed to the header file for the device used.

```
- For RL78/G23(R7F100GLG):
  <main.c>
    #include "ior7f100glg.h"

  <low_level_init.c>
    #include "ior7f100glg.h"
    #include "ior7f100glg_ext.h"


- Example for RL78/G22 (R7F102GGE):
  <main.c>
    #include "ior7f102gge.h"

  <low_level_init.c>
    #include "ior7f102gge.h"
    #include "ior7f102gge_ext.h"
```

> Note: For the device type name of the product, refer to "Target MCU name" column in the Target MCU List.

7.4.2.2   Linker Configuration File Settings

In the sample program "RL78_G23" folder provided by EES RL78 Type 01, The sections (ROM, RAM, and Data flash range) for RL78/G23 (R7F100GLG) are set.
When using other RL78/G23 products or RL78/G22 products, modify the contents of the sample linker file "sample_linker_file.icf" provided for the RL78/G23 of EES RL78 Type 01, because the range of the section settings, and "TraceRAM area" and "debug monitor area" when using the debugger are different.

Target file name: sample_linker_file.icf

This example shows the modify from RL78/G23 (R7F100GLG) to RL78/G22 (R7F102GGE).
- Modify the ROM area to the range of 64 Kbytes [0x00000 - 0x0FFFF]
- Modify the start address to "0xFEF00" because the RAM area is 4 Kbytes [0x0FEF00 - 0x0FFEFF]
- Modify the end address to "0xF17FF" because the data flash area is 2 Kbytes [0x0F1000 - 0x0F17FF]

(1) **Section Settings**

Setting for RL78/G23 (ROM: 128 Kbytes, RAM: 16 Kbytes, DF: 8 Kbytes) Example: R7F100GLG

```
define region ROM_near  = mem:[from 0x000D8 to 0x0FFFF];      ← [R-2]
define region ROM_far   = mem:[from 0x000D8 to 0x0FFFF] | mem:[from 0x10000 to 0x1FFFF];  ← [R-2], [R-3] Note1
define region ROM_huge  = mem:[from 0x000D8 to 0x1FFFF];      ← [R-2] or [R-3] Note2
define region SADDR     = mem:[from 0xFFE20 to 0xFFEDF];
define region RAM_near  = mem:[from 0xFBF00 to 0xFFE1F];      ← [R-1]
define region RAM_far   = mem:[from 0xFBF00 to 0xFFE1F];      ← [R-1]
define region RAM_huge  = mem:[from 0xFBF00 to 0xFFE1F];      ← [R-1]
define region VECTOR    = mem:[from 0x00000 to 0x0007F];
define region CALLT     = mem:[from 0x00080 to 0x000BF];
define region EEPROM    = mem:[from 0xF1000 to 0xF2FFF];      ← [R-4]
```

Notes 1: If the ROM size is larger than 64 Kbytes, the description must be changed as the ROM size increases. For details, please refer to "Examples of ROM_far" on the next page.

   2: Sets the value [R-3] when there is an address value in [R-3] on the Target MCU List. In the case of "-", set the value of [R-2].

Setting for RL78/G22 (ROM: 64 Kbytes, RAM: 4 Kbytes, DF: 2 Kbytes) Example: R7F102GGE

```
define region ROM_near  = mem:[from 0x000D8 to 0x0FFFF];
define region ROM_far   = mem:[from 0x000D8 to 0x0FFFF];
define region ROM_huge  = mem:[from 0x000D8 to 0x0FFFF];
define region SADDR     = mem:[from 0xFFE20 to 0xFFEDF];
define region RAM_near  = mem:[from 0xFEF00 to 0xFFE1F];
define region RAM_far   = mem:[from 0xFEF00 to 0xFFE1F];
define region RAM_huge  = mem:[from 0xFEF00 to 0xFFE1F];
define region VECTOR    = mem:[from 0x00000 to 0x0007F];
define region CALLT     = mem:[from 0x00080 to 0x000BF];
define region EEPROM    = mem:[from 0xF1000 to 0xF17FF];
```

- Examples of ROM_far

The following is an example of entries in ROM_far for each ROM size. Refer to the row with the same
ROM size as the target device. Colored areas indicate values for [R-2] or [R-3].

When ROM size is 64 Kbytes or less ([R-3] is "-").

ROM	[R-2] Value	mem:[from 0x000D8 to [R-2]];
32 Kbytes	0x07FFF	mem:[from 0x000D8 to 0x07FFF];
64 Kbytes	0x0FFFF	mem:[from 0x000D8 to 0x0FFFF];

When ROM size exceeds 64 Kbytes ([R-3] is not "-").

ROM	[R-3] Value	mem:[from 0x000D8 to [R-2] | mem:[from 0x10000 to 0x1FFFF] | …Omitted… | mem:[from 0xX0000 to [R-3]];
96 Kbytes	0x17FFF	mem:[from 0x000D8 to 0x0FFFF] | mem:[from 0x10000 to 0x17FFF];
128 Kbytes	0x1FFFF	mem:[from 0x000D8 to 0x0FFFF] | mem:[from 0x10000 to 0x1FFFF];
192 Kbytes	0x2FFFF	mem:[from 0x000D8 to 0x0FFFF] | mem:[from 0x10000 to 0x1FFFF] | mem:[from 0x20000 to 0x2FFFF];
256 Kbytes	0x3FFFF	mem:[from 0x000D8 to 0x0FFFF] | mem:[from 0x10000 to 0x1FFFF] | mem:[from 0x20000 to 0x2FFFF] | mem:[from 0x30000 to 0x3FFFF];
384 Kbytes	0x5FFFF	mem:[from 0x000D8 to 0x0FFFF] | mem:[from 0x10000 to 0x1FFFF] | mem:[from 0x20000 to 0x2FFFF] | mem:[from 0x30000 to 0x3FFFF] | mem:[from 0x40000 to 0x4FFFF] | mem:[from 0x50000 to 0x5FFFF];
512 Kbytes	0x7FFFF	mem:[from 0x000D8 to 0x0FFFF] | mem:[from 0x10000 to 0x1FFFF] | mem:[from 0x20000 to 0x2FFFF] | mem:[from 0x30000 to 0x3FFFF] | mem:[from 0x40000 to 0x4FFFF] | mem:[from 0x50000 to 0x5FFFF] | mem:[from 0x60000 to 0x6FFFF] | mem:[from 0x70000 to 0x7FFFF];
768 Kbytes	0xBFFFF	mem:[from 0x000D8 to 0x0FFFF] | mem:[from 0x10000 to 0x1FFFF] | mem:[from 0x20000 to 0x2FFFF] | …Omitted… | mem:[from 0xA0000 to 0xAFFFF] | mem:[from 0xB0000 to 0xBFFFF];

(2) Debug Settings

- The start of the "debug monitor area" address sets the address obtained by subtracting "511 bytes (0x1FF)" from the end address of the ROM area. If the end address is "0x1FFFF", set "0x1FE00".
- The start address of the "TraceRAM area" sets the address obtained by adding "1 Kbyte (0x400)" to the start address of the RAM area. If the start address is "0xFBF00", set "0xFC300".

This example shows a modify from RL78/G23 (R7F100GLG) to RL78/G22 (R7F102GGE).
   - Modify the "debug monitor area" range to [from 0x0FE00 size 0x0200]
   - Modify the "TraceRAM area" range to [from 0xFF300 size 0x0400]

The point where modifications to the "TraceRAM area" and "debug monitor area" when using the debugger are to be implemented.

Setting for RL78/G23 (ROM: 128 Kbytes, RAM: 16 Kbytes, DF: 8 Kbytes) Example: R7F100GLG

```
if (isdefinedsymbol(__RESERVE_OCD_ROM))
{
  if (__RESERVE_OCD_ROM == 1)
  {
    reserve region "OCD ROM area" = mem:[from 0x1FE00 size 0x0200];   ← [R-5]
  }
}
            |
            |        Omitted
            |
if (isdefinedsymbol(__RESERVE_OCD_TRACE_RAM))
{
  if (__RESERVE_OCD_TRACE_RAM == 1)
  {
    reserve region "OCD Trace RAM" = mem:[from 0xFC300 size 0x0400];   ← [R-6]
  }
}
```

Setting for RL78/G22 (ROM: 64 Kbytes, RAM: 4 Kbytes, DF: 2 Kbytes) Example: R7F102GGE

```
if (isdefinedsymbol(__RESERVE_OCD_ROM))
{
  if (__RESERVE_OCD_ROM == 1)
  {
    reserve region "OCD ROM area" = mem:[from 0x0FE00 size 0x0200];
  }
}
            |
            |        Omitted
            |
if (isdefinedsymbol(__RESERVE_OCD_TRACE_RAM))
{
  if (__RESERVE_OCD_TRACE_RAM == 1)
  {
    reserve region "OCD Trace RAM" = mem:[from 0xFF300 size 0x0400];
  }
}
```

7.4.3   LLVM Compiler Environment Settings

Points of modifies and examples of modifies when using the LLVM compiler environment (e² studio) is described.

7.4.3.1   Linker Script File Settings

In the sample program "RL78_G23" folder provided by EES RL78 Type 01, The sections (ROM, RAM, and Data flash range) for RL78/G23 (R7F100GLG) are set.

When using other RL78/G23 products or RL78/G22 products, modify the contents of the sample linker script file "sample_linker_file.ld" provided for the RL78/G23 of EES RL78 Type 01, because the range of the section settings, "TraceRAM area" and "debug monitor area (OCDROM)" when using the debugger are different.

The following shows the modified part in red text. Refer to the "Target MCU List" and modify the setting values for the target device.

Target file name: sample_linker_file.ld

This example shows the modify from RL78/G23 (R7F100GLG) to RL78/G22 (R7F102GGE).

- The start address of the OCDROM (debug monitor area) is set to the address obtained by subtracting "511 bytes (0x1FF)" from the end address of the ROM area. If the end address of the ROM area is "0xFFFF", set the ORIGIN of the OCDROM to "0xFE00" [R-5].

- The size of the ROM area is the area from "0xD8" to the start address of the OCDROM. If the OCDROM start address is "0xFE00", set the ROM LENGTH to "64808", which is the decimal value obtained by subtracting "0xD8" from the OCDROM start address "0xFE00".

- The start address and size of "MIRROR (mirror area)" differs depending on the device. For RL78/G22 (R7F100GGE), set "0xF2000", the start address of the mirror area, to the ORIGIN of the MIRROR. For the LENGTH, set "52992", the decimal value from the start address "0xF2000" to the end address "0xFEEFF" of the mirror area.
  For more information about the "Mirror area", please refer to the hardware manual of the device.

- Set the start address of the RAM area "0xFEF00" [R-1] to ORIGIN in the RAM area, and set the LENGTH to "4096", which is 4 KB in decimal.

- "TRACERAM" area uses an area of 1024 bytes from the address obtained by adding 1024 bytes to the start address of RAM, so set the ORIGIN to "0xFF300" [R-6]. Also, since the trace function may not be used or may not be available for some devices, please refer to the hardware manual of the device for details on the TRACERAM area.
  Note: The trace function is not available using RL78/G22. The above is described as a configuration example, but is commented out so that the target line is not compiled.

(1) MEMORY setting

Setting for RL78/G23 (ROM: 128 Kbytes, RAM: 16 Kbytes, DF: 8 Kbytes) Example: R7F100GLG

```
MEMORY
{
  VEC : ORIGIN = 0x0, LENGTH = 4
  IVEC : ORIGIN = 0x4, LENGTH = 188
  CALLT0 : ORIGIN = 0x80, LENGTH = 0x40
  OPT : ORIGIN = 0xC0, LENGTH = 4
  SEC_ID : ORIGIN = 0xC4, LENGTH = 10
  OCDSTAD : ORIGIN = 0xCE, LENGTH = 10
  OCDROM : ORIGIN = 0x1FE00, LENGTH = 512          ← [R-5]
  ROM : ORIGIN = 0xD8, LENGTH = 130344
  MIRROR : ORIGIN = 0xF3000, LENGTH = 36608
  SADDR : ORIGIN = 0xffe20, LENGTH = 0x000a0
  RAM : ORIGIN = 0xFBF00, LENGTH = 16384           ← [R-1]
  TRACERAM   : ORIGIN = 0xFC300, LENGTH = 1024     ← [R-6]
}
```

Setting for RL78/G22 (ROM: 64 Kbytes, RAM: 4 Kbytes, DF: 2 Kbytes) Example: R7F102GGE

```
MEMORY
{
  VEC : ORIGIN = 0x0, LENGTH = 4
  IVEC : ORIGIN = 0x4, LENGTH = 188
  CALLT0 : ORIGIN = 0x80, LENGTH = 0x40
  OPT : ORIGIN = 0xC0, LENGTH = 4
  SEC_ID : ORIGIN = 0xC4, LENGTH = 10
  OCDSTAD : ORIGIN = 0xCE, LENGTH = 10
  OCDROM : ORIGIN = 0xFE00, LENGTH = 512
  ROM : ORIGIN = 0xD8, LENGTH = 64808
  MIRROR : ORIGIN = 0xF2000, LENGTH = 52992
  SADDR : ORIGIN = 0xffe20, LENGTH = 0x000a0
  RAM : ORIGIN = 0xFEF00, LENGTH = 4096
  /* TRACERAM   : ORIGIN = 0xFF300, LENGTH = 1024 */
}
```

Note: The RL78/G22 is not included in compilation because the trace function cannot be used, but only the value should be modified on devices that support the trace function.

(2) Set the start address of the RAM area

Setting for RL78/G23 (ROM: 128 Kbytes, RAM: 16 Kbytes, DF: 8 Kbytes) Example: R7F100GLG

```
.data 0xFBF00 : AT(__mdata)                              ← [R-1]
{
    . = ALIGN(2);
    PROVIDE (__datastart = .);
    __data = .;
    *(.data)
    *(.data.*)
    . = ALIGN(2);
    /*INPUT_SECTION_FLAGS(!SHF_EXECINSTR,SHF_WRITE,SHF_ALLOC)
*(*_n)*/
    __edata = .;
} >RAM
```

Setting for RL78/G22 (ROM: 64 Kbytes, RAM: 4 Kbytes, DF: 2 Kbytes) Example: R7F102GGE

```
.data 0xFEF00 : AT(__mdata)
{
    . = ALIGN(2);
    PROVIDE (__datastart = .);
    __data = .;
    *(.data)
    *(.data.*)
    . = ALIGN(2);
    /*INPUT_SECTION_FLAGS(!SHF_EXECINSTR,SHF_WRITE,SHF_ALLOC)
*(*_n)*/
    __edata = .;
} >RAM
```

7.4.4   Modifying the Sample Program (Common to CC-RL, IAR and LLVM Compilers)

7.4.4.1   Modifying the Number of Data Flash Memories Used for EES Block

The number of blocks of flash memory differs between RL78/G23 and RL78/G22, which is targeted by the EES RL78 Type01 sample program folder "RL78_G23". Therefore, to use the number of EEPROM emulation block at least 3 blocks (recommended), the EES block size must be modified to 512 bytes.

Modify the number of data flash memory used for the EES block of RL78/G22 in the "r_ees_descriptor.h" file. Modify the EES block size from 4u (1024 bytes) to 2u (512 bytes).

Target file name: r_ees_descriptor.h

Setting for RL78/G23 (DF: 8 Kbytes) Example: R7F100GLG

```
/* Specifies the number of physical data flash blocks per one virtual block */
#define R_EES_EXRFD_VALUE_U08_PHYSICAL_BLOCKS_PER_VIRTUAL_BLOCK (4u)
```

Setting for RL78/G22 (DF: 2 Kbytes) Example: R7F102GGE

```
/* Specifies the number of physical data flash blocks per one virtual block */
#define R_EES_EXRFD_VALUE_U08_PHYSICAL_BLOCKS_PER_VIRTUAL_BLOCK (2u)
```

7.4.4.2 Data Resizing for Each Identifier (data ID)

When the EES block size is modified to 512 bytes, Modify the data size of "type_Z" in the "r_ees_user_types.h" file because the total data will exceed the recommended size (251 bytes).

For details of the recommended size, Refer to "4.1 Number of Stored User Data Items and Total User Data Size".

Target file name: r_ees_user_types.h

Setting for RL78/G23 (DF: 8 Kbytes) Example: R7F100GLG

```
typedef    uint8_t    type_A[2];
typedef    uint8_t    type_B[3];
typedef    uint8_t    type_C[4];
typedef    uint8_t    type_D[5];
typedef    uint8_t    type_E[6];
typedef    uint8_t    type_F[10];
typedef    uint8_t    type_X[20];
typedef    uint8_t    type_Z[255];
```

Setting for RL78/G22 (DF: 2 Kbytes) Example: R7F102GGE

```
typedef    uint8_t    type_A[2];
typedef    uint8_t    type_B[3];
typedef    uint8_t    type_C[4];
typedef    uint8_t    type_D[5];
typedef    uint8_t    type_E[6];
typedef    uint8_t    type_F[10];
typedef    uint8_t    type_X[20];
typedef    uint8_t    type_Z[30];
```

8.   Revision History

8.1   Major Modifications in this Revision

Rev.	Date	Description	
		Page	**Summary**
1.00	Jan.12.22	–	Newly created.
1.01	Dec.28.22	–	Add support of RL78/G22.
1.10	Apr.28.23	–	Add support of RL78/G24.
			Added "7.1.3.2 The Setting of User Definition Macro".
			Added "7.2.3.2 The Setting of User Definition Macro".
			Added "7.3 Configurations Modify Procedure for Changing Device".
1.20	Sep.28.23	-	Add support of LLVM compiler
		105	Added "7.3 Creating a Project in the Case of Using LLVM Compiler".
		129	Added "7.4.3 LLVM Compiler Environment Settings".

EEPROM Emulation Software

RL78 Type 01

RENESAS

Renesas Electronics Corporation